CMOS ASIC Design of Multi-frequency Multi-constellation GNSS Front-ends

THÈSE N° 7045 (2016)
PRÉSENTÉE LE 20 JUIN 2016
À LA FACULTÉ DES SCIENCES ET TECHNIQUES DE L’INGÉNIEUR
LABORATOIRE D’ÉLECTRONIQUE ET TRAITEMENT DU SIGNAL
PROGRAMME DOCTORAL EN GÉNIE ÉLECTRIQUE

ÉCOLE POLYTECHNIQUE FÉDÉRALE DE LAUSANNE
POUR L’OBTENTION DU GRADE DE DOCTEUR ÉS SCIENCES

PAR
Saeed GHAMARI

acceptée sur proposition du jury:
Prof. K. Aminian, président du jury
Prof. P.-A. Farine, Dr C. Botteron, directeurs de thèse
Prof. F. Alimenti, rapporteur
Dr G. Tasselli, rapporteur
Prof. H. Shea, rapporteur

Suisse
2016
Dedicated to
my beloved mother, Tahereh, and my beloved father, Einollah...
Acknowledgements

First and foremost, I am grateful to the God for his blessings and for the good health and wellbeing that were necessary to complete this work. I would also like to express my gratitude to several people without whom this work would not have been accomplished. First, I would like to express my sincere gratitude to my kind supervisor Prof. Dr Pierre-André Farine, head of ESPLAB, for giving me the opportunity to be part of ESPLAB and providing me with the most favorable work conditions during my Ph.D.

Special thanks go to Dr Cyril Botteron for being such a supportive and motivating supervisor, for his guidance and support throughout the period of this dissertation as well as continuous review of my work. I have been extremely lucky to have such a committed co-supervisor who cared so much about me and my work.

I would also like to express my gratitude to the rest of the thesis jury committee, Prof. Kamiar Aminian, Dr Gabriele Tasselli, Prof. Federico Alimenti and Prof. Herbert Shea for accepting to review my dissertation and evaluate this work.

My sincere gratitude goes to Dr Gabriele Tasselli, my friend and former officemate for the continuous support of my Ph.D. study and related research, for his patience, motivation, and immense knowledge. His guidance helped me all the time of research and writing of this thesis. I could not have imagined accomplishing this work without his advices.

Special thanks go to Christian Robert for his support and help regarding any questions and problems involving Cadence and PCB design. I am also thankful to him for the French translation of the abstract of this thesis.

Moreover, I would like to thank Christelle Emery and Vincenzo Capuano for their skills in regard with travel organization inside and outside of Switzerland. I thank also all my former and current colleagues at ESPLAB, Aleksandar, Alexis, Ban, Biswajit, Chao, Flavien, Hugo, Jean-Pierre, Jérôme, Laurent, Marcel, Marko, Martin, Mathieu, Miguel, Mitko, Patrick, Paul, Pavel, Sara, Urs, Vasili and Youssef for their friendship and creating a very nice atmosphere and wonderful time during the last five years. My appreciation goes to Mrs. Joelle Banjac for all the administrative helps and supports she provided me during my Ph.D.

My special thanks go to my Iranian friends, Alaleh, Mohssen, Abbas, Milad and Ali Dabirian for making the life in Neuchâtel much easier despite being away from my home town.

Finally, I would like to express my sincere gratitude to my parents, Tahereh and Einollah to whom I owe my life, my brother Madjid and my sister Mahshid for their unconditional love and for supporting me throughout my life.

Neuchâtel, le 19 Mai 2016

S. Gh.
Abstract

With the emergence of the new global navigation satellite systems (GNSSs) such as Galileo, COMPASS and GLONASS, the Global Positioning System (GPS) is no longer the sole player in satellite navigation systems. These new systems offer not only new services but also new frequency bands and signal structures, and challenge engineers to exploit them. Moreover, the deployment of the new satellites will increase the number of visible satellites by three to four times in the near future. The increase in visible satellites and interoperability among the GNSSs open a new door towards multi-constellation multi-frequency GNSS receivers. This creates a new series of challenges for engineers with regard to improving positioning accuracy, precision, robustness, and reliability, and opens the possibility for new applications that are limited only by our imagination. In the course of this dissertation, two application-specific integrated circuit (ASIC) GNSS front-ends (FEs) were designed to address some of these challenges.

Although Galileo is the first global positioning service under civilian control, it offers specialized services such as the public regulated service (PRS). The PRS is a proprietary encrypted navigation service that is designed to be more robust and reliable, with anti-jamming and pseudo-random number (PRN) encryption mechanisms. This service provides position and timing to a specific group of users, authorized governmental bodies, who require a high continuity of service. The PRS as a new service demands a class of advanced FEs that can satisfy its stringent requirements. The project that this thesis is part of, aims to develop a multi-frequency PRS receiver by filling some of the technological gaps in order to enable affordable and robust solutions for future demanding applications that rely on the continuous availability of the PRS. These developments respond to the growing need for low-cost multi-frequency radio modules adapted for professional applications.

Towards this end, the design of a dual-frequency PRS receiver that is capable of simultaneous reception of both the E1 and E6 PRS signals is presented. In order to increase the robustness of the receiver in the presence of interference, the receiver incorporates two independent FEs. The entire radio frequency (RF) chain, including a low-noise amplifier (LNA), a quadrature mixer, a frequency synthesizer (FS), two intermediate frequency (IF) filters, two variable-gain amplifiers (VGAs) and two analog-to-digital converters (ADCs), is the object of research and development within this project. Each FE provides 50 MHz of IF bandwidth to accommodate wide-band PRS signals. Moreover, it achieves 65 dB of gain and 30 dB of gain dynamic range. It features a 6-bit ADC that allows for the implementation of interference mitigation algorithms in the baseband processor in order to withstand strong interferers and...
improve the robustness of the receiver. The complete FE occupies a die area of 11.5 mm$^2$ on 0.18 $\mu$m complementary metal-oxide-semiconductor (CMOS) while consuming 115 mW.

Furthermore, to address civilian applications and exploit the interoperability among GNSSs, this thesis also presents a reconfigurable single-channel FE. The receiver operates in two modes: in the “narrow-band” mode, it shows an IF bandwidth of 8 MHz and can receive Beidou-B1 while drawing 22.85 mA from a 1.8 V supply, and in the “wide-band” mode, with an IF bandwidth of 23 MHz, it can accommodate simultaneous reception of Beidou-B1/GPS-L1/Galileo-E1 while consuming 28.45 mA. Measures to improve the linearity are taken, and the FE shows very good linearity with an input-referred 1 dB compression point (IP1dB) of better than -27.6 dBm. The FE achieves a gain dynamic range of 19.1 dB and a maximum gain of 58 dB. The complete FE including the LNA, quadrature mixer, VGAs, 6-bit ADCs and the IF filters occupies an active die area of only 2.6 mm$^2$ on 0.18 $\mu$m CMOS.

To accommodate the wide-band PRS signals in the IF section of the PRS FE, as well as to provide the dual-mode functionality in the reconfigurable single-channel FE, a highly selective wide-tuning-range 4$^{th}$-order Gm-C elliptic low-pass filter is employed in both FEs. The filter features a continuous tuning range that is achieved by means of a new tuning circuit that adjusts the bias current of the Gm cell’s input stage to control the cutoff frequency. With this tuning circuit, power efficiency is achieved by scaling down the power consumption proportionally to the cutoff frequency while keeping the linearity near constant over a wide range of bandwidths. Moreover, a quality factor (Q) enhancement and common-mode (CM) stability methods are employed in the design of the Gm cell. To extend the tuning range of the filter, Gm switching, which also acts on the Gm cell’s input stage without adding any switches in the signal path, was employed. The filter was fabricated using 0.18 $\mu$m CMOS technology on an active die area of 0.23 mm$^2$. Its cutoff frequency ranges continuously from 7.4 MHz to 27.4 MHz. Not only does this wide tuning range make the filter suitable for modern wide-band GNSS signals in low-IF and zero-IF receivers, but the abrupt roll-off of up to 66 dB/octave, which can mitigate out-of-band interference, also fits the filter better in PRS applications. The filter consumes 2.1 mA and 7.5 mA from a 1.8 V supply at its lowest and highest cutoff frequencies, respectively, and achieves a high input-referred third-order intercept point (IIP3) of up to -1.3 dBV$_{\text{RMS}}$. The measured in-band average non-linear phase error of the filter is less than 6.2°, which satisfies the stringent non-linear phase error requirement of the PRS receiver.

Key words: Galileo, global navigation satellite system (GNSS), Global Positioning System (GPS), Beidou, front-end, receiver, reconfigurable, complementary metal-oxide-semiconductor (CMOS), multi-frequency, multi-constellation, application-specific integrated circuit (ASIC), low-noise amplifier (LNA), passive mixer, gyrator, operational transconductance amplifier (OTA), quality factor (Q), active inductors, active filter, continuous-time filters, Gm-C, quality factor (Q) enhancement, common-mode stability, selectivity enhancement, resonator, analog-to-digital converter (ADC), variable-gain amplifier (VGA), wide-tuning-range filters, elliptic, public regulated service (PRS), zero-IF, low-IF, voltage-controlled oscillator (VCO)
Résumé

L'émergence de nouveaux systèmes globaux de navigation par satellites (GNSS) tels que Galileo, COMPASS et GLONASS, font que le système de positionnement américain (GPS) n’est dorénavant plus l'unique solution de localisation terrestre. Si ces systèmes proposent de nouveaux services, ils exploitent aussi un certain nombre de fréquences distinctes ainsi que des structures de signaux différentes de celles du GPS. Si bientôt par ces nouvelles constellations un récepteur au sol verra le nombre de satellites visibles multiplié par trois ou quatre, apportant ainsi des améliorations notables en termes de précision, de robustesse et de fiabilité, avec à la clef de nouvelles applications inédites, les nuances inter-systèmes sont autant de contraintes et de défis pour qui veut développer des solutions de réception génériques capables de gérer nativement ce nouvel environnement multi-fréquentiel et multi-systèmes. C’est dans le but de répondre à certains de ces défis qu’ont été conçus les deux circuits analogiques radiofréquences frontaux intégrés à application spécifique (ASIC-FE) présentés dans cette thèse.

Le 1er ASIC-FE est un récepteur PRS permettant la réception simultanée des bandes Galileo E1 et E6. Bien que Galileo soit le premier GNSS sous contrôle civil, il inclut des services dits spécialisés tels que le service public réglementé (PRS). Ce service, munis de protection contre le brouillage ainsi que de mécanismes de cryptage, est réservé à des utilisateurs spécifiques, et permet de fournir de manière plus fiable et précise à la fois la position et le temps. Toutefois, ce service demande l’usage de FE spécifiques aux performances accrues. Le premier projet dont est issu cette thèse vise donc à développer un récepteur multifréquence compatible PRS, encore rare sur ce nouveau marché en pleine expansion. Celui-ci devra allier prix abordable et solution robuste pour une implantation dans des applications professionnelles où la disponibilité continue du signal PRS est primordiale. Afin d’optimiser la robustesse en milieu perturbé, ce circuit inclut deux FE indépendantes. La chaîne radiofréquence (RF), objet principal de la recherche au sein de ce projet, est composée d’un amplificateur d’entrée à faible bruit (LNA), d’un mélangeur en quadrature, d’un synthétiseur de fréquence (FS), de deux filtres pour fréquence intermédiaire (IF), de deux amplificateurs à gain variable (VGA) et enfin de deux convertisseurs analogique-numérique (ADC). Afin de permettre la réception de signaux PRS large bande, chaque FE couvre une largeur de bande de 50 MHz et inclut un gain fixe de 35 dB extensible dynamiquement jusqu’à 65 dB. En fin de chaîne, l’ADC de 6 bits permet un interfaçage direct au processeur de bande de base. Gravé dans une technologie de type semi-conducteur à oxyde de métal complémentaire (CMOS) ayant finesse de 0,18 microns, la superficie du récepteur complet (incluant les deux FE) occupe 11.5 mm² et consomme
115 mW sous une alimentation de 1,8 V.

Le 2\textsuperscript{nd} ASIC vise les applications civiles et permet par un canal FE unique et reconfigurable à la volée de bénéficier de l’interopérabilité des systèmes GNSS. Ce FE possède 2 modes de fonctionnement : le premier, dit « bande étroite », propose une bande passante en IF de 8 MHz afin de recevoir la bande Beidou-B1. Le second, dit « large bande », possède une bande passante de 23 MHz permettant ainsi la réception simultanée de Beidou-B1/GPS-L1/Galileo-E1. Le courant consommé est, respectivement, de 22.85 mA et de 28.45 mA sous une tension de 1.8 V. Durant la conception, une attention particulière a été portée à la linéarité. Ce FE atteint ainsi une très bonne valeur pour son point de compression à 1 dB (IP1dB) avec plus de -27.6 dBm. Il possède encore un gain variable dynamiquement sur plus de 19 dB avec un maximum à 58 dB. Développé en CMOS 0.18 micron, le FE complet (LNA, mélangeur en quadrature, VGAs, ADCs, filtres IF) occupe, pour sa partie active, une superficie totale de seulement 2.6 mm\textsuperscript{2}.

Afin de tenir compte de la largeur de bande étendue des signaux PRS en bande IF, pour le 1\textsuperscript{er} ASIC ainsi que pour l’implantation du double mode du 2\textsuperscript{nd}, un filtre passe-bas elliptique réglable du 4\textsuperscript{ème} ordre de type transconductance-Capacité (Gm-C) a été mis au point. L’ajustement de sa fréquence de coupure (Fc) est réalisé via une solution novatrice qui agit sur le courant de polarisation de l’étage d’entrée de la cellule Gm. L’originalité principale de ce circuit réside dans le fait qu’il rend la consommation proportionnelle à Fc, et offre une linéarité quasi-constante sur une large gamme de fréquence. De plus, l’optimisation du facteur de qualité (Q) et la stabilité du mode commun (CM) ont été centraux lors de la conception de la cellule Gm. Pour étendre au mieux la plage de réglage du filtre, un système, dit à commutation de Gm, agissant sur l’étage d’entrée, a été implanté. Il a comme avantage majeur de ne pas insérer de commutateurs sur le chemin du signal. Ce filtre occupe, pour sa partie active, une surface de 0.23 mm\textsuperscript{2}. Sa plage de réglage s’étend de 7.4 MHz à 27.4 MHz, le rendant ainsi parfaitement adapté à une intégration dans des récepteurs de type « Low-IF » et « Zéro-IF ». De plus, son affaiblissement, allant jusqu’à 66 dB/octave, permet une forte atténuation des interférences hors bandes, idéal pour les applications PRS. Le filtre consomme, respectivement, pour Fc minimum et maximum, 2.1 mA et 7.5 mA. Le point d’interception du troisième harmonique (IIP3), a été mesuré à -1.3 dBV\textsubscript{RMS}, et la mesure de l’erreur de non-linéarité de phase montre un résultat inférieur à 6.2°, ce qui satisfait pleinement l’exigence particulièrement stricte des systèmes PRS en ce domaine.

Mots clés : Galileo, global navigation satellite system (GNSS), Global Positioning System (GPS), Beidou, front-end, receiver, reconfigurable, complementary metal-oxide-semiconductor (CMOS), multi-frequency, multi-constellation, application-specific integrated circuit (ASIC), low-noise amplifier (LNA), passive mixer, gyrator, operational transconductance amplifier (OTA), quality factor (Q), active inductors, active filter, continuous-time filters, Gm-C, quality factor (Q) enhancement, common-mode stability, selectivity enhancement, resonator, analog-to-digital converter (ADC), variable-gain amplifier (VGA), wide-tuning-range filters, elliptic, public regulated service (PRS), zero-IF; low-IF; voltage-controlled oscillator (VCO)
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The global navigation satellite system (GNSS) is a constellation of satellites that provide autonomous geo-spatial positioning with global coverage. It allows small electronic receivers to determine their location (longitude, latitude, and altitude) within a few meters using time signals transmitted along a line-of-sight by radio from satellites.

Currently, the GPS, operated by the United States, is the most widely used GNSS system in the world. Due to some security reasons as well as the large demand and potential market of consumer electronics, some other countries have begun to develop their own GNSS systems. Currently, besides GPS, there are three main GNSS systems; including GLONASS from Russia, Galileo from the European Union and Beidou (COMPASS) from China. While GLONASS is the second fully operational GNSS (together with GPS), Galileo has launched 10 navigation satellites (as of February, 2016) and its initial services will be made available by the end of 2016. The Galileo system is scheduled for completion in 2020. Additionally, China is constructing the next-generation GNSS BeiDou-2 (BD-2) (also known as COMPASS), and the systems will also be expanded into a fully operational GNSS by 2020 [1].

Any of these systems can be optimized or made functional for specific geographical regions, which necessitates that the forthcoming GNSS receivers have backward compatibility among these different standards and constellations. Although the Galileo and Beidou systems are not yet fully functional, it is clear that there will be a great increase in satellite by the availability of these two systems, which brings opportunities for interoperation among different constellations and challenges the engineers to exploit them.

1.1 Motivation

The interoperability among the GNSS increases the number of available satellites for a GNSS receiver, thus can help to improve signal reliability in hostile environments, and system reliability in the case of malfunctioning of one of the constellations. It also enables the receiver to select the highest quality available signals which results in faster operation [2]. These can
be achieved at the cost of a reconfigurable radio front-end that can support multiple GNSS systems.

Besides reliability, the positioning accuracy is another concern of GNSS receivers. One optimization method that is generally applied as an answer to this concern is that of a multi-frequency receiver. Excellent accuracy for many applications is currently achieved using only single-frequency receivers, mainly by means of the ionospheric error modeling or differential corrections. The simultaneous reception of two or more signals from the same GNSS system that exhibit a sufficient frequency gap makes it possible to minimize the error introduced by the first-order ionospheric group delay [3] and as a result offer an even greater degree of accuracy. Therefore, in the coming years, multi-frequency multi-constellation receivers are likely to become the product of choice for accurate positioning and personal navigation in hostile signal environments. This is one of the challenges that is going to be addressed during the course of this thesis.

The deployment of Galileo will bring not only an additional GNSS constellation for existing applications, but also a series of new services that will require advanced wide-band receivers and front-ends to be able to process the upcoming modulations at these new frequencies for improved accuracy, reliability and robustness. One of these new services is a PRS, in which wide-band signals transmitted on two different carrier frequencies and designed to provide position, velocity and timing information to specific user groups requiring high continuity and robustness of services, with controlled access ensured by encryption of ranging codes and navigation data. This new service demands an advanced wide-band receiver, another challenge that will be addressed in this thesis.

At present there is no commercial chip addressing a multi-band PRS GNSS receiver, and it is still difficult to predict when multi-frequency GNSS FEs will reach the consumer market (even if the trend is clear, [4]). However, if we look at present and future high-end and professional applications, it seems clear that there could be a market for such a product. In this sense, the possibility of offering a multi-frequency front-end (MFFE) ASIC capable of covering several GNSS bands and with a sufficiently large bandwidth to cope with most GNSS signals could represent a significant advance toward the reduction in cost and size of non-mass-market receivers.

\section*{1.2 Thesis organization}

Two main objectives are pursued in this thesis. The first is to provide a solution for multi-frequency PRS receivers that meets the requirements of the PRS to serve specific users, authorized governmental bodies, requiring a high continuity of service. The second objective is to design and implement a multi-frequency multi-constellation GNSS FE to treat the public demands for mass market applications.

In this regard, a summary of GNSS signals and services are presented in this chapter. It also
presents the advantages and drawbacks of a few important FE’s topologies and architectures. Moreover, the most recent ASIC GNSS FEs are compared to provide a better insight in regards of the architecture selection. A study on the technology choice is presented at the end of this chapter that explores the trade-off of the technology scaling in the FE design.

Chapter 2 is focused on the PRS ASIC FE design. Possible applications for the PRS are discussed at the beginning of this chapter. The proposed FE architecture is presented afterward. The PRS FE specifications are laid out in this chapter that is followed by sub-systems design. The chapter is concluded by presenting the FE’s measurement results.

A wide-tuning-range continuous-time low-pass filter that is designed for the PRS receiver is presented in chapter 3. This chapter starts by presenting a Q-enhancement method that enhances the selectivity of the filter. It is followed then by the proposed methodology to ensure the CM stability of a gyrator-based resonator. At the end of this chapter, the filter measurement results and the effects of the Q-enhancement method on the selectivity of the filter are presented.

Chapter 4 is dedicated to the design of the multi-frequency multi-constellation GNSS FE that accommodates the simultaneous reception of the Beidou-B1, GPS-L1 and Galileo-E1. The FE’s architecture selection and frequency plan are presented at the beginning of the chapter. Then system specification were derived for all the sub-systems. This chapter also contains the sub-systems design and is concluded by presenting measured characterizations of the FE.

Finally, chapter 5 summarizes all the achievements of this thesis and outlines its perspectives.

1.3. GNSS signals and systems

1.3.1 GPS

Conceived and operated by the US Department of Defense, GPS is the most widely used navigation system today. When it became operational in 1995, it was initially transmitted in two bands only, L1 (centered at 1575.42 MHz) and L2 (1227.6 MHz) [5]. L1 comprises both open and restricted signals intended for civil and military applications, respectively, while L2 has no open counterpart. The open signal from L1 is often named C/A or Coarse Acquisition since it was intended to provide relatively simple and fast means of acquisition to speed up the process for the encrypted military signals. The protected transmissions from L1 and L2, designated as P(Y), use secret PRN codes to avoid signal tracking by non-authorized users. However, many codeless techniques have been developed to use P(Y) signals as a positioning aid for high precision commercial applications (for the removal of the ionospheric error using a dual frequency receiver) even with degraded performance.

As part of the GPS modernization plan, an additional civilian band is being enabled at
1227.6 MHz, called L2C. Additional improvements include the upgrade of L1 both for civilian (L1C) and military applications (so called M-code designed to replace P(Y) at L1 and L2). A new band L5 at 1176.45 MHz was recently added for Safety of Life applications. The spectra of all GPS signals with their respective carrier frequencies and modulations are shown in Figure 1.1.

Figure 1.1 – Spectra of all GPS signals with their respective carrier frequencies and modulations.

1.3.2 Galileo

Created as an alternative to GPS and GLONASS, Galileo is the satellite navigation system being developed by the European Union and the European Space Agency. This system is not yet fully operational. However, the fully functional Galileo constellation will transmit three bands of signals, including E1, E5, and E6 centered at 1575.42 MHz, 1191.795 MHz, and 1278.75 MHz, respectively. E1 supports open service (OS) and E6 supports Commercial Service (CS) while PRS is supported by both of these bands. E5, which is usually expressed as two sub-bands, E5a and E5b, centered at 1176.45 MHz and 1207.14 MHz, respectively, supports the OS, Safety of Life and Galileo system integrity [6]. Galileo signals and services with their respective bands and modulations are depicted in Figure 1.2. A brief overview of these services is presented below. For more details refer to [7].

1.3.2.1 Open service (OS)

The OS will operate in two bands, E5 and E1. E1B and E1C, the OS components of the E1 band, are data and pilot respectively, transmitted together in anti-phase using a CBOC(6,1,1/11) modulation with data rate of 250 bps. The CBOC(6,1,1/11) modulation is a BOC(6,1) component added to a BOC(1,1), 1/11 being the power ratio between this BOC(6,1) and the total transmitted signal. Due to the simplicity of the BOC(1,1) component that comprises most of the signal power, many receiver designs focus on the detection of this component instead of the whole CBOC signal [8]. More sophisticated receivers will be able to take advantage of the
1.3. GNSS signals and systems

![Spectra of all Galileo signals with their respective carrier frequencies and modulations.](image)

superior multi-path properties of the CBOC modulation by implementing a larger channel bandwidth and processing the full E1 signal.

Since E1 shares its carrier frequency (1575.42 MHz) with GPS L1, making the two compatible with the use of the same radio front-end, it is expected to become the band of choice for low-cost narrow-band receivers in consumer applications where a relatively inexpensive device will be able to take advantage of both constellations.

As a means to offer dual-frequency capabilities to OS users, an additional band was envisaged. Some advantages of making use of an additional channel are the increased interference resistance, higher bandwidth for navigation data and improved pseudorange calculation by reduction of the ionospheric error [9]. This signal is E5, centered at 1191.795 MHz, which can be processed as a single complex AltBOC(15, 10) modulation or as two separate components E5a and E5b. E5a is indicated particularly for double-frequency OS receivers for professional applications because 1176.45 MHz is also the carrier of one of the new GPS signals, L5, allowing manufacturers to design front-ends compatible with both constellations in a situation similar to E1/L1.

The sub-bands E5a and E5b have two components each. The in-phase components E5a-I and E5b-I carry navigation data, while the quadrature components E5a-Q and E5b-Q are pilot signals, ranging codes without data. The chip rate of these four components is 10.23 Mcps. The data rate of E5a-I is 50 bps, while E5b-I operates at 250 bps. The suggested receiver reference bandwidths, to have correlation loss due to payload distortions below 0.6 dB, are 24.552 MHz and 51.15 MHz for the E1 and E5 signals, respectively [7].

1.3.2.2 Commercial service (CS)

The signals from Galileo CS are transmitted in the band E6. There are two associated components, namely E6-B and E6-C, which comprise the data and pilot channels respectively. The chip rate will be 5.115 Mcps, and the data rate of E6-B will be 1 kbps. CS is expected to yield
improved navigation performance to users through a designated service provider that will restrict the access. These signals will provide a higher data rate and greater accuracy than the use of OS alone, with the addition of a service guarantee. These signals will support encryption. It may be possible to have a private operator restricting the access through commercial agreements with eventual customers, although regulation plans are still in progress and the exploitation plan is not public at this point.

### 1.3.2.3 Public regulated service (PRS)

The PRS is an encrypted navigation service designed to be more resistant to jamming, spoofing, and involuntary interference. It is encrypted, at both the PRN and navigation data levels, and access to the service will be strictly controlled by European authorities. This service ensures continuity of service to authorized users when access to other navigation services is denied. It also increases the likelihood of continuous availability of the signal-in-space (SIS) in case of interference. Thanks to the robustness of the signal, users will be protected on a daily basis against jamming and spoofing. Also, robust encryption mechanisms within the PRN signal will enable positive protection against spoofing.

PRS navigation signals are transmitted in two bands, E6 and E1, their PRS components called E6A and E1A respectively. They are shown in red in Figure 1.2. There is no publicly available SIS ICD for PRS, but Galileo in-orbit validation satellite vehicles currently in orbit are known to be using BOCc(15, 2.5) and BOCc(10, 5) modulations for E1A and E6A respectively. These signals are expected to be encrypted, at both the PRN and navigation data levels, and the access to the service will be strictly controlled by European authorities.

### 1.3.3 Beidou

Beidou (also called Compass) is the Chinese name for the prominent Big Dipper asterism, which historically served the purpose of navigation, now synonymously designating the satellite navigation system currently being developed by China. Beidou aims at providing China with its own navigation system for military uses, but recently there have been plans to support civil applications as well, both open and licensed services. It will use a combination of medium Earth orbit (MEO) and geostationary Earth orbit (GEO) satellites. There are two generations under development: Beidou-1 for regional coverage, and Beidou-2 for global positioning. The Beidou satellites transmit navigation signals in quadrature phase-shift keying (QPSK) modulation on three frequency bands (B1, B2, B3) which shares roughly the same frequency spectrum as Galileo on bands E1, E5b and E6 with the carrier frequency for B1, B2 and B3 at 1561.098, 1207.14 and 1268.52 MHz, respectively [10, 11]. This makes the design of multi-constellation receivers somewhat simpler, however increases the likelihood of inter-system interference. Beidou-1 signals along with their respective carrier frequencies and modulations are shown in Figure 1.3.
1.3.4 GLONASS

GLONASS, the Russian acronym for Globalnaya Navigatsionnaya Sputnikovaya Sistema or the Global Navigation Satellite System, is the counterpart of GPS devised by the Soviet Union during the end of the Cold War. Like GPS, it was initially intended for military applications, but eventually evolved to cover both military and civil users. The investment in the maintenance of the constellation by Russia decayed in the late 1990s, which greatly decreased its usability as a global positioning tool. In recent years, however, it has witnessed a revival and modernization by the Russian authorities. With the launch of the GLONASS-M satellites, two civil bands are used, designated L1 (1598.0625–1605.375 MHz) and L2 (1242.9375–1248.625 MHz), not to be confused with GPS L1 and L2 allocated at different frequencies. The GLONASS L1 and L2 signals are shown in Figure 1.4. The newer GLONASS-K1/K2 satellites are still undergoing testing but will bring additional signals and greater performance, and will be followed by the GLONASS-KM series, currently under development [12]. Like other GNSS constellations, GLONASS uses direct-sequence spread spectrum (DSSS) modulations for their ranging signals but, unlike GPS or Galileo, all satellites use the same PRN, each of them transmitting in a separate frequency (frequency division multiple access (FDMA)). Channel spacing is 562.5 KHz for GLONASS L1 and 437.5 KHz for L2, and the same channels are assigned to antipodal pairs of satellites to reuse frequencies. In both cases the ranging code is a sequence with a period of 1 ms and bit rate of 511 kbps and data are transmitted at 50 bps [13].

1.4 GNSS radio-frequency front-end (RFFE)

The front-end is the section between the antenna and the baseband processor that amplifies and filters the signal, shifts its frequency, and digitizes it. Section 1.4.2 will summarize the main architectural options available for GNSS front-ends. The most general distinction that can be made is whether these front-ends are designed to handle a single band or several. Sections 1.5.1 and 1.5.2 present a literature review of GNSS single-frequency front-ends (SFFEs) and
Chapter 1. Introduction

Figure 1.4 – Spectra of GLONASS L1 and L2 signals with their respective carrier frequencies and modulations.

MFFEs, respectively.

1.4.1 Front-end topology

1.4.1.1 Direct conversion

Direct conversion is the simplest front-end topology that downconverts the RF signal directly to the baseband. This topology does not need any explicit image rejection mechanism. In order to avoid aliasing and remove the out-of-band interferers, the baseband signal can simply be filtered with a low-pass filter.

The simplicity of this topology is really appealing, however, it has drawbacks, including the voltage offsets due to process mismatches and the high level of the low-frequency noise. The voltage offsets can be dealt with by additional circuitries that effectively acts as a very sharp high-pass filter around 0 Hz [14]. Low-frequency noise such as flicker can be reduced through circuit optimization but it is mainly technology-dependent.

Since the main drawbacks of the direct-conversion receivers are in the low-frequency sections of the front-end, the direct conversion topology is not suitable for open service GNSS signals because a significant amount of signal’s energy is around the carrier frequency. However, it is of interest for those of binary offset carrier (BOC) modulated GNSS signals that have their energy concentrated in an offset from the carrier.
1.4. GNSS radio-frequency front-end (RFFE)

1.4.1.2 Low-IF

The low-frequency problems of direct conversion are avoided in a so-called low-IF topology which downconverts the RF signals to an intermediate frequency, low enough to allow inexpensive sampling while sufficiently high to cancel DC offsets with simple high-pass filters. In fact, most GNSS receivers sample the signals at IF instead of performing a direct conversion to the baseband. This has the advantage of showing a lower noise figure (NF) due to the absence of the flicker noise, particularly important in silicon-based technologies, around the IF. Moreover, thanks to the intermediate frequency, the low-IF topology also offers a certain flexibility to compensate for DC offsets: the low-frequency variations caused by component mismatches or LO self-mixing.

However, this topology suffers from an image problem, which has to be filtered out somewhere in the front-end path. Depending on the frequency plan and a downconversion scheme (real or complex) of a receiver, this image can be filtered in RF prior to or after the digitization. In fact, in the real low-IF downconversion, there is no choice but to eliminate the interferer (image) prior to the mixing, while in complex downconversion the image can be eliminated by means of a complex filtering prior to or after the digitization. Due to the flexibilities and benefits that the low-IF topology offers, it has become the most common topology for mass market GNSS receivers.

1.4.2 Radio architectures

This section introduces architectures suitable for MFFEs, with special emphasis on multi-channel receivers with the ability to track several bands simultaneously.

1.4.2.1 Broadband front-end

The simplest approach for a single-channel multi-frequency front-end is a system with a broadband or multi-band LNA/filter at its input and a wide-band frequency synthesizer able to be tuned for all bands of interest. Figure 1.5 shows a complex downconversion broadband front-end. The disadvantage of this approach is that the IF sections must be able to process all the possible signals, and the broadband designs can be difficult to implement and excel their narrow-band counterparts. The input RF filtering should reject as much out-of-band power as possible, which means it should not show a wide-band response but rather a combination of narrow band-pass or even multi-resonant structures to let only those signals of interest go through. The simplicity of this front-end makes it appealing to receive the bands that do not have a wide frequency interval such as GPS-L1 and Beidou-B1.
1.4.2.2 Front-end arrays

In order to have several channels working simultaneously and optimized to their respective bands, the obvious solution is to multiply resources to accommodate as many channels as needed. Figure 1.6 shows a two-channel front-end. Each channel can have its own power control to be switched off when it is not needed. It also allows channels to share some basic resources such as power supplies, references and clocks, particularly in the frequency synthesis [2, 15]. Moreover, one or more of these channels can present nearly any multi-frequency architecture to be able to receive different combinations of signals. The use of a switching mechanism in the RF section of this front-end can enable the possibility of connecting different channels together [16].

1.4.2.3 Overlay front-end

In order to reduce the power consumption of the front-end array, it is possible to share the baseband amplification and ADCs as is shown in Figure 1.7. The idea is to overlap two or more bands in the same bandwidth to share the low-frequency sections by pre-amplifying and filtering each in a specific manner to optimize performances [17]. This exploits the characteristics of GNSS signals, i.e. the high spreading rates of the signals and the spectral separation provided by the use of different modulations, in some cases with a remarkably low theoretical performance degradation. The drawback is the noise floor degradation (up to 3 dB within the overlap) when the conversion frequencies are chosen so that the bands overlap; the advantage in such a case would be the reduction of the cost, size, power consumption, and digital bandwidth [17].

1.4.2.4 Front-end with additional frequency translation

Following the trend from front-end arrays to the overlay front-end, the cost, size, and power consumption can be further reduced by unifying the different paths of the overlay front-end as is shown in Figure 1.8. However, this front-end requires additional (one or more) fre-
1.4. GNSS radio-frequency front-end (RFFE)

Figure 1.6 – Front-end arrays.

Figure 1.7 – Dual-frequency overlay front-end.

Frequency translation to bring the spectrum of the additional signal close to the downconversion frequency of the main front-end.

The main front-end can employ the zero-IF or low-IF topology. Similar to the overlay front-end, thanks to the high spreading rates of the GNSS signals and spectral separation provided by the use of different modulations, these two bands can overlap, be placed adjacent
to each other, or even switched. Due to the high level of hardware reuse, this front-end is more vulnerable to interference compared to the overlay front-end. It will also suffer from a 3 dB noise degradation if the bands overlap.

### 1.4.2.5 Direct sampling front-end

The simplest approach from a theoretical point of view is the sampling of the signal or signals at a RF after the amplifying and filtering as is shown in Figure 1.9. This strategy poses many technical challenges as this sampling has to be very accurate and all the amplification must take place at high frequency. However, it has been proposed for the GNSS applications in [18]. A careful selection of the ADC sampling rates allows the receiver to place aliasing replicas of different bands close to each other in the digital domain. Therefore there are many restrictions on the frequency planning, such as the sampling and intermediate frequencies being directly related, thus reducing flexibility. Extending this technique to several bands becomes even more complex and restricted, since the receiver requires multi-resonant filters or power splitters and combiners to be able to selectively reject the multiple images. The front-end requires minimal hardware compared to the others mentioned above. Once the signals of this multi-frequency front-end are filtered, they can be amplified and sampled together. However
1.5 State of the art

1.5.1 Single-frequency front-end

In the last years several integrated circuit (IC) front-ends for GNSS receivers have been reported in different technologies, showing a growing increase in performance and a steady reduction in power consumption. Table 1.1 shows a summary of the single-frequency IC front-ends with a channel bandwidth greater than 4 MHz, hence able to receive at least the GPS L1 C/A and E1bc OS Galileo signals. However, due to the limited bandwidth of the receivers in Table 1.1, no receiver is capable of treating PRS Galileo signals. Nevertheless, it is useful to have a basic idea of low-end receivers for comparison, especially in terms of noise figure, ADC resolution, receiver topology and power consumption for one channel.

1.5.1.1 Channel bandwidth (IF-BW)

A 4 MHz channel bandwidth is the common choice among the low-end GNSS receivers. However, if the receiver is intended to acquire L5/E5a, it needs a wider channel bandwidth. The widest channel bandwidth reported is 20 MHz in [19], which is barely enough to fully...
include the main lobe of the E5a signal.

1.5.1.2 Topology

The most common architecture for GNSS radios is the low-IF with image rejection mixer. In fact, if the intermediate frequency is chosen so that the image band lies within the GPS band, so that this image is substantially white noise, the low-IF topology allows alternating current (AC) coupling in the IF chain. This eliminates the DC offset problem and low-frequency noise (flicker and on-chip noise).

1.5.1.3 Intermediate frequency (IF)

It can be seen in Table 1.1 that the IF choice is driven by two factors: the IF bandwidth (a large bandwidth requires a higher IF) and the power consumption. Indeed a lower IF is preferable because the amplifiers can be designed with a lower gain-bandwidth product (GBW) resulting in lower power consumption.

1.5.1.4 Noise figure (NF)

The average NF is around 3 dB, but it is not clear which front-end includes electrostatic discharge (ESD) protection on the antenna input pad. Therefore it is difficult to determine the best solution for the LNA in terms of NF.

1.5.1.5 Voltage gain

The overall voltage gain is between 103 dB and 119 dB and the automatic gain control has a range of 50–60 dB. Gain depends on several parameters such as noise bandwidth, ADC dynamic range/precision and linearity requirements. The front-end with the larger IF-bandwidth (BW) requires less voltage gain [19].

1.5.1.6 Linearity

Since linearity requirements depend on the system applications, no clear common linearity requirement could be extrapolated from the different implementations. In fact, some receivers are intended for a stand-alone operation, in which the linearity requirements can be relaxed. On the other hand, those requirements are usually more stringent for receivers that are intended to operate together with other wireless systems, such as in mobile terminal where the Global System for Mobile Communications (GSM) and GPS coexist [23].
1.5. State of the art

1.5.1.7 Image rejection

The image rejection capability achieved with the image rejection mixer is around 30 dB. However, it was boosted to 40 dB by employing the active polyphase filter in [23, 25]. The same image rejection was achieved in [21], which could exploit the surface acoustic wave (SAW) filter selectivity by having its IF high enough.

1.5.1.8 Synthesizer

Most solutions use a VCO that runs at twice the required frequency and a divide-by-2 to ensure accurate quadrature phase generation for the complex mixer LO inputs. An integer-N PLL with a standard reference of 16.368 MHz is widely used for low power consumption, even if a fractional-N PLL allows the use of different clocks in embedded systems. Typically a phase noise of -105 dBc/Hz at 1 MHz is sufficient even if a better performance is achievable.

1.5.1.9 ADC and AGC

Increasing the number of bits in the ADC used in a receiver system such as the GPS will increase the signal-to-noise ratio (SNR) only moderately; therefore most of the solutions use 2 bits. However, to improve the immunity to jamming signal, the ADC is preferred to have more bits such as in [22, 25]. The sampling frequency is derived from the reference signal or generated by dividing the LO if the IF is higher than the reference. A loop that sets the duty cycle of the MAG signal (most significant bit (MSB) of the ADC) at 33%, which is known to provide negligible SNR loss, is typically used for automatic gain control (AGC) [16, 26, 27].

1.5.1.10 Area

The average layout area is 5 mm², which easily fits with most of the commercially available packages with more than 28 pins. Moreover it appears that using a more scaled technology does not significantly pay in terms of layout area saving. Indeed the difference between implementations with the most scaled technology [20] and the less scaled technology [24] is less than 10%. Moreover, the extreme area reduction in [25] is achieved by embedding the source-degeneration inductor of the LNA in the fan-out area of the package.

1.5.1.11 Power consumption

Power consumption between around 13 mW and 45 mW is shown for CMOS technology regardless of scaling nodes. In fact, the power consumption is determined mainly by the channel bandwidth and the linearity requirements.
Table 1.2 – Literature review of multi frequency GNSS receivers with more than 4 MHz of channel bandwidth.

<table>
<thead>
<tr>
<th>References</th>
<th>[28]</th>
<th>[29]</th>
<th>[30]</th>
<th>[15]</th>
<th>[2]</th>
<th>[31]</th>
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<td>E1/E5</td>
<td>E1/E5b</td>
<td>L1/E1bc</td>
<td>B1/Glonass</td>
<td>L1/E1bc</td>
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<td>Low-IF</td>
<td>Low-IF/Zero-IF</td>
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<td>-</td>
<td>2.7/2.5</td>
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<td>112/115</td>
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<td>125</td>
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<td>-</td>
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<td>28/23</td>
<td>50</td>
<td>50</td>
<td>45</td>
<td>33</td>
<td>49</td>
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<tr>
<td>OIP3 [dBm]</td>
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<td>-</td>
<td>-</td>
<td>-</td>
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<tr>
<td>Tech [nm]</td>
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<td>45/ch (90)</td>
<td>44/ch (88)</td>
<td>41.4</td>
<td>26</td>
<td>36.24/ch (72.48)</td>
</tr>
</tbody>
</table>

1 One channel switchable, 2 extrapolated by $I_{-P1d}$ = -61 dBm, 3 in band IIP3, 4 IF frequency varies depending on which two constellations are chosen, 5 with off-chip SAW.

1.5.2 Multi-frequency front-end

This review considers recently published works on multi-frequency front-end (MFFE) GNSS receivers. Given that modern GNSS signals have a bandwidth of more than 4 MHz, only the receivers that offer a channel bandwidth larger than 4 MHz are considered in this review.

Table 1.2 compares measured performances of IC MFFE GNSS receivers. At present there is no IC MFFE intended for high-end or PRS applications. Indeed, the reported works aim more toward OS bands E1bc and E5 or their GPS counterparts. The very recent MFFEs tend to operate in multi-constellation mode and receive all the GNSS constellations. Due to the low cost and good RF performance, the CMOS technology has been adopted for all the reported MFFE implementations.

In addition to the detailed specifications in Table 1.2, an overview of the architectures is helpful in understanding the key points of wide-band GNSS MFFE design. Toward this end, a brief analysis of the architecture and IF design of the receivers in Table 1.2 is presented below.

In 2008, Detratti et al. in [28] presented one of the first GNSS front-ends capable of receiving both GPS and Galileo signals. Indeed, the proposed front-end in [28] is a dual-frequency reconfigurable front-end intended for the L1/E1 and L5/E5a bands. In order to offer the dual-frequency reception, the front-end employs two LNAs with their respectively tuned SAW filters whose outputs are selected with an external active switch that determines which band is to be demodulated. However, there is no simultaneous reception of the two bands in this low-IF architecture. In fact, the dual-frequency reception became possible due to a broadband frequency synthesizer and those aforementioned LNAs. The front-end also includes a double quadrature mixer followed by a real low-pass filter (LPF); thus the image
rejection is realized only in the digital domain. The LPFs have their cut-off frequency at 9 MHz and are AC coupled to prevent offset errors. The external baseband processor can use the double-side complex bandwidth of the I/Q outputs comprising the interval [-9 MHz, 9 MHz] minus the power around direct current (DC) due to the AC coupling. Even though this bandwidth is sub-optimal compared to the total bandwidth of E5a, it is still sufficient for the intended application according to their own studies. This front-end is designed for low noise and high linearity to withstand interference, but the total power of this front-end is about 110 mW, not including ADCs.

The simultaneous reception of E1/L1 and E5a/L5 has been achieved in the dual-band receiver presented in [29]. The front-end consists of separate RF and IF channels: one tuned for E1/L1 and the other one for E5a/L5. However, to reduce power consumption, the LNA in the E1 band is shared with the E5a band. Both front-ends in [28] and [29] have the same architecture as well as low-IF topology. Although the input stage of the mixer in [29] is single-ended, the VCO adopts complementary cross-coupled topology for low power dissipation. The IF section of both channels is composed of a VGA, the channel selection filter and the AGC blocks. In the case of the L1/E1 band, the central frequency and the bandwidth of the downconverted signal are 4 MHz. A 3rd-order complex band-pass filter (BPF) is used for channel selection and image rejection and there is no need for a polyphase filter (PPF), which relaxes the gain specification of the VGA. On the other hand, the channel selection filter has to process 24 MHz bandwidth L5/E5a at the IF frequency of 12 MHz. Therefore, a 3-stage passive PPF as well as a 3rd-order active-RC LPF are used as channel filters to cover the frequency specification of the L5/E5a band. As already mentioned, the front-end in [29] is capable of simultaneous reception of both L1/E1 and L5/E5a. However, sharing the LNA for both bands is not the best choice from the point of view of interference mitigation. If the LNA falls in intermodulation, or worse in saturation, due to an interference in one channel, it is not possible to avoid the intermodulation on the other free channel.

In 2009, Miskiewicz et al. from Infineon Technologies proposed a single-chip radio receiver capable of receiving GPS, Galileo, UMTS, CDMA2000 and GSM standards [30]. The proposed analog zero-IF front-end employs two wide-band paths for the high- and low-band operation with one integrated wide-band VCO. In order to optimize the size of the chip and power consumption, both paths are combined at the mixer, using a switch. The front-end features a reconfigurable analog baseband filter that is suitable for all implemented standards and offers a high selectivity at interferer frequencies. The analog path is ended by two I/Q (in-phase and quadrature) ΣΔ ADCs followed by a digital front-end performing the channel filtering, adaptation of the system data rate to the common bit rate at the digital interface, the correction of the group delay generated in the analog baseband filter and the removal of the DC offset. The overall transfer characteristic of the IF section has a corner frequency of 240 KHz for GSM, 750 KHz for CDMA2000, and 2.5 MHz for UMTS and GPS/Galileo standards, respectively. The bandwidth of the filter is tuned with a capacitive bank controlled by a 5-bit programmable word. The front-end has a high level of hardware reuse; only LNAs and pre-selector filters are channel dependent to achieve the simultaneous reception of GPS/Galileo and UMTS signals.
Chapter 1. Introduction

In [15] a reconfigurable dual-channel RF receiver that meets the demands for separate or simultaneous reception of all-modes and all-bands of the GNSS signals is presented. Two independent FSs, based on integer-N PLLs, provide wide-tuning-range quadrature LO signals for each channel. In each I/Q branch, a programmable gain amplifier (PGA) precedes the complex BPF to relax its noise requirement and optimize the linearity performance. A fully differential operational amplifier (opamp) with resistive feedback is utilized to realize the PGA for low noise and high linearity. A 5th-order Chebyshev-I complex BPF, based on fully differential active-RC integrators, is implemented by means of two real LPF quadrature coupled to achieve the frequency shift at IF. In order to reconfigure the center frequency of IF, bandwidth and gain, all the capacitors and resistors in the filter are implemented as binary arrays. Moreover, an automatic digital RC tuning block guarantees the frequency accuracy of the IF and the bandwidth. The proposed front-end has almost no hardware reuse. In spite of this, its power consumption of 45 mW/ch is in line with other architectures with more hardware reuse. Moreover, two independent synthesizers allow the reception of any two bands at the same time. The 20 MHz of bandwidth is enough for E5a, but is not enough for PRS even though the channel could be switched to E6. The bandwidth of the E1 channel is insufficient for E1-a PRS as well. However this is a good starting point for a hypothetical extension toward the PRS receiver.

In 2012, Qi et al. in [2] presented a front-end very similar to the one in [15] that supports Compass/GPS/GLONASS/Galileo. It employs two independent channels with single-conversion architecture for simultaneous dual-frequency signal receiving. However, contrary to [15], a single fractional frequency synthesizer is shared by both channels, and an extra clock generator provides programmable sampling and reference clocks for the ADCs, filters and digital logic circuits. A reconfigurable filter is placed ahead of a PGA in each channel to provide image rejection and out-of-band interference rejection. In order to get accurate frequency selectivity for all operation modes, the IF filter is capable of switching its order, type, center frequency and bandwidth. The receiver is configured to the low-IF architecture using a 5th-order complex BPF, while for some wide-band applications it is reconfigured to zero-IF architecture using a 3rd-order LPF. Moreover, all OTAs in the filter are arranged into arrays, some of which can be shut down in low center frequency or narrow-bandwidth modes to save power. Moreover an I/Q calibration module is presented to enhance the image rejection where it achieved up to 20 dB of improvement. Due to the reuse of the synthesizer, only the reception of the neighboring band is possible, and it is, therefore, not possible to receive E1 and E5 at the same time.

In 2013, Qi et al. developed his receiver’s architecture in [2] and proposed a dual-channel multi-constellation receiver as in [31] that can receive GPS L1, Galileo E1bc, Beidou B1 as well as GLONASS L1. Similar to the one in [2], the receiver features a simultaneous dual-system signal reception for all the combinations of the GNSS signals except the pair of GLONASS-Beidou. The proposed receiver is composed of two channels that adopt the low-IF architecture in which the RF section and the FS are shared. In this case, however, the IF sections are independent from each other. Each IF section consists of an I/Q mismatch calibration prior to
the complex bandpass filter. The complex filter is used to remove the image and is followed by a digitally controlled PGA to regulate the signal strength delivering to 2–4 bits ADC. Similar to the receiver in [2], the RF section is composed of an LNA, a noise-canceling RF amplifier and a Gilbert quadrature mixer. However, in this development, not only the FS but the whole RF section is shared between two channels, which provides more hardware reuse. The reconfigurable filter and the synthesizer result in a different IF bandwidth from 2.2 MHz to 10 MHz as well as different IF frequencies range from 3.996 MHz to 13.29 MHz in different configurations.

More recently, Tan et al. proposed a receiver featuring the highest degree of hardware reuse in [32]. The receiver is a one-channel reconfigurable low-IF quadrature receiver with a fractional-N FS, and a digital baseband processor. It downconverts the GNSS signals as an image of one another and then separates them in the digital domain. The FS is reconfigurable to provide three LO signals which result in three cases of dual reception: In the case of simultaneous GPS/Galileo and GLONASS dual reception, the LO is set to 1588.608 MHz; in the case of simultaneous GPS/Galileo and Beidou dual reception, the LO is set to 1568.256 MHz; and for GPS/Galileo-only reception, the LO is set to 1571.328 MHz. The front-end features a noise-canceling inductorless wide-band LNA driving a current-driven quadrature passive mixer. The mixer is followed by a cascade of two reconfigurable Butterworth biquad filters where the second filter has a variable gain and performs also as a PGA. A 9-bit successive approximation register (SAR) ADC is employed in each I and Q channel to accommodate large interferer signals.

The last receiver in Table 1.2 was proposed by Li et al. in [16]. It is a fully integrated reconfigurable all-band RF transceiver for GPS/GLONASS/Galileo/Beidou. The receiver employs two RF front-ends with different matching network to process the GNSS signals around 1.2 GHz and 1.6 GHz carrier frequencies. Moreover, two independent IF channels with constant IF frequencies of 15.902 MHz and 15.48 MHz are incorporated. The receiver also features a digitally assisted calibration scheme to compensate analog parameter variations. It incorporates the switching scheme proposed in [30] to connect the RF front-ends and IF channels. This reduces the complexity of the IF channels and the die area of the eventual receiver. In order to process all GNSS signals with different bandwidths, one of the IF channels is designed to provide 2/4 MHz bandwidth to process narrow-band GNSS signals such as GPS-L1/L2, Galileo-E1 and Beidou-B1. On the other hand, the other IF channel provides 10/20 MHz bandwidth and deal with wide-band GNSS signals, such as GPS-L5, GLONASS-L1/L2, Galileo-E5a(b), and Beidou-B2/B3. The receiver uses two FSs to provide flexible frequency planning to receive any combination of two mentioned GNSS signals. This is possible thanks to the switching module that connects the RF sections and IF channels. Note that the simultaneous dual reception of some signals with the same or close bandwidth happens in the same IF channel owing to the fact the GNSS signals are uncorrelated. To see the advantage of this method, let's compare it with the other methods utilized in [15,31,32] which make the simultaneous reception possible. In [15,31], two independent IF channels are utilized to provide the simultaneous reception, which requires a bandwidth-reconfigurable IF channel and as a result increases the design
complexity and die area. Moreover, due to the limited flexibility of the IF channels in [15, 31], in some cases two identical receivers must be used to provide the simultaneous reception. On the other hand, only one receiving channel is incorporated in [32] to receive dual-band GNSS signals simultaneously, which decreases the complexity, die area, and mostly current consumption compared to the dual-channel ones in [15, 31]. However, the receiver does not provide the image rejection function, and therefore the SNR will be degraded at least 3 dB and the baseband processor will require an IF filter to filter out the out-of-band noise. Moreover, due to the limited bandwidth of the LPF and narrow-tuning VCO, the signals processed in [32] are only bandwidth-limited signals centered around 1.6 GHz.

1.5.3 Conclusion

As can be seen from the study of the state of the art on the recent RF front-ends, there are currently no viable options readily available for ASIC front-ends to be used for the PRS signals. Many designs exist for different combinations of the GNSS bands, but none of them is suitable for PRS due to the size, power, bandwidth or linearity requirements demanded for a secure and compact GNSS receiver. This however indicates that extending the current technology to satisfy these requirements is feasible as there are many alternatives for ASIC multi-frequency front-ends. The required bandwidth and frequency range for PRS are along similar lines to recent developments, even though PRS is more demanding in terms of both bandwidth and linearity, which will mean more power and overall cost for the front-end.

1.6 ASIC technology choice

The effects of deep sub-micron scaling of CMOS technologies in analog ASIC designs is explained in this section. Considering the advantages and disadvantages of these technologies will help us to choose the level of integration among the 180, 130 or 65 nm CMOS technologies.

In the last decades the scaling trend in CMOS technologies towards greater degrees of integration has not stopped and is expected to follow a similar progression in the immediate future. This evolution has allowed faster circuits (higher operating frequency), greater density (more functionality per area unit) and lower power/more complex designs for a given power budget. All of these are translated into increasing processing power/cost ratios every year [33]. Nowadays ASICs are mixed-signal systems that consist of a digital core with analog interface blocks such as mixers, LNAs, synthesizers and so on. It is preferable to integrate all the analog and digital modules on a single die. The evolution towards deep submicron in CMOS technology is very beneficial for digital circuitries (increasing circuit speed and density). However, this is not yet the case for analog circuits. Therefore, analog circuits must cope with the CMOS evolution dictated by the digital circuit [34].

The power consumption of analog circuits is proportional to the signal frequency and the specification of the system such as the NF. In other words, higher performance analog
circuit design demand higher power consumption [35, 36]. For a given power budget, the analog performance degrades by incorporating newer technologies, because of their lower supply voltages. The supply voltage, for example, has dropped from 1.8 V in 180 nm to 1 V in 65 nm. The voltage degradation results in lower signal headroom which makes it difficult to design analog circuits with sufficient signal integrity at reasonable power consumption levels [37]. This is probably the main challenge to designing analog circuits at low supply voltages [36].

In the miniaturization of CMOS transistors (scaling down of the gate length), because of short-channel effects such as punch-through and hot-electron degradation [38], manufacturers generally require scaling down of the oxide thickness, reducing the junction depths, and increasing the substrate doping. Reducing the oxide thickness raises another issue which is gate leakage. The thin gates start to show quantum-mechanics-related effects (tunnel currents) that make the approximation of a perfect DC isolator no longer accurate. Despite the fact that the magnitude of these currents is still very low, this can become significant in ultra-low power applications [39]. It becomes more serious with gate leakage current mismatch, especially for long transistors. In fact, for long transistors, mismatch mainly means gate leakage mismatch. This effect puts a new upper limit on achievable matching performance. However, this problem can be addressed by increasing power consumption [36].

In the following, the main effects of submicron CMOS technology on the performance of analog circuits are gathered from scientific publications. It is followed by a performance review of some recent GNSS FEs in different CMOS technologies.

1.6.1 Limits of low power

The first constraint for analog circuits is low power consumption, for which we have to sacrifice speed or dynamic range, or vice versa. The absolute limit in analog circuits comes from the necessity to keep the energy of the signal larger than the energy of the noise, to achieve the required SNR [35]. This boundary does not directly depend on the technology but in sub-micron technologies the signal headroom becomes too small and makes it difficult to design circuits with sufficient signal integrity at reasonable power consumption levels. Therefore, in analog circuits, power is proportional to frequency and to NF. Thanks to new technologies we can fabricate low power circuits but keeping the same performance is always challenging.

There are also several technical obstacles on the approach of the low power design for analog circuits such as the poor power efficiency of some blocks and losses in bias circuitry. In downscaled processes with lower supply voltages, the coupling and noise through the substrate is higher, partially because of the limitations of the substrate and well bias [40, 41]. Therefore, sometimes noise that is produced by the chip due to the digital blocks may be orders of magnitude above the thermal noise, so to achieve the required dynamic range we require a proportional increase in power.
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1.6.2 Scaling and transistor properties

The CMOS technology evolution towards deep sub-micron alters the transistor characteristics. In order to analyze the influence of sub-micron technology in CMOS, we need to consider some of these characteristics.

1.6.2.1 DC properties at constant voltage headroom

Constant voltage headroom is the need to do fair comparison on the DC properties of CMOS transistors. However, due to the degradation of the supply voltage in the new technologies, these conditions are not usually satisfied.

Quasi-DC distortion (low distortion at quasi-DC frequencies) is typically caused by nonlinearities in the transistors’ transconductance ($g_m$) and in their output conductance. Nonlinearities of $g_m$ are almost constant over all technologies. But for the output conductance $g_{ds}$, it is totally different. It faces larger voltage swings than $g_m$ and is more dependent on biasing, size and technology [36].

Annema et al. in [36] have shown that the voltage loop gain at quasi-dc frequencies in transistors is dependent on $g_m/g_{ds}$ and its output conductance. They showed that, at constant gate-overdrive voltage ($V_{GT}$) and fixed drain-source voltage, the voltage gain of transistors decreases in newer technologies. However, with the same scaling, the output third-order intercept point (IP3) improves. Therefore, at a fixed transistor length and at constant voltage headroom, the quasi-dc circuit performance hardly changes over technology.

1.6.2.2 DC properties at decreasing voltage headroom

Since the supply voltage of analog circuits is decreased in the new CMOS technologies, the voltage headroom and signal swing of each transistor are also decreased.

It is shown in [36] that, with reducing the drain-source voltage and the signal swing proportional to the nominal supply voltage, but maintaining a constant transistor length, the $g_m/g_{ds}$ and output IP3 both decrease drastically. In this case, the amplitude of the higher harmonic components may increase; therefore the total harmonic distortion (THD) increases significantly too.

1.6.2.3 AC properties

The AC performance of transistors improves with the newer technologies. This is one of the main benefits of newer CMOS technologies for analog circuits. Transistors’ intrinsic and junction capacitances play an important role in the speed and bandwidth of the analog circuits.
1.6. ASIC technology choice

The impact of the intrinsic capacitances is almost the same for transistors in different technologies with a fixed length [42]. Approximately, the unity gain frequency \( f_T \) of transistors depends only on the effective gate-overdrive voltage and on channel length.

\[
f_T \approx \frac{g_m}{2\pi C_{ox} W L} \propto \frac{V_{GT}}{L^2},
\]

where \( C_{ox} \) is the oxide capacitance per unit area and \( W \) and \( L \) are the width and length of the channel, respectively. Therefore, in the newer technologies with shorter \( L \), the higher unity gain frequency is achievable. However, with the same transistor length (usually larger \( L \) to achieve good voltage gain and matching accuracy), the transistor’s intrinsic speed hardly changes over technology. In other words, there is always a trade-off between gain and speed via transistor length (see also [43]). In fact, it is possible to achieve higher bandwidths for analog circuits in newer CMOS technologies, but at the cost of degradation in quasi-DC performance.

Another aspect of AC performance is the junction capacitance. Toward the sub-micron technology the actual junctions become shallower approximately proportional to the technology size. Also, since the junction area scales in proportion to the minimum gate length while the dope level does not increase significantly, the capacitance per area decreases with newer CMOS technologies. This allows for better RF performance for CMOS circuits with technology evolution.

1.6.3 Review of the latest IEEE publications and commercial products related to L1 Galileo RF-FEs

Comparing FE receivers is not straightforward due to the number of parameters to take into account and the different ways in which they are measured or reported. In Table 1.3 we have selected parameters that are meaningful to chosen the technology and to distinguish which solution is suitable for receiving PRS or OS.

Table 1.3 underscores the fact that power consumption in the FE is mainly driven by requirements, such as linearity, NF and bandwidth. These are slightly affected by the scaling as shown by the comparison between [15, 50]. Both have very similar performances (NF, large IF-BW, number of bits) and architectures (two independent channels with a shared synthesizer) and also the same power consumption (around 45 mW per channel) despite their implementation respectively on 180 nm and 65 nm CMOS technology. Furthermore, we note that the lowest power consumption is in fact associated with the more narrow IF bandwidth (only OS) and worse NF, regardless of technology.

1.6.4 Conclusions

It is clear that the use of a higher density process leads to an immediate power and area reduction of all the digital blocks used in the FE. Moreover, the use of 65 nm CMOS tech-
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Table 1.3 – E1 Galileo RF FE comparison.

<table>
<thead>
<tr>
<th>References</th>
<th>Technology [nm]</th>
<th>Number of simult. CH</th>
<th>NF [dB]</th>
<th>IF-BW [MHz]</th>
<th>ADC bits</th>
<th>Input P1dB [dBm]</th>
<th>Die Area [mm²]</th>
<th>Power [mW]</th>
</tr>
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<td>&lt; 2.5</td>
<td>4</td>
<td>3</td>
<td>-18²</td>
<td>4.65</td>
<td>33.6</td>
</tr>
<tr>
<td>[2]</td>
<td>65</td>
<td>2</td>
<td>2.2</td>
<td>18</td>
<td>4</td>
<td>-61³</td>
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<td>65</td>
<td>1</td>
<td>2</td>
<td>4</td>
<td>2</td>
<td>-12⁴</td>
<td>1.4³</td>
<td>84</td>
</tr>
<tr>
<td>[44]</td>
<td>90</td>
<td>1</td>
<td>4.5</td>
<td>3</td>
<td>4</td>
<td>-38²</td>
<td>12.8</td>
<td>41.4</td>
</tr>
<tr>
<td>[24]</td>
<td>180</td>
<td>1</td>
<td>2.7</td>
<td>4</td>
<td>2</td>
<td>-40³</td>
<td>5.2</td>
<td>45</td>
</tr>
<tr>
<td>[15]</td>
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<td>2</td>
<td>8.5</td>
<td>20</td>
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<td>19</td>
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<td>2</td>
<td></td>
<td>5</td>
<td></td>
</tr>
</tbody>
</table>

¹ paper related to the commercial product [49], ² in band P1 dB related to the LNA and mixer only, ³ in band P1 dB, ⁴ out of band P1 dB, ⁵ only RF part area, including digital part is 6.6 mm², ⁶ power with only one channel active, ⁷ in tracking mode.

Technology would enable the future integration of the FE with purely digital functionality related to baseband processing, secure module or general purpose logic, aiming at a single-die solution. Nevertheless, analog circuits do not benefit from downscaling in the same manner as digital designs. The size of RF circuits is mostly determined by the size of the inductors, which depends on physical parameters such as the conductivity of the metalization and electromagnetic performance of the substrate, and not the mask resolution [51]; their physical dimensions for a given inductance value vary very little between circuit generations. Passive devices in general (resistors, capacitors, etc.) experience very few variations. In fact, published FEs with similar performances on different technology nodes have similar areas [20, 23, 24, 46].

Furthermore, based on the discussion in section 1.6.2.3, the AC performance of the CMOS transistors improves in 65 nm as compared to 180 nm technology. This enables electronic circuits to have a higher operating frequency, which is of interest for RF circuits such as LNAs, downconverters and synthesizers. However, since the carrier frequency of GNSS signals is much lower than the current unity gain frequency \( f_T \) of CMOS 180 nm, moving to 65 nm is not necessary. On the other hand, as explained in section 1.6.2.2, the performance degradation of the analog circuitries in the IF chain of the FE in 65 nm is expected due to the degradation of the transistors’ DC properties in lower voltage headroom. However, this problem can be dealt with by accepting the increased power consumption [36]. In fact, comparison of the recent published GNSS FEs in Table 1.3 confirms that the power consumption of the FEs depends mainly on the bandwidth and the performance of the FE such as NF and linearity regardless of the integration technology.

Therefore, employing 65 nm CMOS technology would not help to save the power consumption of the FE or even achieve the better performance than in 180 nm. Furthermore, for the purpose of this thesis, the planned GNSS FEs are eminently analog, thus would not benefit in reduction of size from downscaling. Based on all of these considerations, and thanks to the
1.6. ASIC technology choice

much lower cost, the UMC 180 nm CMOS technology is chosen for the FE integration in this thesis.
This chapter presents the design and implementation of a custom ASIC FE capable of simultaneously receiving at least two Galileo PRS signals (E1 and E6), in the framework of the Antenna and fRont-end MOdules for PuUblic Regulated Service applications (ARMOURS) project. Given the nature of the PRS signals, their users will be more protected on a daily basis against jamming and spoofing than the users of the OS signals. Moreover, since there is a sufficient frequency gap between the two PRS bands, the baseband processor will be able to account for the first-order ionospheric group delay (which is on the order of 1–50 m depending on the ionospheric conditions, satellite elevation, season, and solar cycle) [3] and minimize its error. On the other hand, the dual reception improves the receiver’s robustness over the intrinsic robustness gained by the PRS signals; in fact, the simultaneous dual reception offers the flexibility that the band of operation can be selected depending on the receiver operating conditions, i.e. if strong jamming or spoofing is detected in one band the receiver can switch off the band and use the other one.

ARMOURS as a part of FP7 collaborative project, in partnership with three other partners (IMEC, ACORDE and SOFANT), was committed to the development of novel technologies for the implementation of future multi-frequency PRS receivers, filling some of the technological gaps to enable affordable and robust solutions for future demanding applications relying on the continuous availability of the PRS service. The entire RF chain was object of research and development within ARMOURS: from the receiving antennas, the RF filters and the ASIC FE. However, ESPLAB was only involved in the specification definition of the ASIC front-end as well as the design and test of the continuous-time IF filter and the ADC.

The possible applications for the PRS are presented at the beginning of this chapter. The band selection and front-end architecture are laid out afterwards. The front-end needs to fulfill a series of stringent requirements for a PRS receiver that will be discussed in detail. Finally the measurements of the fabricated front-end are presented.

Disclaimer: The PRS information used in this thesis is freely available through references of this thesis. No classified documents or information were used.
2.1 PRS applications

The main goal of the PRS is to provide restricted and highly secure access to a reliable navigation signal. This access will be given by each European Union (EU) member state through a designated Competent PRS Authority respecting the so-called Common Minimum Standards, minimum requirements mandatory to all the PRS participants, as described by the PRS access rules defined in [52]. This controlled access is intended for both military and civilian applications under government supervision where signal authentication, accuracy and robustness are critical. Some of these applications are as follows.

2.1.1 Emergency services

The PRS is meant to provide a reliable and secure positioning and timing service under difficult conditions such as interference or heavy multipath. Therefore, it is appropriate to be used by emergency services in different applications such as coordinating search and rescue operations, personnel deployment on the field and situation assessment to control fire, etc.

2.1.2 Regulatory tracking

Transportation of dangerous or regulated loads like nuclear waste or chemicals often undergoes strict monitoring. The use of PRS receivers can provide satellite-based positioning resistant to jamming and spoofing, ensuring a certain degree of reliability.

Civilian users are sometimes subject to position monitoring as well. For example, fishing vessels in the EU must be equipped with homologated tracking devices to log and report their position periodically to guarantee they operate in legal waters. Convicted criminals are sometimes required by the authorities to remain in a controlled area or away from certain locations. These tracking devices generally include anti-tamper measures and jamming or spoofing detection/mitigation mechanisms, but their reliability can be greatly improved with the use of PRS.

2.1.3 Energy generation and distribution

The GPS is a key tool for worldwide synchronization, and it plays a major role in the coordination of electrical power plants and distribution, oil and gas production, etc. These systems can benefit from the PRS as well, as the reliability of this essential infrastructure is conditioned by the availability of a secure and precise timing mechanism.

2.1.4 Telecommunication systems

Similar to power distribution, many telecommunication systems and pieces of equipment use GPS as a means of synchronization and in many cases the continuity of this timing
is critical for the seamless operation of the communications link. Therefore there is an inherent vulnerability in systems relying on open signals for this kind of synchronization. The PRS can provide a more solid mechanism to prevent system malfunctions due to accidental interference or even hostile attacks against communication networks.

2.1.5 Critical infrastructure

Besides certain energy generation and distribution and telecommunications, there are other vital systems that may rely on GNSS for their operation and need an increased availability and protection to operate in adverse circumstances, such as airports or railway transport, where positioning and timing are not merely informative but play a major role in their normal operation.

2.1.6 Security forces

Despite Galileo being a primarily civil service, as with any global navigation system, the military applications are undeniable. Most EU countries have shown interest in the potential of Galileo for defense [53], and the implementation plans for the PRS already reflect these future military uses. Still on the civilian segment, police units could take advantage of the PRS. For similar reasons, coast guards could also use secure receivers to guarantee a certain degree of reliability in their navigation despite potentially adverse conditions, something particularly important when dealing with jurisdictional borders. This issue can be extended to border control in general where security forces may need very accurate and trustworthy positioning.

2.2 ARMOURS RF front-end architecture

2.2.1 Band selection

2.2.1.1 GNSS signals overview

Most of the multi-frequency front-ends (MFFEs) intended for the mass market are designed to receive E1-B/C and E5a or E5b signals because, with this combination, many of the desired requirements—fast acquisition, precise ionospheric error correction, availability of the integrity signal, increased precision and increased tracking accuracy—are achieved. Similar considerations could be made about the need for E1-A/E6-A in high-performance PRS receivers. The only published PRS receiver, the Bavarian security receiver (BaSE) described in [54], is based on L1C, E1-A, E1-B/C and E6 A to receive both PRS available signals and to help the PRS signal acquisition and tracking by means of the Galileo OS signal. In order to analyse services, functionalities and technical requirements, a summary of most of the available Galileo and GPS signals is presented in Table 2.1.

The channel bandwidths shown in Table 2.1 indicate the minimum bandwidth allocated to
Table 2.1 – Galileo and GPS signals.

<table>
<thead>
<tr>
<th>Signal</th>
<th>Center Freq. [MHz]</th>
<th>Channel BW [MHz] outer nulls</th>
<th>Modulation</th>
<th>Service</th>
</tr>
</thead>
<tbody>
<tr>
<td>E1B/C</td>
<td>1575.42</td>
<td>4.092</td>
<td>CBOC(6,1,1/11)</td>
<td>OS</td>
</tr>
<tr>
<td>E1A</td>
<td>1575.42</td>
<td>35.8</td>
<td>BOCC(15,2.5)</td>
<td>PRS</td>
</tr>
<tr>
<td>L1C</td>
<td>1575.42</td>
<td>2.046</td>
<td>BPSK(1)</td>
<td>OS</td>
</tr>
<tr>
<td>L1 P(Y)</td>
<td>1575.42</td>
<td>20.46</td>
<td>BPSK(10)</td>
<td>Military</td>
</tr>
<tr>
<td>L1 M</td>
<td>1575.42</td>
<td>30.69</td>
<td>BOC(10,5)</td>
<td>Military</td>
</tr>
<tr>
<td>L2C</td>
<td>1227.6</td>
<td>2.046</td>
<td>BPSK(1)</td>
<td>OS</td>
</tr>
<tr>
<td>L2 P(Y)</td>
<td>1227.6</td>
<td>20.46</td>
<td>BPSK(10)</td>
<td>Military</td>
</tr>
<tr>
<td>L2 M</td>
<td>1227.6</td>
<td>30.69</td>
<td>BOC(10,5)</td>
<td>Military</td>
</tr>
<tr>
<td>E6A</td>
<td>1278.75</td>
<td>30.69</td>
<td>BOCC(10,5)</td>
<td>PRS</td>
</tr>
<tr>
<td>E6B/C</td>
<td>1278.75</td>
<td>10.23</td>
<td>BPSK(5)</td>
<td>CS</td>
</tr>
<tr>
<td>L5</td>
<td>1176.45</td>
<td>20.46</td>
<td>BPSK(10)</td>
<td></td>
</tr>
<tr>
<td>E5a</td>
<td>1176.45</td>
<td>20.46</td>
<td>AltBOC(15,10)</td>
<td>OS</td>
</tr>
<tr>
<td>E5b</td>
<td>1207.14</td>
<td>20.46</td>
<td>AltBOC(15,10)</td>
<td>OS/CS</td>
</tr>
<tr>
<td>E5</td>
<td>1191.795</td>
<td>51.15</td>
<td>AltBOC(15,10)</td>
<td>OS/CS</td>
</tr>
</tbody>
</table>

Note that, with the deployment of a modernized GPS-M-capable constellation, P(Y) signals will eventually be replaced. Thus, P(Y) receivers should try to support this new GPS-M as well to allow for the transition between the two bands.

### 2.2.1.2 Services and functionalities

Looking at Table 2.1, one can see that the E1 band offers the opportunity to gain all the services in both Galileo and GPS thanks to the overlapping bands between Galileo E1 and GPS L1C and L1M, a design decision made to simplify interoperability. Moreover, this band has high interference protection provided by the international standard for Aeronautical Radio Navigation Service (ARNS). Therefore the selection of E1 becomes virtually mandatory due to its convenience.

A key consideration is the choice of a second band between E5, E6 and even L2. As already stated, the presence of a second channel allows for the correction of ionospheric errors and adds an alternative channel in case of jamming or spoofing of the other, which is one of the goals of the project. The most obvious choice for a second frequency would be E6, as the main service to be addressed by the FE is the PRS.
The selection of E5 would entail a very wide-band compared to all other signals, which is the reason why typical dual-frequency receivers are more likely to focus on either E5a or E5b. However as in the course of this project, the allocated bandwidth for the PRS bands in the front-end will be 50 MHz, the IF section of the FE should provide acceptable performance for the complete E5 signal. A PRS-capable front-end for E6 would be technically similar to one designed for E5. In addition to the OS and PRS, E5 offers compatibility with GPS L5 that is a desirable function to consider because it can foster the market during the Galileo transition to full operation. Let’s begin analyzing the technical repercussions of these possible choices.

### 2.2. ARMOURS RF front-end architecture

The most challenging technical point is related to the receiver channel bandwidth. From Table 2.1 we can see that the widest signal is E5. These numbers do not reflect the full bandwidth of every signal, but still show an interval where most of each signal’s power is contained, ensuring low correlation losses. For this project, the required bandwidth for the PRS (both E1-A and E6-A) is 50 MHz despite the outer nulls separation for the in-orbit validation (IOV) signals as stated in Table 2.1.

The channel bandwidth affects both power consumption and circuital complexity in the IF filters, IF amplifiers and ADCs, but RF sections only a little. Remembering that the bandwidth of a large majority of IC FEs is typically lower than 20 MHz, it is clear that breaking this limit is a challenge for the E1-A channel, which would demand more power. For a second channel, besides E6, targeting a single lobe of the E5 or L2M is realistic by considering their relative bandwidth compared to the PRS requirement of 50 MHz, so these goals would be similar.

Band selection affects also the tuning bandwidth of the local oscillators, the ones used for selecting the received band in reconfigurable channels. For example, a single oscillator able to tune E1 and E6 has a relative tuning range $2(f_{E1} - f_{E6})/(f_{E1} + f_{E6})$ of about 20%; it increases to about 25% for E1/L2, and reaches 27% for E1 and E5b. The pair of E5b/E6 is quite convenient, requiring a relative bandwidth of around 6%.

The reception of the OS signal is another issue to consider because it could be desirable to achieve fast acquisition and basic operation without authority restriction, but it is not for free in terms of technical requirements. In fact, even though E1-A and E1-B/C share the same central frequency, they have distinct spectral shapes with different channel needs. In section 1, it is seen that for BOC signals (large bandwidth and spectral energy shifted away from central frequency) the preferred scheme is the direct conversion (or zero-IF) with AC coupled IF stages to remove the DC offset and to avoid flicker noise. In contrast, for the Binary Phase-Shift Keying (BPSK) signals used in OS, the preferred choice is the low-IF scheme, where the high pass frequency response of the AC coupling does not affect the main signal lobes. BOC modulations can also be affected by this if the cutoff is not sufficiently close to 0 Hz. Furthermore, flicker noise sources make low-IF preferable for moderately narrow-band signals as the averaged NF can be significantly higher if too close to 0 Hz, while for wide-band
channels this effect is less important. Compatibility between the PRS and OS would entail the receiver scheme to be reconfigurable between zero-IF to low-IF and vice versa, or a certain performance decrease otherwise. This might increase the complexity of some blocks in the IF chain and further flexibility in the LO frequency tuning.

For the same reason the receiver scheme reconfiguration could be required also for GPS compatibility, at least for BPSK modulations. Therefore, we can say that if Galileo OS reception is required then GPS OS compatibility is achievable with a minimum impact on the FE. From an operational point of view, military bands avoid allocating power near the carrier to allow jamming of the OS with a reduced effect in the secure signals [55]. Therefore a reception null at the carrier frequency would be desirable in these cases. This null would be optional if OS capabilities are planned – as this would obviously filter the OS signals (with BPSK modulation) out.

In Table 2.2 seven band configurations are selected on the basis of the above considerations. Three critical requirements are considered: the LO tuning range, the receiver topology configuration (zero-IF and low-IF) and the IF bandwidth. Additionally, three functionalities are shown: PRS redundancy, IF path reconfigurability for OS and GPS compatibility. It is not a thorough comparison of all the combinations, but the most relevant ones. Note that in principle a front-end channel with a large bandwidth and wide tuning range would be able to receive several bands between the upper and lower limits by choosing the right LO frequency, assuming the antenna, RF filters and LNA allow it. The LO tuning range might have a very different impact depending on the FE architecture, but is included as a reference for the relative distances between the carriers that will be taken into account for the architecture selection, particularly for the case of having reconfigurable channels.

Receiver topology means how the bandwidth will be allocated after downconversion, in either a zero-IF or a low-IF channel. GPS compatibility is conditioned not just by the band

<table>
<thead>
<tr>
<th>Bands</th>
<th>Design choices</th>
<th>Functionalities</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>CH1</td>
<td>CH2</td>
</tr>
<tr>
<td>E1A</td>
<td>E6A</td>
<td>50/50</td>
</tr>
<tr>
<td>E1A</td>
<td>E5-b</td>
<td>50/20</td>
</tr>
<tr>
<td>E1A</td>
<td>L2M</td>
<td>50/20</td>
</tr>
<tr>
<td>E6A</td>
<td>E5b</td>
<td>50/20</td>
</tr>
<tr>
<td>L1C/E1†</td>
<td>E6A</td>
<td>50/50</td>
</tr>
<tr>
<td>L1C/E1†</td>
<td>E5b</td>
<td>50/20</td>
</tr>
<tr>
<td>E1†</td>
<td>L2M/C</td>
<td>50/20</td>
</tr>
</tbody>
</table>

* with degraded compatibility, † E1-A/B/C.
choice but by its bandwidth allocation. Zero-IF configurations necessarily have a DC null that corresponds to the carrier frequency, which means some power losses for L1 (and, to a lesser extent, E1-B/C). This DC null results in degraded compatibility, meaning a low-IF design would be better for this purpose. Depending on the precision of this AC coupling, these losses may or may not degrade L1 operation significantly. Making the FE flexible enough to shift the IF, or using low-IF despite the bandwidth of the PRS, would give better support to E1-B/C and L1C.

Encryption redundancy indicates whether or not there is more than one secure band. E1 without E6 or the other way around does not provide an additional PRS channel, so jamming one channel makes the receiver unable to provide a secure position, velocity and timing solution from Galileo. L2M could be used as a secondary secure band in a dual-frequency dual-constellation receiver, but this application is extremely specific, limited basically to military devices. Besides, E1-A and L2M offer the fewest services: a partial PRS redundancy based on GPS L2M service and no OS. Finally, double PRS would require the widest bandwidth, but provides PRS encryption redundancy.

2.2.2. ARMOURS RF front-end architecture

2.2.1.4 Band selection conclusions

Given the wide range of applications that take advantage of simultaneous dual-frequency reception and the PRS-oriented character of this project, it seems clear that the main goal should be the coverage of E1-A and E6-A with two channels for simultaneous operation.

Considering the wide-band requirements of the PRS, it might take comparatively little effort to adjust the lower frequency channel E6 to receive E5 as well, or at least E5b, depending on the flexibility given by the architecture. On the other hand, the bandwidth of E1-A and E6-A also allows the reception of E1-B/C and E6-B/C, so such a front-end would be able to demodulate OS and CS at the same time, with some GPS coverage (L1) despite a more than likely DC decoupling.

The proposed band selection is therefore E1 and E6, with the latter showing some flexibility to switch to E5b. This way the receiver could be used for pure PRS dual-frequency operation or high-performance civil receivers (OS E1& E5b), with capabilities in the commercial band (E6) or even hybrid operation (GPS/Galileo). The flexibility should be higher for the FE ASIC, trying to optimize compatibility with non-PRS bands at these frequencies plus E5b or even the whole E5, while the support for other bands below E6 would depend mainly on the filter and antenna designs.

The use of a third simultaneous frequency was suggested in the description of work but it is considered not critical for most applications. This additional frequency would further improve the correction of ionospheric errors, and reduce the ranging variance, but it does not extend redundancy significantly beyond having two channels able to cover three or more bands (a triple-channel receiver with one band being jammed would offer two bands, just like
a dual-channel that selects the ones without interference). However, it would increase power consumption and would not provide additional protection in a PRS application as the third band would not be PRS. It would make sense only in a GPS/Galileo military receiver, and the added benefits would still be debatable.

### 2.2.2 Architecture selection

The architectures shown in section 1.4.2 are now compared to consider their advantages and disadvantages for the implementation of the ARMOURS FE. Table 2.3 summarizes their advantages and disadvantages. It is followed by a short trade-off description of each architecture.

#### 2.2.2.1 Broadband front-end

The broadband FE is a multi-frequency FE that is very simple in concept, involving the use of a reconfigurable channel with a wide-band RF stage. The downconversion stage selects the band to be processed and sampled, while a common RF line reaches the mixer. This is more vulnerable to interference because jamming one channel can still cause intermodulation in the LNA or mixer, even if the selected band is another one. The LNA, mixer and synthesizer need to be designed to support a wide frequency interval, so their performance will be lower than if they were optimized for single-frequency operation. Moreover, to receive both PRS bands, the IF section also requires more than 300 MHz of bandwidth which is impractical. Due to these reason this FE is not an optimal choice for ARMOURS.

#### 2.2.2.2 Front-end arrays

The main alternative to the broadband architecture is having a separate dedicated channel for each band. The power per channel is potentially lower as each channel can be optimized to its corresponding band. The main disadvantages of this design are higher power and larger area, although not per channel but rather because of allowing simultaneity. It also requires more development effort. This FE can potentially meet the ARMOURS requirements including robustness against interference and simultaneous reception of two bands. The following architectures will reduce the power and area costs by reusing different sub-systems.

---

**Table 2.3 – Comparison of multi-frequency front-end architectures.**

<table>
<thead>
<tr>
<th>Front-end architecture</th>
<th>Power per channel</th>
<th>Channel reconfigurability</th>
<th>Simultaneous channels</th>
<th>Noise performance</th>
<th>Interference immunity</th>
<th>Design complexity</th>
</tr>
</thead>
<tbody>
<tr>
<td>Broadband</td>
<td>Medium-high</td>
<td>High</td>
<td>No</td>
<td>Good</td>
<td>Low</td>
<td>Medium/Low</td>
</tr>
<tr>
<td>FE Arrays</td>
<td>Medium</td>
<td>High</td>
<td>Yes</td>
<td>Very good</td>
<td>High</td>
<td>Medium/Low</td>
</tr>
<tr>
<td>Overlay</td>
<td>Medium-low</td>
<td>Medium</td>
<td>Yes</td>
<td>Average-Good</td>
<td>Medium</td>
<td>Very high</td>
</tr>
<tr>
<td>Add. Freq. Tran.</td>
<td>Medium-low</td>
<td>High</td>
<td>Yes</td>
<td>Poor</td>
<td>Medium-low</td>
<td>High</td>
</tr>
<tr>
<td>Direct sampling</td>
<td>Low</td>
<td>Very low</td>
<td>Yes</td>
<td>Average</td>
<td>Very low</td>
<td>Very high</td>
</tr>
</tbody>
</table>
and resources of the FE. The consequence of this is the reduction of robustness against interference and a greater design complexity.

### 2.2.2.3 Overlay front-end

The overlay architecture solves some of the limitations of the previous FE by keeping the channels separated at the beginning of the IF chain. This gives some flexibility in the frequency plan while allowing for the possibility of disabling one of the channels when a jammer appears in it. The disadvantages are potential noise degradation and filter design complexity, which depend heavily on understanding the power spectral density of the signals in order to minimize the overlap of noise. This means a generic FE designed to work with an arbitrary or unknown modulation will generally be more complex or will show worse noise performance. The relationship between the IF of the different channels will also depend on this spectral density (a 3 dB NF degradation would take place if they were overlapped without any further assumptions), so reconfigurability also has some limitations.

### 2.2.2.4 Front-end with additional frequency translation

The FE with additional frequency translation is very similar to the overlay FE. There are several ways of overlapping the different channels depending on the spectral allocation of the signals and their respective filtering. However, if the main RF carrier is being jammed, no other frequency can be used, as they share the same downconversion stage, unless this is made variable as well, like a switching FE with an additional mixing stage for an extra channel. This is a simpler solution than the overlay FE, however overall noise performance is worse.

### 2.2.2.5 Direct-sampling front-end

Among the architectures presented in section 1.4.2, direct-sampling FEs show the potentially lowest power consumption, as the concept is merely a low-noise amplifier, a filter and an ADC. However, there are many complications with this sort of design. Its frequency downconversion is based on aliasing. Because of this, there is a direct link between the sampling frequency and the IF, so it is not possible to set these to arbitrary values. This also means the frequency at which the baseband processor takes the samples is heavily restricted by the downconversion and not freely adapted to the baseband needs, so if a different sampling frequency is desirable the signal will have to be re-sampled. In general this sampling ratio will be fractional, resulting in additional complications. The optimal sampling frequencies are not likely to be obtained with standard crystal oscillators or integer multiple/submultiples of these frequencies, meaning specific reference oscillators would have to be manufactured for these receivers alone. Otherwise, these arbitrary frequencies would have to be generated with additional synthesizers.

Regarding multi-frequency channels, even though it is theoretically possible to simultane-
ously downconvert several bands to adjacent intervals of the spectrum through sampling, this would impose further constraints to the possible frequency combinations, which would make the FE less usable by a generic baseband processor, while requiring in any case, a particularly large bandwidth. On the other hand, separating each band with a dedicated direct sampling channel or ADCs would likely require different sampling frequencies, creating additional synchronization complications for the baseband processor, and causing inter-channel cross-interference of sampling spurs that are not present when using the same sampling rate for all channels.

Its performance is severely limited by that of the filters and ADC, thus this architecture is vulnerable to sampling jitter and aliasing noise. Sampling has to be particularly accurate, so even if the topology of the FE is simple, achieving an ADC with such good characteristics is not. Moreover, since for processing the GNSS signals a huge amplification (typically > 80 dB) is required, such a huge amplification at the RF prior to sampling, without down conversion stages, may lead to instabilities in the RF amplification chain.

Because of this frequency translation through aliasing, this FE is extremely vulnerable to interference; virtually any spurious tones become in-band. Therefore, anything not thoroughly filtered before the sampling process will necessarily overlap with the signals of interest. Although it is an attractive solution for single-frequency narrowband receivers, overall this is clearly unsuitable for PRS receivers.

### 2.2.3 ARMOURS architecture and frequency plan

Given that robustness against interference is a priority, the FE should make channels as independent as possible. Low design complexity and good noise performance are desirable, so the best option is to have a FE with either a dedicated channel for each frequency or a single channel able to switch between bands as needed. Since simultaneous dual-frequency operation is one of the aims of this project, the possibility of a single reconfigurable channel for all of them has to be discarded. Consequently, the general architecture chosen for ARMOURS is a dual-frequency front-end arrays as it is shown in Figure 2.1.

One of the channels will be fixed at E1, while the other will be designed for E6. The topology of each channel will be that of a single-conversion zero-IF receiver with I/Q outputs, mainly due to the difficulties of performing image rejection with complex filters at high frequencies and the high-frequency requirements of the IF amplifiers otherwise. The frequency plan of the receiver for both the E1 and E6 front-end bands is shown in Figure 2.2. This means four ADCs will be required, two per channel. The ASIC or FE core will comprise of an LNA, a pair of low-noise I/Q down-converters with their respective filters, amplifiers and ADCs. Additionally, external LNAs will be merged with the antennas to reduce the effect of the insertion losses of the RF bandpass filters in the receiver sensitivity; these LNAs will be designed in the same technology as the ASIC core, but packaged or integrated separately.
One of the advantages of this approach is the reuse of the designs for the baseband sections (low-pass filters, amplifiers and ADCs) to accommodate 50 MHz with a cutoff frequency of 25 MHz, as they will be identical for both channels.

These sections will cancel offsets with a narrow high-pass response in the amplification stages that should not affect Galileo OS or CS signals because of their null at the carrier frequency. Legacy signals like L1 C/A should still be usable if this DC notch is selective enough [56]. Given the relative proximity of E5 and E6, the LNA, mixers and synthesizer for the E6 channel will be designed to additionally accommodate E5b, E5a or both, depending on other implementation constraints.

### 2.3 ARMOURS RF front-end specification

#### 2.3.1 Power consumption

Looking at Table 1.2, the average power consumption of GNSS receivers is around 54 mW per channel. Considering that the required bandwidth of the PRS FE in this project is 50 MHz and that the FE has two channels, a 125 mW is chosen as a preliminary estimation of the power consumption for the FE.
For the ASIC, the maximum supply voltage is given by the technology. The process chosen for the ASIC developments is UMC 0.18 μm, which has a nominal supply voltage of 1.8 V for the standard transistors, and 3.3 V for lower performance transistors and digital input and output cells. Standard digital cells are designed to work at 1.8 V as well, so it makes sense to use this level for the whole ASIC core. The total power consumption is divided to assign the power consumption of each block as a preliminary goal of the design. The preliminary power consumption is shown in Table 2.4.

Table 2.4 – Preliminary estimation of power consumption.

<table>
<thead>
<tr>
<th>Block</th>
<th>Power consumption</th>
</tr>
</thead>
<tbody>
<tr>
<td>LNA(^1)</td>
<td>6 mW</td>
</tr>
<tr>
<td>Downconverter</td>
<td>5 mW</td>
</tr>
<tr>
<td>Frequency synthesizer</td>
<td>12 mW</td>
</tr>
<tr>
<td>VGA</td>
<td>3 mW/I-Q branch</td>
</tr>
<tr>
<td>Filter</td>
<td>5 mW/I-Q branch</td>
</tr>
<tr>
<td>ADC</td>
<td>6.5 mW/I-Q branch</td>
</tr>
</tbody>
</table>

\(^1\) External LNA.

For a sampling frequency of about 50 MHz, considering two I/Q branches and two channels, the total power estimation excluding digital control circuitry (which should have a negligible impact) is on the order of 100 mW.
2.3. ARMOURS RF front-end specification

This power consumption is only for the front-end itself and not the full GNSS receiver. The total power of the PRS baseband processor is unknown a priori, and heavily dependent on implementation. U-blox LEA-M8S modules [57] are high-performance, low-cost, low-power multi-frequency receivers for L1/E1/B1. Their reported tracking sensitivity is -167 dBm, 4 dB better than the expected performance of the GNSS receiver integrated in [58], with a power consumption of about 78 mW. This power can be divided into three main blocks: front-end, and low- and high-level signal processing. The first two blocks are affected by the signal bandwidth (greater analog bandwidth, higher sampling frequencies), while the third block of the position, velocity and timing solution, computation, or navigation should remain in the same order. PRS receivers, like current P(Y) modules, are also expected to have additional circuitry executing secure operations like code generation or decryption. A qualitative estimation indicates that such a receiver implementation that is optimized for high performance, maintaining low noise and high bandwidth, would not be suitable for a low-power device like the Terrestrial Trunked Radio (TETRA) transceiver [58].

However, the power consumption of the whole front-end does not have to be the power consumption of the front-end under normal operation. Even if the GNSS receiver is expected to be fully operative, a dual-frequency regime is a feature that may not be required in some cases. One option would be to allow the user to disable either channel when simultaneous reception is not required, effectively halving the power consumption. Another strategy implemented in certain receivers where power management is critical is the continuous supply control of different blocks to switch them on and off depending on the quality of service [59].

Undersampled DSSS signals keep their autocorrelation properties [60] reducing sampling and processing power at the cost of effective $C/N_0$. For example, decimating by a factor of two theoretically causes a 3 dB SNR degradation at the correlator outputs. In the power breakdown above, ADCs working at a sampling frequency of 52 MHz would account for about 25% of all the front-end power, which could be dynamically reduced by modifying the duty cycle (i.e. sampling at submultiples of 52 MHz). ADCs can be switched off easily and quickly by bypassing the clock input, since their static power consumption can be very low.

A more effective power-saving strategy would be the switching off practically the whole front-end. ADCs and most of the analog blocks could be controlled by a power-down signal that would shut down most of the RF channel. To avoid lock transients, the frequency synthesizer could remain on, but the rest would be switched on and off for a fraction of time. In this scenario, total power would ideally be:

$$P_{FE} = P_{SYN} + \tau (P_{LNA} + P_{MIX} + 2P_{VGA} + 2P_{FIL} + 2P_{ADC}) \approx 12 \text{ mW} + 70 \text{ mW}. \quad (2.1)$$

In high-quality signal conditions or when sensitivity values can be lower than optimal (such as in the TETRA terminal described above), 6 dB losses would be affordable to reach...
a theoretical power consumption on the order of 22 mW per channel with a duty-cycle of 25%. This way the same high-performance receiver could be adjusted to different sensitivity requirements by means of power management.

### 2.3.2 Noise figure

The noise figure (NF) has a direct effect on sensitivity; for a given baseband implementation, sensitivity is degraded by 1 dB per 1 dB of NF. The noise specification is therefore the sensitivity requirement for the receiver, and the sensitivity achieved by the baseband processor. The gap between the two is approximately the maximum NF.

The sensitivity achieved by the baseband processor is usually expressed in two values: acquisition and tracking sensitivity. Tracking sensitivity is generally higher (i.e. able to detect weaker signals) because the effects of the combined dynamics of the satellites and the receiver are estimated to a certain extent by the phase and code tracking loops. Acquisition sensitivity does not generally make any assumption about local dynamics (cold start) and involves the search of the space vehicle (SV) signals in a two-dimensional space (carrier phase/frequency and code delay).

While the receiver sensitivity is typically given as a power level, commonly in an ideal scenario with nominal antenna noise or temperature and no interference, the sensitivity of the baseband processor is generally expressed in $\frac{C}{N_0}$ or signal power over noise power density.

In reality, not all sources of signal degradation between the antenna and the signal processor can be approximated as additive white noise. As will be seen, distortion, quantization, interference, sampling jitter or phase noise causes an effective $\frac{C}{N_0}$ reduction that does not directly translate into a NF approximation. For this reason the maximum NF of the front-end is only one of many factors that have to be taken into account to optimize the receiver sensitivity, even if usually the most important as well.

Typical NF values in GNSS receivers are between 2 dB and 5 dB (see Table 1.1 and Table 1.2). Given the bandwidth restrictions and novelty of the designs, 4 dB will be set as a reasonable system goal for the NF of the receiver (including the FE, RF filter and active antenna). As will be seen, it is believed technically possible to achieve a lower NF, closer to 2 dB, so this will be treated as an upper boundary or worst-case scenario.

### 2.3.3 Gain

As specified in [7], the minimum received power on ground, measured at the output of an ideally matched right-hand circularly polarized (RHCP) 0 dBi user receiving antenna with the SV elevation angle higher than 10 degrees, is approximately -157 dBW (-127 dBm) for the E1 signal and -155 dBW for the E5 and E6 signals. However, GNSS signals are DSSS, which means their power density is low and the minimum bandwidth required to process them contains
mostly thermal noise.

Assuming an ADC input dynamic range of 500 mV_{pp} and that we are using 4 bits of back-off for interference mitigation, then the required ADC’s input voltage is around 31.25 mV_{pp}. Given that the GNSS signals are buried under the noise floor, we can consider 31.25 mV_{pp} as three times the standard deviation (\sigma) of the noise voltage at the ADC’s input. Therefore, the noise voltage at the ADC’s input is:

\[ V_{n,ADC} = \frac{31.25 \text{ mV}_{pp}}{3} = 10.42 \text{ mV}_{RMS}. \] (2.2)

On the other hand, the input signal is basically thermal noise within the receiver bandwidth and can be calculated by:

\[ P_{n,\text{ant}} [\text{dBm}] = N_0 + 10 \log(BW) \approx -100 \text{ dBm}, \] (2.3)

where \(N_0\) is the noise spectral density (\(N_0 \approx -174 \text{ dBm/Hz}\) at room temperature of 300 °K) and \(BW\) is the equivalent noise bandwidth approximated by that of the FE’s most-selective filter. Over a bandwidth of 25 MHz, the equivalent input power is about -100 dBm, which can be converted to volts root mean square (RMS) through the load impedance of \(R\) equal to 50 \(\Omega\) by:

\[ V_{n,\text{ant}} = \sqrt{R \times 10^{\frac{P_{n,\text{ant}} [\text{dBW}]}{10}}} = 2.23 \text{ \mu V}_{RMS}. \] (2.4)

Accordingly, the required receiver’s voltage gain can be calculated by:

\[ G_v = 20 \log \left( \frac{V_{n,ADC}}{V_{n,\text{ant}}} \right) = 20 \log \left( \frac{10.42 \text{ mV}_{RMS}}{2.23 \text{ \mu V}_{RMS}} \right) \approx 70.4 \text{ dB}. \] (2.5)

Considering temperature variations and additional losses as well as the processing of smaller bandwidth signals, a gain range of 60 dB to 80 dB would be an appropriate gain range.

### 2.3.4 Channel frequency response

Traveling through the receiving chain, from the antenna to the digital processing unit, the GNSS signal is delayed by a comparatively large value (up to 1 \(\mu\)s). Absolute delay is not as critical as relative variations given that the position, velocity and timing solution is calculated based on phases between signals, so the absolute delay would mostly increase latency which is considerably lower than the processing time. On the other hand, relative delays introduce an error in positioning if not calibrated or estimated. These, also called hardware biases, are due to the group delay variations versus both frequency and physical parameters (e.g. temperature
Chapter 2. Public regulated service receiver

Figure 2.3 – (a) Phase variation of a 4th-order elliptic filter with 2 dB ripple and cut-off frequency at 1 Hz compared to linear fit and (b) non-linear phase error.

and aging).

Generally, front-ends do not have constant group delay throughout their frequency band. Hence, some hardware biases are expected between spectrally different signals on one carrier frequency, or among signals on different carrier frequencies. More importantly, for a given SV, its signal will suffer dispersion, meaning a distortion of the autocorrelation function. Group delay is also important for multi-frequency receivers and carrier-based measurements.

In high-selectivity filters such as SAW filters, the group delay changes quickly in a frequency band close to the filter’s corner frequencies. Since the PRS signal energy is concentrated mainly on the band edges, the group delay variation over frequency may be not negligible depending on the channel design.

Most of the phase error will be concentrated in the RF and IF filters. An approximated boundary of 8.8° is given to each section from the client. Figure 2.3a shows the phase response of a low-pass elliptic filter with a normalized cutoff frequency of 1 Hz and 3 dB ripple. Figure 2.3b shows the phase error with respect to a linear fit or non-linear phase variation. The average deviation $\sigma$ in the interval where the filter attenuation is lower than 20 dB (thus well beyond its cutoff) is approximately 5°, indicating that such a filter would cause very low phase distortion. The actual consequences of this error, however, will have to be evaluated on a case-by-case basis, calculating numerically the correlation of different signals with a model of the channel.

The carrier phase error is the result not just of the phase at the carrier frequency but the accumulation of phase distortion in the whole bandwidth of the signal. While these can show important differences in FDMA GNSS such as GLONASS, when dealing with pure code division multiple access (CDMA) systems, the only frequency variations are due to Doppler shifts below 10 kHz when subject to slow dynamics. To see a phase variation of 1° over a carrier
2.3. ARMOURS RF front-end specification

shift of 20 kHz, group delay should be approximately:

\[
GD \approx - \frac{\Delta \phi}{\Delta \omega} \approx \frac{\pi}{180 \cdot 2\pi 20 \text{kHz}} \approx 140 \text{ ns.} \tag{2.6}
\]

Typical RF filters have group delays one order of magnitude below that, meaning their frequency response can be considered constant regardless of the Doppler shift. IF filters do not show greater phase variations. Looking at Figure 2.3 one can see that the phase variation over a frequency shift representing such a small fraction of the total bandwidth can be ignored as well.

2.3.5 Subsystems’ specifications

2.3.5.1 Gain and noise budget

Distribution of the noise and gain requirements across the front-end chain is presented in Table 2.5. Combining losses and performance expectations of the LNA, a NF of 2 dB with a gain of at least 15 dB is a reasonable estimation. The insertion losses of the RF filter should not be greater than 5 dB as a very conservative worst case, while the downconversion stage should be able to provide a gain of 25 dB with a NF of 5 dB while keeping a reasonably low power consumption. Under these conditions, a total FE’s (combine ASIC, RF filter and active antenna) NF of lower than 3 dB can be obtained if the IF NF is kept in the range of 15–20 dB. These goals seem a feasible starting point to progress towards a more optimized gain/noise distribution.

2.3.5.2 Low-noise amplifier

The bandwidth applies to the impedance, gain and noise requirements; a 70 MHz bandwidth is chosen to guarantee a 50 MHz bandwidth for the whole FE. The LNAs will be integrated with their respective antennas to result in a low-noise active antenna. The requirements of the LNAs are summarized in Table 2.6.

Table 2.5 – Sub-systems’ noise and gain.

<table>
<thead>
<tr>
<th>Sub-system</th>
<th>Gain (dB)</th>
<th>NF (dB)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Active antenna (antenna+LNA(^1))</td>
<td>15</td>
<td>2</td>
</tr>
<tr>
<td>RF Filter</td>
<td>-5</td>
<td>5</td>
</tr>
<tr>
<td>Low-noise mixer</td>
<td>25</td>
<td>5</td>
</tr>
<tr>
<td>IF section [20, 40]</td>
<td>[20, 40]</td>
<td>15</td>
</tr>
<tr>
<td>Total [60, 80]</td>
<td>&lt; 3</td>
<td></td>
</tr>
</tbody>
</table>

\(^1\) External LNA.

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## Table 2.6 – Low-noise amplifier requirements.

<table>
<thead>
<tr>
<th>Requirement</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>Input impedance</td>
<td>50 Ω, single-ended,</td>
</tr>
<tr>
<td>Output impedance</td>
<td>50 Ω, single-ended,</td>
</tr>
<tr>
<td>Minimum gain</td>
<td>15 dB</td>
</tr>
<tr>
<td>Maximum NF</td>
<td>2 dB</td>
</tr>
<tr>
<td>Bandwidth</td>
<td>1575.42 ± 35 MHz</td>
</tr>
<tr>
<td></td>
<td>1278.75 ± 35 MHz</td>
</tr>
<tr>
<td>Supply voltage</td>
<td>1.8 V</td>
</tr>
<tr>
<td>DC power consumption</td>
<td>6 mW</td>
</tr>
</tbody>
</table>

## 2.3.5.3 Low-noise downconverter

The design requirements of the low-noise downconverter are summarized in Table 2.7.

<table>
<thead>
<tr>
<th>Requirement</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>Input impedance</td>
<td>50 Ω, single-ended,</td>
</tr>
<tr>
<td>Output impedance</td>
<td>Match to IF filter</td>
</tr>
<tr>
<td>Minimum gain</td>
<td>25 dB</td>
</tr>
<tr>
<td>Maximum NF</td>
<td>5 dB</td>
</tr>
<tr>
<td>Bandwidth</td>
<td>1575.42 ± 35 MHz</td>
</tr>
<tr>
<td></td>
<td>1278.75 ± 35 MHz</td>
</tr>
<tr>
<td>Supply voltage</td>
<td>1.8 V</td>
</tr>
<tr>
<td>DC power consumption</td>
<td>5 mW</td>
</tr>
</tbody>
</table>

## 2.3.5.4 Frequency synthesizer

In principle, the PLL frequency synthesizer will provide fixed outputs for direct conversion (f\text{LO} = f\text{RF}) but it will also provide some flexibility in situations where losing bandwidth by shifting the IF can lead to less degradation of the signal caused by interference or jamming. The requirements of the frequency synthesizer are summarized in Table 2.8.

## 2.3.5.5 Active IF filters

Figure 2.4 shows the frequency response of two sample 4\textsuperscript{th}-order filters like the ones that could be implemented for the IF sections of the ASIC.

The elliptic configuration is particularly convenient because of the filter’s abrupt cutoff
Table 2.8 – Frequency synthesizer requirements.

<table>
<thead>
<tr>
<th>Requirement</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>Frequency output</td>
<td>1575.42 ± 35 MHz</td>
</tr>
<tr>
<td></td>
<td>1278.75 ± 35 MHz</td>
</tr>
<tr>
<td>Maximum quadrature error</td>
<td>1°</td>
</tr>
<tr>
<td>Phase noise</td>
<td>&lt; −110 dBc/Hz @ 1 MHz</td>
</tr>
<tr>
<td>Supply voltage</td>
<td>1.8 V</td>
</tr>
<tr>
<td>DC power consumption</td>
<td>5 mW</td>
</tr>
</tbody>
</table>

Figure 2.4 – Frequency response of 4\textsuperscript{th}-order Chebyshev I and elliptic filters (2 dB ripple).

that strongly mitigates interferers just out of band while allowing for sampling frequencies tightly above the Nyquist limit without suffering from aliasing noise. The IF section will also present a transmission zero at DC to cancel offset errors due to fabrication mismatches in the differential pairs (stages will be AC coupled) and reduce noise (typically high close to DC, but also because of the self-mixing of the local oscillator in direct-conversion receivers). In addition, the filters will be able to show a high-pass response with a higher cutoff frequency to improve operation under OS/CS jamming (interferers close to the carrier frequency).

Some pre-amplification is recommended to keep the noise figure within moderate intervals. Channel ripple has a very limited effect in the autocorrelation of the signal. To illustrate this, a sample BOC(15,2.5) signal has been generated with a bandwidth of 50 MHz and different 4\textsuperscript{th}-order elliptic filters, then compared to an ideal flat filter (approximated by a 9\textsuperscript{th}-order Butterworth with the same bandwidth). Power was then normalized to avoid variations caused by different integrated power values, and group delay was equalized in the time domain (correlation peaks aligned by time-shifting each signal).
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It is seen that even with ripple values as high as 6 dB all four curves look very similar. In fact, in this simulation zero-crossings vary by less than 1 ns, and this shift does not necessarily translate into a ranging error of 30 cm, as the phase of the code is tracked computing differences between early and late correlators. If the channel is fully symmetrical (as in the case of matched I/Q real filters), the differential errors are expected to be several orders of magnitude lower.

Due to the difficulties in trying to generalize the effects of arbitrary channels, like for the phase variations, the actual effect of the ripple will be tested with simulations for specific filter implementations in order to guarantee that the signal integrity is not significantly affected. As a conservative bound, the ripple requirement for the IF filter will be set to 1 dB, assuming total ripple (ideally combined quadratically with other stages such as the RF filters) of less than 3 dB. The IF filter requirements are shown in Table 2.9.

2.3.5.6 Variable-gain amplifiers

The VGA adjusts the gain of the FE to provide the total gain of the FE as is indicated in Table 2.5. Accordingly, the requirements of the VGA are summarized in Table 2.10.

2.3.5.7 Analog-to-digital converters

Increasing the ADC’s resolutions improves the SNR of the signal only moderately. In fact, it is shown in [2], a 1-bit ADC leads to 3.5 dB signal degradation in a narrow-band receiver. This value reduces to 1.2 dB/0.7 dB for 2-bit/3-bit and less than 0.5 dB for 4-bit and above ADC resolutions. For a wide-band receiver, this degradation is even less [61], resulting in 2.25 dB signal degradation for a 1-bit and less than 0.3 dB for a 3-bit and above ADC resolutions.
### Table 2.9 – Active IF filter requirements.

<table>
<thead>
<tr>
<th>Requirement</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>$f_{3 \text{ dB}}$</td>
<td>25 MHz</td>
</tr>
<tr>
<td>Attenuation mask</td>
<td>[100 kHz, 2 MHz]</td>
</tr>
<tr>
<td></td>
<td>10 dB @ 27 MHz</td>
</tr>
<tr>
<td>Maximum ripple</td>
<td>20 dB @ 30 MHz</td>
</tr>
<tr>
<td>Gain</td>
<td>10 dB</td>
</tr>
<tr>
<td>Maximum NF Combined IF section</td>
<td>&lt; 20 dB</td>
</tr>
<tr>
<td>Supply voltage</td>
<td>1.8 V</td>
</tr>
<tr>
<td>DC power consumption</td>
<td>5 mW/filter</td>
</tr>
<tr>
<td>Average non-linear phase error</td>
<td>8.8°</td>
</tr>
</tbody>
</table>

### Table 2.10 – Variable gain amplifier requirements.

<table>
<thead>
<tr>
<th>Requirement</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>$f_{3 \text{ dB}}$</td>
<td>35 MHz</td>
</tr>
<tr>
<td>Gain</td>
<td>[10, 30] dB in 1 dB-steps</td>
</tr>
<tr>
<td>Maximum ripple</td>
<td>1 dB</td>
</tr>
<tr>
<td>Maximum NF Combined IF section</td>
<td>&lt; 20 dB</td>
</tr>
<tr>
<td>Supply voltage</td>
<td>1.8 V</td>
</tr>
<tr>
<td>DC power consumption</td>
<td>3 mW/amplifier</td>
</tr>
</tbody>
</table>

Therefore, as it is shown in Table 1.2, the vast majority of the GNSS receivers use fewer than 4 bits in the ADC. The higher ADC resolution however, enables the implementation of effective interference mitigation algorithms at the baseband processor which can lead to a better interference mitigation and a more robust system against jamming and spoofing. Therefore, a 6-bit resolutions which offers a dynamic range of about 37 dB is chosen for the ADC.

The FE bandwidth is 50 MHz, that means the IF bandwidth of 25 MHz in a quadrature direct conversion receiver. A sampling frequency of 52 MHz (the filter could have an attenuation of about 5 dB at 26 MHz) should be more than enough in this regard. Increasing the sampling frequency at the cost of power would add very little in performance improvements.

The sampling frequency will have some flexibility to allow for power saving when the receiver works with narrower bandwidths. Frequency synthesis sources will be kept to a minimum to avoid the generation of clock spurs inside the FE, avoiding the unnecessary use of clock multipliers and programmable dividers.

Let us consider a probability density function of the ADC, $f(v)$, between ADC input values $v_1$ and $v_2$ when $v_1 < v_{IN} < v_2$. Let $u$ be the threshold between the two values. The variance of
the quantization error becomes:

\[
\sigma^2 = \int_{v_1}^{u} (v - v_1)^2 f(v) dv + \int_{v_2}^{u} (v_2 - v)^2 f(v) dv. \tag{2.7}
\]

For a high resolution ADC, we can approximate this density function \( f(v) \) as locally flat for most steps.

\[
\sigma^2 \approx \frac{1}{v_2 - v_1} \left( \int_{v_1}^{u} (v - v_1)^2 dv + \int_{v_2}^{u} (v_2 - v)^2 dv \right). \tag{2.8}
\]

Ideally, if the threshold \( u \) is exactly between \( v_1 \) and \( v_2 \), we have [62]:

\[
\sigma_0^2 = \frac{(v_1 - v_2)^2}{12}. \tag{2.9}
\]

Assuming a threshold shift \( \Delta u \) with respect to the distance between the two quantization steps, we can express this threshold as:

\[
u = \frac{v_1 + v_2}{2} + (v_2 - v_1) \Delta u. \tag{2.10}\]

Accordingly, the quantization error can be written as:

\[
\sigma^2 \approx \frac{1}{v_2 - v_1} \left( \int_{v_1}^{u} (v - v_1)^2 dv + \int_{v_2}^{u} (v_2 - v)^2 dv \right) = \frac{(v_1 - v_2)^2}{12}(1 + \Delta u^2). \tag{2.11}\]

The noise factor \( (F) \) of this shift in the threshold \( \Delta u \) is:

\[
F \approx \frac{\sigma_{\Delta u}^2}{\sigma_0^2} = 1 + \Delta u^2, \quad \text{and} \quad NF = 10\log_{10}(F). \tag{2.12}\]

If we limit this NF to 0.1 dB, we get that the maximum threshold shift must be lower than 0.15 LSB by:

\[
\Delta u \leq \sqrt{\frac{NF}{10}} - 1. \tag{2.14}\]

As a result, the requirements of the ADC are summarized in Table 2.11.
### 2.4 Subsystems’ design

ARMOURS was part of an FP7 collaborative project in which four partners including IMEC, ACORDE, SOFANT and ESPLAB were collaborating to fulfill the tasks of the project. In this project, ESPLAB was involved in defining the system and subsystem specifications for the front-end and was in charge of the design, testing and development of an ADC and a continuous-time low-pass filter. The following section is dedicated to the design and testing of the ADC employed in the ARMOURS. The filter design and its related topics are explained in detail in chapter 3.

#### 2.4.1 Analog-to-digital converter

There are a variety of architectures available to implement the ADC [63] using a CMOS process. Based on the ADC requirements presented in Table 2.11, pipeline and two-step architectures [64–67] are the potential candidates. However, they suffer from large latency. The ADC’s latency is usually presented in its clock-cycle unit. The front-end overall latency is the sum of the ADC latency and the front-end group delay. Usually, this latency is constant and does not degrade the position, velocity and timing accuracy of the receiver and, in the case of a high-sampling-rate ADC, this latency is small. However, the latency increases in a reconfigurable design approach in which the ADC needs to operate sometimes at a low sampling rate. Even though the increase in the latency does not degrade the receiver accuracy, it will deteriorate the capability of the baseband processor to mitigate interference. In fact, due to the latency, the baseband processor requires more time to detect any interference, which may put the VGA and analog buffers in the ADC in saturation and take some time to go back in full operation. Therefore, in order to have a front-end that is robust against interference, an ADC architecture with minimal latency is preferred.

Another possible architecture for the ADCs is folding architecture [68,69], which shows low power and low latency as well as the ability to run at high sampling rates. However, it is limited in dynamic performance due to bandwidth requirements on the circuitry that processes the folded signal. According to these considerations, a full flash ADC architecture [70–72] emerges as an optimal choice because the required resolution is only 6 bits, it shows good

---

Table 2.11 – Analog-to-digital converter requirements.

<table>
<thead>
<tr>
<th>Requirement</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>Precision</td>
<td>6 bits</td>
</tr>
<tr>
<td>DNL</td>
<td>0.15 LSB</td>
</tr>
<tr>
<td>Maximum NF</td>
<td>Combined IF section &lt; 20 dB</td>
</tr>
<tr>
<td>Maximum sampling frequency</td>
<td>52 MSps</td>
</tr>
<tr>
<td>Supply voltage</td>
<td>1.8/3.3 V</td>
</tr>
<tr>
<td>DC power consumption</td>
<td>6.5 mW per ADC</td>
</tr>
</tbody>
</table>
dynamic performance, and the latency is minimal. An additional option in reducing power consumption is interpolation [73, 74], which reduces the number of preamplifiers. However, it is more suitable for a very high sampling rate and increases the load that preamplifiers need to drive [75] and consequently was not employed in the present implementation.

The simplest ADC architecture is the flash ADC. For \( N \) bit resolution, a flash ADC requires \( 2^N \) resistors and at least \( 2^N - 1 \) comparators. Reference voltages and comparators are the main components of a flash ADC. A reference voltage at each comparator can be easily obtained by a resistor ladder from the main reference voltage [76]. Since all the comparators are connected in parallel and everything is happening in one clock, the flash ADC is also called parallel ADC and has the lowest latency among ADCs. The reference ladder divides the reference voltage into \( 2^N \). The input voltage is then compared with these references and the output codes are generated according to the comparison results. During this operation, the offset voltages of the comparators are added to the input voltage, which causes a differential non-linearity (DNL) error at the output.

The overall block diagram is shown in Figure 2.6. The ADC is designed for differential input but, unlike the high-resolution ADCs for which it is better to use differential architecture to reduce common-mode noise and interference as well as capacitor voltage dependency, for an ADC with low resolution, i.e. 8-bit or less, the differential architecture does not provide any specific advantage. In other words, if the least significant bit (LSB) size is around the error that is produced by all the aforementioned items, then using differential architecture improves the quality. If the LSB size is larger than that noise, however, single-ended architecture is better, in order to save the power and area. To that effect, a single-ended architecture is chosen and the differential input signal is dealt with by adding a differential to single-ended amplifier at the beginning.

The first buffer stage is to improve the settling time of the S/H in order to be suitable for a clock frequency of 104 MHz. The second buffer stage, along with the 1.24 pF capacitor, buffers the capacitor’s voltage of the S/H and sends it to the comparators, and prevents this voltage from changing due to the kick-back current of comparators. The S/H is used here to limit the

Figure 2.6 – Overall block diagram of a 6-bit flash ADC.
2.4. Subsystems’ design

error of the sampling time to clock jitter. The output of the comparators is thermometer code which must be encoded to binary. Magnitude representation is used for the binary code. At the end, a digital block was placed to synchronize the six output digits with the Data Ready (DR) signal, which is the square-wave signal with the same frequency as the sampling rate of the ADC. The digital output is ready to read at the output at the rising edge of the DR signal.

2.4.1.1 Differential to single-ended

The differential to single-ended amplifier consists of three identical Miller amplifiers. Two of the amplifiers are used as a buffer for differential input, and the third is used to convert the differential signal to single-ended and to set the common-mode voltage. The schematic of the op-amp and a block diagram of the differential to single-ended amplifier are shown in Figure 2.7a and Figure 2.7b, respectively.

Figure 2.7 – (a) Schematic of the Miller amplifier and (b) block diagram of the differential to single-ended amplifier.

The geometry and operating point of the transistors and the resistor and capacitor of the amplifier in Figure 2.7a are presented in Table 2.12. The simulated frequency response of the Miller amplifier is shown in Figure 2.8. It shows a DC gain of 63 dB, phase margin (PM) of more than 69 ° and a GBW of 398 MHz with the capacitive load of 103 fF. Moreover, the frequency response of the differential to single-ended amplifier shown in Figure 2.9, shows a very flat response up to 100 MHz.

2.4.1.2 Buffer stages

The ADC employs two buffer amplifiers, which are called the first and second buffer stages in Figure 2.6. The first buffer stage, which is used to buffer the signal at the output of the differential to single-ended amplifier, drives the S/H and decreases its settling time, is the same Miller amplifier presented in Figure 2.8 configured in unity feedback. Its unity-gain
Table 2.12 – Geometry and operating point of the Miller amplifier’s transistors with its components’ values.

<table>
<thead>
<tr>
<th>Device</th>
<th>W/L μm</th>
<th>( I_{ds} ) μA</th>
<th>Parameter</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>M1</td>
<td>12.3/10</td>
<td>1.91</td>
<td>( R_f )</td>
<td>3.62 kΩ</td>
</tr>
<tr>
<td>M2</td>
<td>25/0.5</td>
<td>53.8</td>
<td>( C_c )</td>
<td>153.75 fF</td>
</tr>
<tr>
<td>M3</td>
<td>52.68/0.5</td>
<td>131.1</td>
<td>( R )</td>
<td>12.84 kΩ</td>
</tr>
<tr>
<td>M4a,b</td>
<td>20/0.3</td>
<td>26.91</td>
<td></td>
<td></td>
</tr>
<tr>
<td>M5</td>
<td>2.13/10</td>
<td>1.91</td>
<td></td>
<td></td>
</tr>
<tr>
<td>M6a,b</td>
<td>2.16/0.92</td>
<td>26.91</td>
<td></td>
<td></td>
</tr>
<tr>
<td>M7</td>
<td>4/0.25</td>
<td>131.1</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

Figure 2.8 – Simulated frequency response of the amplifier in Figure 2.7a.

The second stage buffers the voltage on the capacitor of the S/H and sends it to the comparators. It also reduces the fluctuation on the voltage of the capacitor which is caused by kick-back current from the comparators. The schematic of the amplifier is shown in Figure 2.11 with its geometry and operating points presented in Table 2.13. Its simulated frequency response is presented in Figure 2.12, which shows a DC gain of 60 dB, PM of 60 ° and GBW of 430 MHz.

2.4.1.3 Comparators

Latch-type voltage sense amplifiers, or sense-amplifier-based flip-flops, are very effective comparators. They achieve fast decisions due to a strong positive feedback, and their differential input enables a low offset. However, the stack of transistors in conventional latch-type voltage
sense amplifiers [77] requires a large voltage headroom, which is problematic in low-voltage deep-submicron CMOS technologies. Furthermore, the speed and offset of this circuit are very dependent on the common-mode voltage of the input which is problematic for applications with a wide common-mode range, such as ADCs.

As a comparator, a double-tail sense amplifier presented in [77] is used, having one tail for the input stage and another for the latching stage, as shown in Figure 2.13. This topology has less stacking and can therefore operate at lower supply voltages. The double tail allows for both a large current in the latching stage for fast latching independent of the common-mode voltage, and a small current in the input stage for low offset.

Figure 2.9 – Simulated frequency response of the differential to single-ended amplifier.

Figure 2.10 – The frequency response of the first buffer stage (before S/H).
Figure 2.11 – Schematic of the symmetrical amplifier for the second buffer stage.

Table 2.13 – Geometry and operating point of the symmetrical amplifier’s transistors with its components’ values.

<table>
<thead>
<tr>
<th>Device</th>
<th>W/L μm</th>
<th>Ids μA</th>
<th>Parameter</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>M1</td>
<td>12.3/10</td>
<td>1.91</td>
<td>Rf</td>
<td>7.42 kΩ</td>
</tr>
<tr>
<td>M2</td>
<td>40/0.3</td>
<td>151.5</td>
<td>Cc</td>
<td>204.5 fF</td>
</tr>
<tr>
<td>M3a,b</td>
<td>9.48/0.25</td>
<td>137.9</td>
<td>Vb1</td>
<td>1108 mV</td>
</tr>
<tr>
<td>M4a,b</td>
<td>24.18/0.3</td>
<td>137.9</td>
<td>Vb2</td>
<td>600 mV</td>
</tr>
<tr>
<td>M5a,b</td>
<td>45/0.18</td>
<td>75.75</td>
<td>Vtune</td>
<td>600 mV</td>
</tr>
<tr>
<td>M6a,b</td>
<td>4.8/1</td>
<td>75.75</td>
<td></td>
<td></td>
</tr>
<tr>
<td>M7a,b</td>
<td>3.6/0.25</td>
<td>137.9</td>
<td></td>
<td></td>
</tr>
<tr>
<td>M8a,b</td>
<td>20/0.3</td>
<td>137.9</td>
<td></td>
<td></td>
</tr>
<tr>
<td>M9</td>
<td>2.13/10</td>
<td>1.91</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

As seen in Figure 2.13, when the CLK is low, transistors M1a,b charge the Di nodes to VDD. As a result, M6a,d discharge the output nodes to ground, and there is therefore no need of having dedicated reset transistors in the latch. When the CLK goes high, it turns ON transistors M3 and M4 and discharges the Di nodes. As a result, an input-dependent differential voltage ΔVDi will build up. Transistors M6a,d pass this differential voltage to the cross-coupled inverters, and also perform a shielding between the input and output which results in less kick-back current at the input. When the common-mode voltage at the Di nodes goes down, the inverter starts regenerating the output base on the voltage difference at the Di nodes, ΔVDi. The geometry of the transistors of the designed double-tail sense amplifier is presented in Table 2.14.
2.4. Subsystems’ design

Figure 2.12 – Simulated frequency response of the second buffer stage (after S/H).

Figure 2.13 – Double-tail latch-type voltage sense amplifier.

Table 2.14 – Geometry of the transistors of the double-tail sense amplifier in Figure 2.13.

<table>
<thead>
<tr>
<th>Device</th>
<th>M1a,b</th>
<th>M2a,b</th>
<th>M3</th>
<th>M4</th>
<th>M5a,b</th>
<th>M6a,b,c,d</th>
</tr>
</thead>
<tbody>
<tr>
<td>W/L μm</td>
<td>0.5/0.18</td>
<td>4/0.18</td>
<td>0.5/0.18</td>
<td>1/0.25</td>
<td>1.2/0.3</td>
<td>0.6/0.3</td>
</tr>
</tbody>
</table>

2.4.1.4 Resistor ladder

A 6-bit full flash ADC requires 63 comparators. These comparators compare the input voltage that comes from S/H to the 63 reference voltages. A resistor ladder provides these reference
voltages. In this case, the input voltage range is 500 mV with the common-mode voltage of half the VDD (≈900 mV). That is, the input voltage range is from 650 mV to 1150 mV, and therefore for a 6-bit ADC the LSB is 7.81 mV.

2.4.1.5 Binary encoder

An amplitude representation is used to represent the binary output with respect to the analog input. To that effect, a thermometer-to-binary encoder that can correct for one bubble error is employed.

2.4.1.6 Measurements

The ADC is fabricated in a 0.18 μm CMOS process and occupies 760×450 μm². The microphotograph of the ADC is shown in Figure 2.14. It can operate at 52 MS/s from a 1.8 V while consuming 4.8 mA.

![Figure 2.14 – Micro photograph of the ADC.](image)

The static characterization was conducted at a sampling frequency of 1 MS/s and the result is shown in Figure 2.15. Two precision amplifiers [78] were used to drive the differential-input ADC. The ADC was designed for a differential input range of -250–250 mV input voltage corresponding to a single-ended range of 650–1150 mV. However, as is shown in the Figure 2.15, the ADC suffers from -1 LSB of an offset error and a gain error of -4 LSB. Fortunately, both of these errors can be corrected by a software calibration.

Furthermore, from the static characterization, the DNL and integral non-linearity (INL) are extracted and reported in Figure 2.16 and Figure 2.17, respectively. The maximum DNL is +0.85/−0.48 LSB and as for the INL is +2.46/−1.58 LSB. In order to perform a dynamic characterization of the ADC, a low distortion opamp [79] was employed for the single-ended to differential conversion at the input of the ADC. The signal-to-noise-and-distortion ratio (SNDR) and effective number of bits (ENOB) of the ADC were derived using the single-tone
2.4. Subsystems’ design

![Graph showing static characterization of the 6-bit ADC.](image)

**Figure 2.15** – Static characterization of the 6-bit ADC.

![Graph showing measured DNL of the ADC.](image)

**Figure 2.16** – Measured DNL of the ADC, maximum DNL is $+0.85/-0.48$ LSB.

measurements at the sampling rate of $52$ MS/s. The output spectra of the ADC for a tone at $3.87$ MHz and $20.14$ MHz are shown in Figure 2.18 and Figure 2.19, indicating a spurious-free dynamic range (SFDR) of $33$ dB and $32.4$ dB, respectively. The SNDR of $27.63$ dB, that results in a ENOB of $4.3$ bits, is achieved for an input tone at $3.87$ MHz while the input at $20.14$ MHz results in a SNDR of $26.97$ dB and a ENOB of $4.19$ bits. The figure of merit (FOM) of the ADC can be expressed by normalizing the ADC’s power consumption to its Nyquist bandwidth and ENOB as:

$$FOM = \frac{P}{2f_s 2^{\text{ENOB}}} = 4.55 \text{ pJ/conv.} \quad (2.15)$$
**Figure 2.17** – Measured INL of the ADC, maximum INL is $+2.46/−1.58$ LSB.

**Figure 2.18** – Measured ADC output spectra with a tone at 3.87 MHz sampling at 52 MS/s, the measured SNDR is 27.63 dB resulting in an ENOB of 4.3.

### 2.5 ASIC measurements

For the sake of completeness of this manuscript, this section presents the measured results of the proposed PRS front-end ASIC. Note that the following results have been obtained by ACORDE. Since the front-end was designed to cover Galileo PRS signals at E1 and E6, the results are shown for both bands. The layout of the ARMOURS FE ASIC is shown in Figure 2.20. The characterization of the external LNAs and RF filters are not included in this section.
2.5. ASIC measurements

Figure 2.19 – Measured ADC output spectra with a tone at 20.14 MHz sampling at 52 MS/s, the measured SNDR is 26.97 dB resulting in a ENOB of 4.19.

Figure 2.20 – The layout of the ARMOURS front-end ASIC.

2.5.1 Input matching

The first stage in the FE ASIC is the low noise mixer. It consists of a linear low-noise amplifier stage and two Gilbert cells. The low-noise stage in both E1 and E6 FE's require an external matching network. The input impedance measured with a network analyzer before and after matching is shown in Figure 2.21 and Figure 2.22 for E1 and E6, respectively. Note that the return-loss improvement after matching the E1’s LNA is small, however, it is sufficient for the LNA requirements (|S11| < -10 dB). The upper resonance, which is more pronounced,
happens beyond the bands of interest and is merely incidental.

Figure 2.21 – The E1 LNA’s input impedance before and after matching.

Figure 2.22 – The E6 LNA’s input impedance before and after matching.
2.5.2 Frequency synthesizer

There are no dedicated VCO outputs, so the output frequency was measured from radiation coupling using a probe, very low but still within the sensitivity range of the spectrum analyzer. The resulting frequency intervals are represented in Figure 2.23. The dots represent the target frequencies 1278.75 MHz and 1575.42 MHz for direct conversion. There are two intervals per channel because the coarse tuning switch was implemented to account for tolerances with two overlapping low/high segments.

![Figure 2.23 – The quadrature VCO tunable range; dots represent the target frequencies 1278.75 MHz and 1575.42 MHz.](image)

2.5.3 Frequency response

The front-end transfer function was verified in the analog domain. A constant-power single-tone sweep around the downconversion frequency was performed for each channel to obtain the amplitude variation with frequency or frequency response of each channel. The results are shown in Figure 2.24. The amplitude responses of E1 and E6 are fairly similar to each other and to the stand-alone filter measurements with a progressive attenuation caused by the limited bandwidth of the integrated analog buffer. Note that the integrated filter in this front-end is lacking the out-of-band notch. This was caused by capacitive coupling in the capacitor bank which was noticed and fixed for the next integration. Despite this effect, the band flatness is still within ±1.5 dB, demonstrating a good integration of the custom filters inside the front-end’s chain.
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2.5.4 Quadrature matching

The responses of all four branches (E1-I, E1-Q, E6-I, E6-Q) are in good agreement with each other, although gain mismatches of approximately ±1 dB between branches within each channel are observed. Because of the relatively low power levels of the signals and the bandwidth of the channels, accurate measurements of the phases require some processing. However, the direct use of a digital oscilloscope is not practical because, if the SNR is too low, the random shift of the trigger is too high to make the averaging process useful, while if the SNR is high enough to make the trigger clean, distortion makes the measurements unusable. In Figure 2.25 the outputs are averaged 1024 times at nearly 1200 mVpp, where the distortion begins to become apparent and the instability in the trigger still causes measurement problems.

Therefore, the signals were captured and loaded onto a computer for additional processing. The digitized I/Q outputs go through a narrow bandpass zero-delay digital filter that greatly reduces noise and removes DC offsets, and the resulting signals are fitted with sine functions via least squares. The results are shown in Figure 2.26. The measured quadrature error is kept within ±1 dB in amplitude and ±2° in phase for the whole usable bandwidth. The phase error is higher than expected but no compensation mechanism was implemented other than a symmetrical layout. The main source of error in the quadrature phase is the mixer/oscillator pair, and could be tuned by making the feedback of the quadrature VCO adjustable to produce asymmetries.

The amplitude error can be compensated for by adjusting the gain of the I and Q branches independently. This functionality would be trivial to implement to allow post-fabrication calibration by making a small change in the digital decoder that sets the gain of the VGA, but it was not included in the current version. Since gain steps are separated by 1 dB, the resulting error of this kind of correction would be ±0.5 dB without any additional circuitry other than a
2.5. ASIC measurements

Figure 2.25 – E1 I/Q outputs at $f_{IF} = 5$ MHz showing both distortion and trigger problems.

Figure 2.26 – E1 I/Q outputs in time-domain, filtered and fitted at $f_{IF} = 5$ MHz.

digital adder/subtractor.

2.5.5 Noise figure

Note that, the preliminary implementation of the front-end was found to suffer from high total noise figure. Further analysis showed that the mixer had high parametric sensitivity that could...
cause incorrect matching between its two stages (the input low-noise stage and the actual quadrature mixers). Therefore, the input stage of the mixer was replaced by a preamplifier with a different topology with lower gain and power consumption, with the advantage of having very robust wideband impedance matching at the cost of total noise figure. As a result, instead of having a nominal ASIC noise figure on the order of 4–5 dB, this was increased to about 12 dB. In a typical scenario this is still affordable due to the wide gain/noise budget originally planned, where the external LNAs integrated in the active antennas have a noise figure on the order of 1 dB with enough gain to meet the total 4 dB noise figure requirement despite filter losses.

The noise figure estimation has been derived from the gain method:

\[
NF \approx P_{N,\text{out}} - (-174 \text{ dBm/Hz} + 10\log_{10}(\text{RBW}) + \text{Gain}).
\] (2.16)

If the gain of the chain can be accurately known and noise at room temperature is assumed to be known as well (approximately -174 dBm/Hz), it is possible to obtain the noise figure as the excess of noise over the amplified input floor. The RBW in (2.16) is the resolution bandwidth of the spectrum analyzer used to measure the noise floor.

The noise floor of the instrument itself must be several orders of magnitude below that of the device. This measurement is nearly as accurate as the gain, for which one must characterize the setup used to obtain this value. However, this method is not appropriate for the characterization of moderate gain or low-noise devices such as the LNAs, but its simplicity makes it convenient for the front-end ASIC, with considerably higher gain and noise figure.

Table 2.15 shows these results at different offsets with respect to the origin. Both gain and noise levels change with frequency, so several points within the band have been considered. The noise figure is slightly higher at E1 because of the lower gain of the mixer. Moreover, the noise figure is higher at a lower frequency offset since the contribution of the flicker noise is more pronounced.

Table 2.15 – Measured front-end noise figure.

<table>
<thead>
<tr>
<th>IF (MHz)</th>
<th>NF(_{E1}) (dB)</th>
<th>NF(_{E6}) (dB)</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>15.9</td>
<td>15.5</td>
</tr>
<tr>
<td>5</td>
<td>15.2</td>
<td>15.0</td>
</tr>
<tr>
<td>10</td>
<td>14.8</td>
<td>14.5</td>
</tr>
<tr>
<td>20</td>
<td>14.7</td>
<td>14.2</td>
</tr>
</tbody>
</table>

The measured noise figure is higher than the expected 10–12 dB. Note that this is the noise figure of the ASIC (front-end without the active antenna and the RF filter). The noise figure requirement in section 2.3 considers the whole front-end (ASIC with an active antenna and the RF filter). However, the measured ASIC noise figure means that the noise figure requirement of the FE (noise figure less than 4 dB) is not satisfied. As a solution to this, the
external LNA designed for the active antennas can also be integrated with the front-end core in the same package. The gain of the LNAs is adjustable (and to some extent parallel to the noise figure performance), so this setup would result in an effective front-end with the intended performance and essentially identical form factor, at the cost of power and efficiency.

### 2.5.6 Power consumption

The power consumption of the front-end ASIC was measured. The total current for nominal settings was 48 mA for the analog sections and 23 mA for the digital ones, which resulted in a total power of 162 mW. This is above the target of 100 mW in section 2.3.1, noting this version includes additional analog buffers, filters and other support circuitry for testing. Although it is not possible to measure the power of these devices separately, as they share internal supply lines, conservative estimations based on simulations of the additional sub-circuits lower this figure to about 115 mW.

### 2.6 Conclusions

A fully integrated reconfigurable dual-band GNSS receiver is implemented in 0.18 μm CMOS, which can accommodate simultaneous reception of both E1 and E6 PRS signals. As for the nature of the PRS, the front-end capable of receiving PRS signals needs to fulfill a series of stringent requirements. These requirements were discussed in details as far as any classified information was not involved. Some design efforts for high linearity and big dynamic range have been made to improve the receiver robustness against interferences by utilizing highly linear IF filter and high resolution ADC.

The receiver consumes 115 mW while achieving an average NF of 15.15/14.8 dB at E1 and E6, receptively. It offers an image rejection ratio (IMRR) of 18.7 dB, maximum voltage gain of 65 dB and a gain dynamic range of 30 dB. The active die area for the whole receiver is 11.5 mm².

The reception of E1 and E6 PRS signals not only improves the robustness of the receiver against jamming, i.e. if strong jamming or spoofing is detected in one band the receiver could be capable of switching off the band and using the other one, but also allows the receiver to account for the ionosphere propagation and minimizes its error. Therefore, it acts in favor of better GNSS navigation accuracy and availability.

At the time of writing this thesis, there is no publicly available chip addressing a multi-band PRS GNSS receiver to enable us to compare the performances of this receiver with its counterparts. However, the measurement results are summarized in Table 2.16.
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Table 2.16 – Measured front-end Performance.

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Value</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>Frequency Band</td>
<td>E1 and E6 PRS bands</td>
<td></td>
</tr>
<tr>
<td>Topology</td>
<td>Zero-IF</td>
<td></td>
</tr>
<tr>
<td>IF-BW</td>
<td>50</td>
<td>MHz</td>
</tr>
<tr>
<td>NF</td>
<td>15</td>
<td>dB</td>
</tr>
<tr>
<td>Voltage Gain</td>
<td>65</td>
<td>dB</td>
</tr>
<tr>
<td>ΔG</td>
<td>30</td>
<td>dB</td>
</tr>
<tr>
<td>Image Rejection</td>
<td>18.7</td>
<td>dB</td>
</tr>
<tr>
<td>ADC sampling rate</td>
<td>52</td>
<td>MS/s</td>
</tr>
<tr>
<td>ADC resolutions</td>
<td>6</td>
<td>bits</td>
</tr>
<tr>
<td>Technology</td>
<td>180</td>
<td>nm</td>
</tr>
<tr>
<td>Die Area</td>
<td>11.5</td>
<td>mm²</td>
</tr>
<tr>
<td>Dissipation Power</td>
<td>115</td>
<td>mW</td>
</tr>
</tbody>
</table>
3 Wide-tuning-range continuous-time active filter

Mobile wireless communication systems, such as the GNSS, Wi-Fi and LTE, are adopting signals with tens of megahertz of bandwidth in order to improve their performance [2, 80–83]. At the same time, greater mobility requires longer battery life and multi-standard compatibility to deal with different service coverages. All these requirements are nowadays achievable thanks to software-defined radios, which rely on flexible hardware architectures, such as direct-conversion radio frequency front-end, as well as on low-power technologies such as CMOS. Continuous-time active low-pass filters in CMOS technology are a key building block in direct-conversion IC front-ends. In a design re-use approach, a reconfigurable continuous-time low-pass filter that can satisfy requirements of the different standards is necessary. Moreover, the coexistence of many systems (e.g., GNSS, Wi-Fi and LTE), on the same mobile equipment is common nowadays and therefore interference rejection requirements are becoming more and more stringent. This is directly reflected in the low-pass filter’s requirements in terms of selectivity and linearity.

These filters can be realized by means of passive components such as resistors, capacitors and inductors. However, passive inductors in CMOS technology are bulky and suffer from a low Q. A well-known solution to this problem consists of adopting an active inductor which occupies less chip area and provides a variable large inductance as well as a tunable Q. Therefore, low-power high-Q active inductors are of interest in high-selective filter design.

Active inductors can be realized by transforming the impedance of a capacitor by means of an active device [84]. To that effect gyrators provide the most direct way of realizing an inductor and are commonly used in active filter design [85–88]. As a result, the Q of the active inductors are directly related to the gyrators or more precisely to the OTAs within the gyrators.

Furthermore, system-on-chip integration demands that a fully differential configuration be able to reject the CM disturbances generated by the digital circuitries, clock drivers, substrate coupling and so on. On the other hand, CMFB amplifiers are an inevitable part of any fully differential amplifier. Therefore, the CM stability of OTAs and gyrators must be considered during the design. Although the two OTAs in a gyrator configuration are in negative
feedback for their differential signals, the loop still acts as a positive feedback for CM signals. This positive feedback may cause CM oscillation or latching in a gyrator.

Therefore, in order to satisfy the selectivity requirement of the system, a comprehensive analysis on the Q of the active inductor is necessary prior to the design of an active filter. Moreover, in order to ensure the CM stability while optimizing the power of the active inductor, a CM stability analysis is also required.

Towards this end, section 3.1 presents a design methodology for low-power high-Q OTA-based resonators that takes advantage of the OTA’s second pole to enhance the resonator’s Q with no extra power consumption. A comprehensive analysis that accounts for the CM stability of the OTA-based gyrators is presented in section 3.2. Based on this analysis, a new methodology that ensures the CM stability of OTA-based resonators is introduced. These two methodologies are employed in the design of a highly selective 4th-order Gm-C elliptic low-pass filter in section 3.3. Finally, since the resonator’s Q plays a main role in the filter’s selectivity in active filter design, section 3.4 demonstrates the effects of the Q-enhancement method of section 3.1 on the selectivity of the filter of section 3.3.

### 3.1 Controlled-Q resonator

Active filters entail a minimum Q for their components, in particular for their active inductors, to achieve a desired selectivity and frequency response. Towards this end, this section presents a design methodology for a low-power high-Q OTA-based resonator in which the Q of the resonator is translated to the requirements of the OTA. The effects of the OTA’s imperfections on the Q are investigated. The proposed methodology takes advantage of the OTA’s second pole to enhance the resonator’s Q with no extra power consumption. A design chart is presented that can be used to design an OTA fulfilling a given resonator’s Q. The design methodology has been validated by realizing a resonator with 8 MHz resonance frequency and a Q of 10, consuming 520 μA from 1.8 V, using UMC 0.18 μm CMOS technology.

#### 3.1.1 Introduction

Gyrators usually consist of two identical OTAs that are joined in a negative feedback loop. However, an OTA’s non-idealities such as its limited output impedance and internal poles alter the Q as well as the frequency response of both the inductors and filters. Limited output impedance results in a finite DC (low frequency) gain for an OTA, thereby limiting the maximum Q of the inductor or the resonator made from it [89]. Moreover, the internal poles of the OTA produce a phase shift of the signal in the loop of the gyrator. This extra phase simulates a negative resistance in parallel with the active inductor and enhances its Q. As the frequency of the signal approaches these internal poles, the excess phase becomes larger and may result in oscillations in the gyrator loop. To avoid these effects, a conventional design approach is to place the internal poles of the OTA far beyond its unity-gain frequency. Although this reduces
the excess phase caused by the internal poles at the OTA’s unity-gain frequency and therefore limits their effects, it usually results in more power consumption for the OTA.

Some techniques have been proposed in the literature to compensate for this excess phase and to cancel its effects. This is achieved in [90] by choosing the optimum input transistor channel length to compensate for the excess phase at the center frequency of a band-pass filter. Also a slave gyrator is used to compensate for the excess phase and boost the inductor’s Q in [89], which results in higher power consumption.

However, the goal of this thesis is to take advantage of this excess phase to boost the Q of a resonator to a desirable value with no extra power consumption. Based on this idea, a simple design methodology for a controlled-Q resonator was presented in [91] and was validated by simulations and measurements. In particular, a resonator with 8 MHz resonance frequency and a Q of 10 was designed and fabricated, and it was shown that the enhanced Q can be predicted with the proposed design chart. This section expands on this topic by examining the effects of OTA’s internal poles on the resonator’s Q and deriving its theoretical equations. Techniques to meet the resonator’s specification and measures to avoid oscillation in the resonator are also described. The sensitivity of the resonator’s Q to the OTA’s second pole and DC gain is analyzed.

This section is organized as follows. The Q of a resonator, as its main specification, is translated to the requirements of the OTA. Moreover, the effects of the OTA’s finite output resistance and internal poles are investigated in section 3.1.2. A step-by-step design methodology for a low-power high-Q resonator is proposed in section 3.1.3. A resonator with 8 MHz resonance frequency and a Q of around 10 is fabricated using UMC 0.18 μm CMOS to validate the proposed methodology. The key points and results of this section are summarized in section 3.1.4.

3.1.2 From resonator specifications to OTA requirements

OTA-based resonators are commonly used in active filter design, thus their specifications are imposed by the filter’s requirements. More precisely, the specifications of the filter translate to the specifications of the OTA inside the resonator. Since the performance of the filter depends on the most selective resonator of the filter, we will focus in this section on the specifications of a resonator such as Q and resonance frequency \( \omega_0 \) and translate them to the specifications of an OTA. An active inductor constructed from two identical OTAs and a capacitor \( c_L \) is shown in Figure 3.1 along with its equivalent circuit. Assuming that, in a narrow-band system, the OTA has a constant transconductance of \( g_m \), a finite output resistance of \( r_o = 1/g_o \) and an input and output parasitic capacitance \( c_p \), the equivalent circuit’s parameters are

\[
L = \frac{c_L + c_p}{g_m^2}, \quad R_s = \frac{g_o}{g_m^2}, \quad R_p = \frac{1}{g_o}.
\]
Figure 3.1 – A resonator consists of an active inductor (in black) and a loading capacitance $c_R$ with its equivalent RLC circuit. $g_m$ is the transconductance. $c_p$ and $r_o = 1/g_o$ are the output parasitic capacitance and output resistance of the OTA, respectively.

To examine the $Q$ and $\omega_0$ of a resonator, consider the case in which a capacitor $c_R$ is connected in parallel to the active inductor of Figure 3.1 to obtain the resonator. The RLC network impedance can be written as:

$$Z(s) = \frac{sL + R_s}{s^2 + s \left(\frac{1}{R_p(c_R + c_p)} + \frac{R_s}{L}\right) + \frac{R_s + R_p}{R_p(c_R + c_p)+L}}. \quad (3.2)$$

Considering complex conjugate poles for the resonator, its resonance frequency can be written as:

$$\omega_0 = \sqrt{\frac{R_s + R_p}{R_p(c_R + c_p)L}} = \sqrt{\frac{g_o^2 + g_m^2}{(c_R + c_p)(c_L + c_p)}}. \quad (3.3)$$

It is clear that the input parasitic capacitance and the finite output resistance of the OTA cause a frequency shift in the resonance frequency of the resonator and increase the active inductor value. Assuming $c_p = 0$ ($c_p$ can still be modeled with $c_R$ and $c_L$), $c_R = c_L$ and $g_m \gg g_o$, the resonance frequency in (3.3) will be equal to the GBW of the OTA.

3.1.2.1 The resonator’s $Q$

The main specification of a resonator is its $Q$; its other specifications such as noise in active inductor and the resonator’s dynamic range pertain to that [89]. Based on the definition of $Q$ in [92], from (3.1) and (3.2) and considering complex conjugate poles for the resonator, the $Q$
of the resonator can be written as:

\[ Q \triangleq \frac{-\omega_0}{R_p c_R + R_s L} = \sqrt{\frac{(g_o^2 + g_m^2)(c_R + c_p)(c_L + c_p)}{g_o(c_R + c_L + 2c_p)}} = \sqrt{\frac{2g_o}{g_o}} \bigg|_{c_R = c_L} \frac{g_m}{2g_o} \bigg|_{g_m > g_o} = \frac{A}{2}, \quad (3.4) \]

where \( A = g_m / g_o \) is the DC gain of the OTA. The maximum value of (3.4) occurs when \( c_L = c_R \), and in this case with a realistic assumption of \( g_m \gg g_o \), the maximum \( Q \) will be half of the DC gain of the OTA. Therefore, to design a resonator with quality factor of \( Q \) with an OTA-based gyrator, the gain of the OTA should be at least twice the required \( Q \). Note that in the derivation of (3.4) only the dominant pole of the OTA is considered.

Apart from the dominant pole of the OTA, \( \omega_1 \), which is defined by its output resistance \((1/g_o)\) and the loading capacitance \((c_L)\), OTAs have some internal poles. These poles cause a phase shift in the signal through the OTA, and in the loop of the gyrator this phase shift changes the gyrator behavior at high frequencies. In that case the active inductor shows a negative resistance and causes peaking in the Q of the resonator as well as in its frequency response. By considering that the resonator’s internal poles are higher than its resonance frequency, the \( Q \) of the resonator in Figure 3.1 can be approximated as [90]:

\[ \frac{1}{Q} \approx -2A - 2\omega_0 \sum_{j=2}^{\infty} \frac{1}{\omega_j}, \quad (3.5) \]

where \( A \) is the OTA’s DC gain, \( \omega_0 \) is the resonance frequency and \( \omega_j \)'s are the internal poles of the OTA. It is clear that the second term of (3.5), which is due to the existence of the internal poles, enhances the \( Q \) of the resonator. In fact, as the resonance frequency approaches the internal poles \((\omega_j)\), the \( Q \) increases. However, the excess phase caused by these poles decreases the PM of the OTA and may result in an oscillation. Any zero in the OTA’s transfer function causes the opposite effect on the PM and \( Q \).

The second pole of the OTA \((\omega_2)\) as its dominant internal pole has the main contribution in the resonator’s \( Q \) enhancement. To elaborate, assuming that the OTA’s other internal poles are far from its second pole, from (3.5) the \( Q \) of a resonator by considering only \( \omega_1 \) and \( \omega_2 \) can be written as:

\[ Q = \frac{\beta}{\beta - 2} Q_i, \quad (3.6) \]
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where

\[ \tilde{\beta} = \frac{\omega_2}{Q_i \omega_0}, \]  

(3.7)

and \( Q_i = A/2 \) is the Q of the resonator where the resonator does not have any internal pole. It can be seen from (3.6) that for \( \beta \gg 1 (\omega_2 \gg A\omega_0) \), the Q of the resonator approaches the ideal quality factor \( (Q_i = A/2, \text{ see } (3.4)) \). On the other hand, decreasing \( \omega_2 \) toward \( A\omega_0 \) enhances the resonator’s Q by increasing the value of the parallel resistance of the active inductor. For this reason, theoretically at \( \omega_2 = A\omega_0 \), the Q goes to infinity which may cause an oscillation in the resonator.

To examine this in greater detail, two simulations were carried out by employing an OTA with one internal pole at \( \omega_2 \). First, we simulated a resonator to see the variation of its Q over different positions of \( \omega_2 \) to demonstrate the behavior of (3.6). Then we simulated the active inductor of the resonator to see when it shows a negative resistance. The active inductor in these simulations is the same as the one in Figure 3.1 with one internal pole and the assumption of no parasitic capacitance \( (c_p = 0) \). The resonator uses the same inductor loaded by the capacitance \( c_L \) \( (c_R = c_L \text{ in Figure 3.1}) \). The simulation results are shown in Figure 3.2 and Figure 3.3.

Figure 3.2 shows the variation of Q versus \( \beta \) (or \( \omega_2 \), assuming that \( \omega_0 \) and \( Q_i \) are constant) regardless of the value of \( Q_i \). Here the Q is the quality factor of the resonator which is calculated based on the definition of Q for a resonator:

\[ Q \triangleq \frac{\omega_0}{\Delta \omega}, \]  

(3.8)

where \( \omega_0 \) and \( \Delta \omega \) are the resonance frequency and 3-dB BW of the resonator, respectively. \( Q_i = A/2 \) is the Q when the OTA has no internal pole \( (\omega_2 \rightarrow \infty; \text{ same as the Q in } (3.4)) \). The simulation result in Figure 3.2 shows that the definition of the Q in (3.6) is completely in accordance with the definition of the resonator’s Q in (3.8). It indicates that, regardless of the value of \( Q_i \) and \( \omega_0 \), around \( \beta = 2 (\omega_2 = 2Q_i\omega_0) \), the Q shows a peaking in its value. This figure or the definition of Q in (3.6) can be used as a chart or formula either to locate the \( \omega_2 \) in the OTA design process based on the amount of tolerable variation of the Q of a resonator or to anticipate the Q of a resonator based on the specification of its OTA. For example, for \( \omega_2 = 4Q_i\omega_0 \), the Q is twice the value that was intended \( (Q_i) \). Figure 3.2 also shows that to keep the variation of Q within 25%, \( \omega_2 \) should be placed at least at \( 10Q_i\omega_0 \).

The variation of Q in Figure 3.2 is due to the negative resistance that the inductor shows because of its internal pole. Figure 3.3 indicates when the active inductor starts to show negative resistance for a different location of \( \omega_2 \). The \( \omega_N \) in this figure is the zero-resistance frequency of the active inductor which, for frequencies lower and higher than \( \omega_N \), the inductor shows positive and negative resistance, respectively. To compare Figure 3.3 with Figure 3.2, \( \omega_N \) and \( \omega_2 \) are normalized by \( \omega_0 \) and \( Q_i \) of the resonator of Figure 3.2. Looking at \( \beta = 2 \) in Figure 3.3, one can see that the zero resistance happens at \( \omega_N = \omega_0 \). This means that the
3.1. Controlled-Q resonator

Figure 3.2 – Design chart of the variation of the resonator’s Q versus $\beta = \omega_2/Q_i\omega_0$ (see (3.7)) while sweeping the second pole ($\omega_2$) of the OTA; $Q_i$ is the Q when the OTA does not have the second pole (i.e. $\omega_2 \rightarrow \infty$) and $\omega_0$ is the resonance frequency of the resonator.

inductor does not show any resistance and that is why the resonator shows a peaking of Q for the same location of the internal pole.

Figure 3.3 – The zero-resistance frequency ($\omega_N$) of the active inductor versus $\beta = \omega_2/Q_i\omega_0$ (see (3.7)) while sweeping the second pole ($\omega_2$) of the OTA; $\omega_0$ is the resonance frequency of the resonator that is made by the active inductor loaded by capacitance $C_L$, and $Q_i$ is the Q of the resonator when $\omega_2 \rightarrow \infty$.

3.1.2.2 Sensitivity of the resonator’s Q

As is shown in Figure 3.2, the resonator’s Q is a function of $\omega_2$ and $A$ for a fixed resonance frequency. Since the gain and the second pole of an OTA might change due to process, voltage
Figure 3.4 – Variation in gain and Q with tuning of $\omega_0$ (at 18.7, 21, 23 MHz) for the two cases of $\beta = 3$ and $\beta = 80$, along with the resonator’s response in ideal case when the OTA has no second pole ($\omega_2 \to \infty$).

and temperature (PVT) variations, knowing the sensitivity of the Q to these variables helps us to design a more robust resonator to these variations. From (3.6) the sensitivity of the Q to $\omega_2$ and $A$ can be calculated respectively, as:

$$S_{\omega_2}^Q = \frac{\partial Q}{\partial \omega_2} = \frac{-\beta_0 \omega_0}{\omega_2 - \beta_0 \omega_0} = \frac{-2}{\beta - 2}, \quad (3.9)$$

and

$$S_A^Q = \frac{\partial Q}{\partial A} = \frac{2\omega_2}{\omega_2 - \beta_0 \omega_0} = \frac{2\beta}{\beta - 2}. \quad (3.10)$$

It shows that the Q is very sensitive around $\beta = 2$ to both the gain and the second pole. Therefore, for more robust design, this region should be avoided. Also comparing (3.9) and (3.10) shows that the Q is always more sensitive to the gain than $\omega_2$ and increasing the $\beta$ reduces the sensitivity of the Q.

A simulation was carried out to show the effect of the variation of Q over $\beta$ on the resonator response for three different resonance frequencies (18.7, 21, 23 MHz). The results are shown in Figure 3.4.

The resonator was designed to have the $Q_i = 20$ and the second pole of the OTA was located at 3 and 80 times the $Q_i \omega_0$ ($\beta = 3$ and 80 in Figure 3.2). Furthermore, the resonator’s response for one resonance frequency in the ideal case when the OTA has no second pole
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\((\omega_2 \to \infty)\) is also shown in Figure 3.4. As was expected from Figure 3.2, the Q of the resonator made by the OTA with its second pole at \(80Q_i\omega_0\) is coincident with the ideal case. In fact, in this case, from (3.6) the variation of Q is less than 2.5% of the ideal case. However, there is some peaking in the resonator response for the other case, which results in enhancing the Q. Therefore, Figure 3.2 can be utilized to locate the second pole of the OTA in the design process of the resonator based on the tolerable variation of the Q. However, since PVT variation effects can cause a slight shift in \(\omega_2\), a high ratio of \(Q/Q_i\), where the Q of a resonator is very sensitive to \(\omega_2\), should be avoided to have a predictable Q.

3.1.2.3 Stability

It has been shown that it is possible to take advantage of the OTA’s second pole to enhance the Q of a resonator by placing it the right distance from \(\omega_0\). This enhancement can be achieved with no extra power consumption. However, as the \(\omega_2\) approaches the \(\omega_0\), the excess phase it causes reduces the PM of the OTA. On the other hand, the OTA should have sufficient PM at its unity-gain frequency to ensure its stability. The PM of the OTA, considering its dominant and all internal poles, can be written as:

\[
PM = 180^\circ - \sum_{j=1}^{\infty} \tan^{-1}\left(\frac{\omega_0}{\omega_j}\right).
\]  

(3.11)

From (4.38) it can be deduced that for an OTA with no internal pole other than \(\omega_2\), more than 68° of PM is achieved when

\[
\omega_2 > 2.5\omega_0.
\]  

(3.12)

Since the DC gain of the OTAs (A) is usually more than 2.5, to avoid possible oscillation and peaking in resonator’s Q, the inequality in (3.12) can be written as:

\[
\omega_2 > A\omega_0.
\]  

(3.13)

Of course, as was shown before, due to the high sensitivity of the Q to \(\omega_2\) around \(A\omega_0\), this region should be avoided for \(\omega_2\). For OTAs with more than one internal pole, the inequality in (3.13) is still valid to have less sensitive Q, however, the PM in (4.38) has to be considered for the stability of the OTA.

3.1.3 Design methodology for a controlled-Q resonator

This section presents the design methodology for a resonator with a Q of 10 and a resonance frequency at 8 MHz which was fabricated using UMC 0.18 μm CMOS technology. A photograph of the test chip is shown in Figure 3.5.

The design procedure starts with choosing a value for the loading capacitance since all the
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Figure 3.5 – Micro photograph of the resonator implemented in UMC 0.18 μm CMOS technology; the resonator occupies $370 \times 475 \mu m$.

parameters of the resonator are related to that. Usually the minimum value of the capacitor is set by the noise requirement of the resonator [90] and, based on this fact, a differential load of $c_L = 1.2 \text{ pF}$ was chosen in this design. The next step is to design a gyrator that consists of two identical OTAs.

OTA’s topologies are well explained in [93] and the folded cascode topology was preferred for this design owing to the fact that its second pole is located at very high frequency compared to other topologies, i.e. telescopic or symmetrical OTA, without any extra compensation techniques. More importantly, the second pole of a folded cascode OTA can be set independently from its transconductance. The schematic of the folded cascode is shown in Figure 3.6.

![Figure 3.6 – Schematic of the folded cascode OTA; $c_L = 1.2 \text{ pF.}$.](image)

The next step is to set the value of $\omega_0 = 2\pi f_0$ and $Q$. The $\omega_0$ is set by the transconductance of differential pair M1 ($g_{m1}$). For the first-guess design, from (3.3) and assuming that $g_{m1} \gg g_o$ and $c_L = c_R \gg c_p$, for $f_0 = 8 \text{ MHz}$ and $c_L = 1.2 \text{ pF}$, $g_{m1} = \omega_0 c_L$ can be calculated as $60 \mu S$. To size M1, its overdrive voltage also needs to be set. This voltage affects the linearity of the resonator.
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For a low-power design, 300 mV is chosen as the differential pair overdrive. The overdrive voltage along with the \( g_{m1} \) sets the bias current of M1a and M1b at around 18 \( \mu \)A. To have a good trade-off between the gain and the transition frequency \( (f_T) \) of the differential pair, the length of M1 was chosen to be 1 \( \mu \)m and its width was chosen to provide the bias current.

After the design of the differential pair, the next step is to design the output stage of the OTA. As was discussed in section 3.1.2, the DC gain of the OTA limits the maximum Q and the second pole must be placed beyond \( A \omega_0 \). These are the two main criteria which should be considered to design the output stage of the OTA. In this case, to save power a maximum variation of 25\% of Q is acceptable which, from (3.6), leads to \( \beta = 10 \) and the \( Q_i \) is chosen to be 10. Therefore, the second pole of the OTA should be placed at \( f_2 = \beta Q_1 f_0 = 800 \) MHz. For the OTA in Figure 3.6, its second pole can be written as:

\[
f_2 = \frac{g_{m4}}{4\pi C_{n1}},
\]

where \( g_{m4} \) is the transconductance of the transistor M4 and \( C_{n1} \) is the parasitic capacitance at node 1 which can be written as:

\[
C_{n1} = C_{GS4} + C_{DB1} + C_{DB3}.
\]

Therefore, to have \( f_2 \) at around 800 MHz, a high value of \( g_{m4} \), as well as low parasitic capacitance at node 1, is needed. The latter has been achieved by choosing a channel length of 300 nm and 250 nm for M3 and M4, respectively. The bias current can be set by considering the required slew rate. In this design, since the resonator might be tuned up to 20 MHz, to satisfy the slew rate for 400 mV of output swing at a maximum frequency of 20 MHz, a bias current greater than 100 \( \mu \)A is needed. In this case, the low overdrive for M4 helps to increase the \( g_{m4} \); the \( g_{m4} = 1 \) mS has been achieved by an overdrive of 230 mV. Transistor M3 is 21 \( \mu \)m wide to provide the current for the input and output stage of the OTA. Moreover, its overdrive along with the overdrive of M2 are adjusted to tune the \( g_{m1} \). The simulated parasitic capacitance of \( C_{n1} \) is about 90 fF which from (3.14) places the second pole of the OTA at 880 MHz. In the active load, M5 has a short channel to have high \( f_T \) while M6 is designed for CM control. Also, the differential load capacitor of \( c_L \) is implemented with a 2\( c_L \) capacitor connected to the ground to provide the path also for the CM signal. The transistors’ size and bias currents are optimized in a Cadence® Spectre® simulator and the final values are shown in Table 3.1.

<table>
<thead>
<tr>
<th>Device</th>
<th>M1a,b</th>
<th>M2</th>
<th>M3a,b</th>
<th>M4a,b</th>
<th>M5a,b</th>
<th>M6a,b</th>
<th>MC1</th>
<th>MC2a,b,c</th>
<th>MC3a,b</th>
<th>MC4a,b</th>
</tr>
</thead>
<tbody>
<tr>
<td>W/L ( \mu )m</td>
<td>3/1</td>
<td>24.4/3</td>
<td>24.9/0.3</td>
<td>20/0.25</td>
<td>4/0.5</td>
<td>8/1</td>
<td>20/2</td>
<td>10/1</td>
<td>10/1</td>
<td>1/3</td>
</tr>
<tr>
<td>( I_{ds} ) ( \mu A )</td>
<td>17</td>
<td>34</td>
<td>118</td>
<td>101</td>
<td>101</td>
<td>101</td>
<td>15</td>
<td>3.75</td>
<td>7.5</td>
<td>5</td>
</tr>
</tbody>
</table>

The fabricated resonator consumes 520 \( \mu \)A from 1.8 V resonating at 8 MHz. The measured
responses of the resonator for the resonance frequencies at 8, 15 and 20 MHz are shown in Figure 3.7. Considering $f_2 = 880 \text{ MHz}$ and $Q_i = 10$, the resonator shows an expected $Q$ of 11 at 8 MHz which roughly corresponds to $\beta = 11$ in Figure 3.2. Furthermore, the $Q$ at other resonance frequencies were also predictable because for resonance frequencies at 15 and 20 MHz, $\beta$ is equal to 5.8 and 4.4, which correspond to a $Q$ of 15.5 and 18.5 from (3.6), respectively. Considering the PVT variations, the measured results are therefore well in agreement with (3.6) and Figure 3.2, which validates their use for the proposed design methodology.

### 3.1.4 Conclusions

The design methodology of a low-power high-$Q$ OTA-based resonator was presented in this section. The resonator’s $Q$ and resonance frequency were translated to the specifications of the OTA. Furthermore, a comprehensive analysis on the effect of the OTA’s second pole on the resonator’s $Q$ was carried out with modeling, mathematical derivation and simulations. It showed that the second pole of the OTA has a direct influence on the resonator’s $Q$ and its variation in response to tuning the resonator’s resonance frequency ($\omega_0$). The analysis provided a design chart and methodology which takes advantage of the OTA’s second pole to enhance the resonator’s $Q$. Moreover, the enhanced $Q$ is predictable and can be controlled during the design process. To validate the proposed approach, a resonator using the proposed methodology was fabricated. The measurement results show a $Q$ of 11, slightly above the required $Q$ of 10 resonating at the correct resonance frequency of 8 MHz which was expected from the design chart in Figure 3.2.
3.2 Common-mode stability of OTA-based gyrators

System-on-chip integration demands that a fully differential configuration be able to reject the CM disturbances generated by the digital circuitries, clock drivers, substrate coupling and so on. On the other hand, CMFB amplifiers are an essential part of any fully differential amplifier. Therefore, during the design of fully differential active inductors and gyrators, the CM stability of the OTAs must be considered. A fully differential representation of the high-level schematic of the gyrator in Figure 3.1 is shown in Figure 3.8. Although the two OTAs in Figure 3.8 are in negative feedback for their differential signals, the loop still acts as a positive feedback for CM signals. This positive feedback may cause CM oscillation or latching in a gyrator. CM stability is the main problem in gyrator design and is often overlooked in the literature [94, 95].

![Figure 3.8 – Fully differential representation of the gyrator-based active inductor in Figure 3.1 with its equivalent RLC circuit.](image)

This section is published in [96] which proposes, for the first time, a comprehensive analysis that accounts for the CM stability of the OTA-based gyrators. A CM equivalent model of an OTA and a gyrator are used for the analysis. It provides CM stability requirements which can be easily considered during the design process of a CMFB amplifier. Moreover, based on these requirements and considering all the practical issues, a design methodology for CM stability of OTA-based gyrators is also presented. Finally, the developed methodology is validated by simulations and measurements. For this purpose, a resonator with 20 MHz resonance frequency and a Q of 20 is fabricated using the UMC 0.18 µm CMOS technology and is fully characterized [91].

The remainder of this section is organized as follows: A mathematical model and derivation for the CM stability analysis of a gyrator is presented in section 3.2.1. A design methodology to ensure the CM stability of a resonator is proposed in section 3.2.2. Section 3.2.3 presents a practical design procedure based on the proposed methodology. A case study is demonstrated in section 3.2.4. Finally, section 3.2.5 provides the conclusions.
3.2.1 Common-mode stability: Modeling and analysis

Fully differential OTAs must be able to reject the CM disturbances of the circuit and they need CMFB amplifiers to regulate their output CM voltage. The input and output of the CMFB amplifier are the output of the main amplifier. This means that the CMFB amplifier is connected in unity feedback. As a result, its stabilization is usually troublesome since amplifiers are more prone to instability when they are configured as a unity feedback, and thus it might require more power to ensure stability. Besides that, there is a feedback loop in the gyrator (Figure 3.8) which consists of two OTAs. Without a proper CMFB amplifier for the OTAs, this loop can act as a positive feedback from the CM point of view which may cause a CM oscillation or latching in the gyrator. This oscillation happens inside the loop of the gyrator and is different from the CM oscillation that can happen inside an OTA due to an improper CMFB amplifier. Figure 3.9 shows the equivalent CM representation of a gyrator consisting of two folded cascode OTAs with their CMFB amplifiers. The path of the CM positive feedback of the gyrator is shown with a dashed line. This positive feedback is the reason for more stringent requirements for the OTA and its CMFB amplifier in a gyrator loop. In this section, we analyze the CM stability of a gyrator by means of a mathematical model and provide stability conditions for it.

Figure 3.9 – CM equivalent circuit of a gyrator realized by two OTAs; the gyrator’s CM path is shown by the dashed line.

3.2.1.1 Common-mode stability of an OTA

The block diagram of an OTA and its CMFB amplifier is shown in Figure 3.10. Since the focus of this section is on the CM, $G_{CM}(j\omega)$ in Figure 3.10 is the CM transfer function of a differential OTA without a CMFB amplifier, and $F(j\omega)$ is its CMFB amplifier. For simplicity, it is assumed that the $G_{CM}(j\omega)$ has two poles, one dominant due to the capacitive loading of the OTA ($\omega_1$) and an internal pole ($\omega_2$). The same assumption can be used for $F(j\omega)$; apart from an internal pole ($\omega_4$), $F(j\omega)$ has a dominant pole ($\omega_3$) which is due to its capacitive loading. Furthermore, $G_0$ and $k$ are the DC gain of $G_{CM}(j\omega)$ and $F(j\omega)$, respectively. Therefore, the overall CM
3.2. Common-mode stability of OTA-based gyrators

The transfer function of the OTA in Figure 3.10 can be written as:

\[ H(j\omega) = \frac{G_{CM}(j\omega)}{1 + F(j\omega)}, \]  

where

\[ G_{CM}(j\omega) = \frac{G_0}{(1 + j\omega/\omega_1)(1 + j\omega/\omega_2)} \quad \omega_2 > \omega_1, \]  
\[ F(j\omega) = \frac{k}{(1 + j\omega/\omega_3)(1 + j\omega/\omega_4)} \quad \omega_4 > \omega_3. \]

Assuming that the OTA has been designed for differential mode performance and that it is stable, then the values of \( \omega_1, \omega_2 \) and \( G_0 \) are fixed, which leaves us with \( \omega_3, \omega_4 \) and \( k \) to be set for the design of a CMFB amplifier. Note that \( G_{CM}(j\omega) \) and \( F(j\omega) \) see the same load because they share the loading stage and their outputs are at the same point (assuming the loading capacitors are connected to the ground to provide the path for the CM signal). Accordingly, the dominant pole of \( G_{CM}(j\omega) \) and \( F(j\omega) \) are the same (\( \omega_1 = \omega_3 \)) which leaves us with only \( \omega_4 \) and \( k \) to be defined. Considering (3.16), \( H(j\omega) \) is a negative feedback system and one way to examine its stability is to draw the Bode plot of its loop gain \( (F(j\omega)) \) which for the two-pole system of (3.18) is straightforward. The parameter \( k \) is the DC gain of the CMFB amplifier which sets the error of the CM output voltage of the OTA. It also sets the common-mode gain-bandwidth product (GBW\textsubscript{CM}) of the OTA since \( \omega_3 \) is already set. The higher the \( k \) is, the lower the error of the CM voltage and the higher the GBW\textsubscript{CM} will be. Although a larger value of \( k \) is desired, increasing \( k \) increases the power consumption of the CMFB amplifier. Therefore, the minimum value for \( k \) can be chosen based on the required GBW\textsubscript{CM}. For a chosen value of \( k \), the position of \( \omega_4 \) sets the PM of the CMFB amplifier, and thus plays the main role in the CM stability of the OTA. For the sake of stability, \( \omega_4 \) should be placed beyond the GBW\textsubscript{CM}, thus requiring more power. However, the common technique to reduce this power is to set \( \omega_4 \) lower than GBW\textsubscript{CM} and introduce a zero at \( \omega_5 \) (i.e. by means of a compensation capacitor) into the transfer function of \( F(j\omega) \) to gain enough PM to ensure the stability of \( H(j\omega) \). In this
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case, \( F(j\omega) \) can be rewritten as:

\[
F(j\omega) = \frac{k(1 + j\omega/\omega_5)}{(1 + j\omega/\omega_3)(1 + j\omega/\omega_4)} \quad \omega_4 > \omega_3.
\] (3.19)

### 3.2.1.2 Common-mode stability of a gyrator

For the stability of the CM positive feedback of a gyrator, the CMFB amplifier needs extra attention. Gyrators are normally loaded with two capacitors to construct a resonator. For simplicity let's assume that the value of these two capacitors is the same. So if \( H(j\omega) \) is the CM transfer function of the OTA with its CMFB amplifier which is loaded with a capacitor \( 2c_L \) (see Figure 3.10), the block diagram of the CM representation of a resonator can be drawn as in Figure 3.11.

![Block diagram of a CM representation of a resonator](image)

Figure 3.11 – Block diagram of a CM representation of a resonator; \( H(j\omega) \) is the CM transfer function of the OTA with its CMFB amplifier (Figure 3.10).

From Figure 3.11 the CM transfer function of the resonator \( T(j\omega) \) can be written as:

\[
T(j\omega) = \frac{H(j\omega)}{1 - H^2(j\omega)} = \frac{H(j\omega)}{[1 - H(j\omega)][1 + H(j\omega)]}.
\] (3.20)

It seems from (3.20) that \( T(j\omega) \) consists of the cascade of a negative and a positive feedback system. Assuming \( H(j\omega) \) is stable by choosing appropriate values for \( k \) and \( \omega_4 \), the stability of \( T(j\omega) \) can be examined by looking at the Bode plot of the loop gain \( H(j\omega) \) of each system. Having enough PM for the stability of \( T(j\omega) \) for both positive and negative feedback systems of \( H(j\omega) \) is cumbersome and—especially due to the parasitic poles and zeroes in the circuit—is tricky to control. Therefore, a sufficient condition to ensure the stability of \( T(j\omega) \) is to avoid any zero crossing in the magnitude Bode plot of \( H(j\omega) \), i.e.:

\[
|H(j\omega)| = \left| \frac{G_{CM}(j\omega)}{1 + F(j\omega)} \right| < 1.
\] (3.21)

Referring to Figure 3.10 and by substituting (3.17) and (3.19) in (3.16), the transfer function
of $H(j\omega)$ can be rewritten as (3.22), considering that $\omega_1 = \omega_3$.

$$H(j\omega) = \frac{G_0}{1 + \frac{k}{k+1}} \frac{\frac{G_0}{k+1} \left( 1 + j\frac{\omega}{\omega_4} \right) \left( 1 + j\frac{\omega}{\omega_3} + \frac{1}{\omega_4} + \frac{k}{\omega_5} \right) - \frac{\omega^2}{(k+1)\omega_3\omega_4}}{\omega_2 > \omega_1, \quad \omega_4 > \omega_3}. \quad (3.22)$$

It can be deduced from (3.22) that $H(j\omega)$ has one zero and three poles. To locate them on the Bode plot it is helpful to look back at the poles of $G_{CM}(j\omega)$ and $F(j\omega)$. For a differential OTA $G(j\omega)$, the internal pole should be located far beyond its GBW [91]. Therefore its dominant and internal poles are fairly separated from each other. Although $\omega_1$ and $\omega_2$ are the CM poles of $G(j\omega)$, they cannot be far away from their differential counterparts, thus it easily can be assumed that $\omega_2 \gg \omega_1$. The position of the poles and zero of $F(j\omega)$ is taken as in (3.18) (i.e., $\omega_4 > \omega_3$). Based on these assumptions, the relative position of the poles and zero on the frequency axis is shown in Figure 3.12.

![Figure 3.12 – Bode magnitude plot of $G_{CM}(j\omega)$, $F(j\omega)$ and $H(j\omega)$, for the case of real poles in $H(j\omega)$.](image)

Apart from $\omega_2$, $H(j\omega)$ has two other poles ($\omega_6$ and $\omega_7$). From (3.22) it can be deduced that they are either negative and real, or a pair of complex conjugate poles. Each case will be described separately.
3.2.1.3 Real poles

If $\omega_6$ and $\omega_7$ are real, assuming that $\omega_6 \leq \omega_7$, the pole of interest that may cause instability in $T(j\omega)$ is $\omega_6$. In other words, $\omega_6$ should compensate for the effect of the zero at $\omega_4$ to avoid zero crossing in $H(j\omega)$. Figure 3.12 shows a magnitude Bode plot of $G_{CM}(j\omega)$ and $F(j\omega)$ as well as $H(j\omega)$ for one case where $\omega_4 < \omega_6 < \omega_2$ and $k > G_0$. If $\omega_6$ occurs before $\omega_4$ then the effect of the zero at $\omega_4$ is compensated for and the condition for no zero crossing is ensured. The problem starts when $\omega_6$ takes place after $\omega_4$ and rises by increasing the value of $\omega_6 - \omega_4$. The worst case is when $\omega_6$ occurs at a higher frequency than $\omega_2$; in that case, to ensure the stability, the required value of $k$ can be derived as:

$$20\log_{10}\left(\frac{1 + k}{G_0}\right) - 20\log_{10}\left(\frac{\omega_2}{\omega_4}\right) = GM,$$  \hspace{1cm} (3.23)

where $GM$ is the safety margin to avoid zero crossing due to the approximations used with the modeling of $G_{CM}(j\omega)$ and $F(j\omega)$. Assuming $GM = 20$ dB in (3.23), the minimum value of $k$ can be calculated as:

$$k = \frac{10\omega_2 G_0}{\omega_4} - 1,$$  \hspace{1cm} (3.24)

where $\omega_4$ comes from the stability condition of $H(j\omega)$. However, it is preferred to place $\omega_6$ somewhere between $\omega_4$ and $\omega_2$ as shown in Figure 3.12. In this case it is possible to push $\omega_4$ to a lower value and save power.

3.2.1.4 Complex conjugate poles

If the system has a pair of complex conjugate poles ($\omega_6 = \omega_7^*$) close to the imaginary axis, the magnitude of the frequency response has a peak, or resonance, at frequencies in the proximity of the pole which for (3.22) happens at (3.25). The real part of the resonance frequency can be calculated as (3.26). Increasing it, i.e. placing $\omega_{6,7}$ away from the imaginary axis of the s-plane, decreases the magnitude of the peak at the resonance frequency.

$$|\omega_{6,7}| = \sqrt{(1 + k)\omega_3\omega_4}.$$  \hspace{1cm} (3.25)

$$Re(\omega_{6,7}) = \frac{1}{2} \left( \omega_3 + \omega_4 + \frac{k\omega_3\omega_4}{\omega_5} \right).$$  \hspace{1cm} (3.26)

From (3.25) and (3.26) it is clear that the frequency and the magnitude of the peaking can be controlled by the value of $k$ and $\omega_4$, while $\omega_5$ sets the magnitude of the peak independently. The magnitude Bode plot of $H(j\omega)$ along with $G_{CM}(j\omega)$ and $F(j\omega)$ is sketched by inspection on the position of the poles and zeroes in Figure 3.13 for the case of the existence of a pair of complex conjugate poles in $H(j\omega)$.  

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3.2 Common-mode stability of OTA-based gyrators

\[
\omega_1 = \omega_3, \quad \omega_2, \quad \omega_6, \omega_7
\]
\[
\omega_4, \ \omega_5
\]

\[
|GCM(j\omega)|, \quad |F(j\omega)|, \quad |H(j\omega)|
\]

![Figure 3.13 – Bode magnitude plot of \( G_{CM}(j\omega), F(j\omega) \) and \( H(j\omega) \), for the case of complex conjugate poles in \( H(j\omega) \).](image)

To avoid any zero crossing in the magnitude Bode plot of \( H(j\omega) \) in Figure 3.13, due to the existence of a zero at \( \omega_4 \) in \( H(j\omega) \), a high value of \( k \) is required. Besides, placing the compensation zero (\( \omega_5 \)) close to or even before \( \omega_4 \) increases (3.26) and thus helps to decrease the peaking in the magnitude response of \( H(j\omega) \) and avoids zero crossing.

### 3.2.2 Common-mode stability: Design methodology

The mathematical analysis and the requirements to ensure the CM stability of a gyrator was presented in section 3.2.1.2. In this section, we provide a design methodology for the CM stability of a gyrator that transforms the requirements in section 3.2.1.2 to the more practical ones that can easily be verified during the CAD-based CMFB amplifier design. These requirements can be developed fairly easily at high and low frequencies, while the requirements on \( F(j\omega) \) for the transition frequency are more difficult to determine. Assuming that \( H(j\omega) \) is stable (see section 3.2.1.1), these requirements are as follows:

#### 3.2.2.1 Stability at low frequencies

At low frequencies, if the magnitude of \( F(j\omega) \) is much larger than 1, the following approximations can be made:

\[
|F(j\omega)| \gg 1 \Rightarrow \left| \frac{1}{1 + F(j\omega)} \right| \approx \left| \frac{1}{F(j\omega)} \right|.
\] (3.27)
If (3.27) is used in (3.21) the following approximate requirement results:

\[
\left| \frac{G_{CM}(j\omega)}{F(j\omega)} \right| < 1. \tag{3.28}
\]

Thus, the requirement of (3.21) is very close to being satisfied at low frequencies if (3.28) is satisfied. The inequality in (3.28) means that, at low frequencies, a large value of \(|F(j\omega)|\) is needed, and that \(|F(j\omega)| > |G_{CM}(j\omega)|\). Hence, a high DC gain for \(|F(j\omega)|\) is required. Indeed, this is the equivalent of increasing the value of (3.23) and (3.26) to avoid zero crossing in \(|H(j\omega)|\).

### 3.2.2.2 Stability at high frequencies

At high frequencies, if the magnitude of \(F(j\omega)\) is much smaller than 1, the following approximations can be made:

\[
|F(j\omega)| \ll 1 \Rightarrow \left| \frac{1}{1 + F(j\omega)} \right| \approx 1. \tag{3.29}
\]

If (3.29) is used in (3.21) the following approximate requirement results:

\[
|G_{CM}(j\omega)| < 1. \tag{3.30}
\]

Therefore, the requirement of (3.21) is very close to being satisfied at high frequencies if (3.30) is satisfied. The inequality in (3.30) means that the CM gain of the OTA should be made small enough at high frequencies, and that \(|F(j\omega)| \ll 1\). This condition is commonly satisfied by using resonator’s loading capacitors \(c_L\) connected to GND rather than a purely differential load.

### 3.2.2.3 Stability within the transition band

The requirement of \(F(j\omega)\) in the transition band is more difficult to determine because the assumptions leading to (3.27) and (3.29) are no longer valid. However, it is clear that \(|F(j\omega)|\) must change from being large at low frequencies to being small at high frequencies, and thus somewhere in the transition band \(|F(j\omega)|\) has its crossover frequency \(\omega_c\) with the PM \(\phi_m\) where \(|F(j\omega_c)| = 1\). At \(\omega_c\), we have:

\[
|1 + F(j\omega_c)| = 1 + e^{j[\pi - \phi_m]} = 2 \sin \left( \frac{\phi_m}{2} \right). \tag{3.31}
\]

By using (3.31) in (3.21) the required PM can be derived as

\[
\phi_{m,\text{min}} \geq 2 \arcsin \left( \frac{|G_{CM}(j\omega_c)|}{2} \right). \tag{3.32}
\]
3.2. Common-mode stability of OTA-based gyrators

Equation (3.32) determines the minimum required PM, but to ensure the stability practically, it must be made larger than the minimum requirement to handle PVT variations.

3.2.3 Design procedure for common-mode stability

Assuming that an OTA has been designed for differential mode performance and is stable, based on the proposed methodology in section 3.2.2, we present the procedure to design a CMFB amplifier that ensures the CM stability of the gyrator or the resonator constructed by that OTA, as follows:

1. Before the CMFB amplifier is designed, its topology has to be chosen. A topology that allows control of the $\text{GBW}_{\text{CM}}$ independent from the differential-mode gain-bandwidth product ($\text{GBW}_{\text{DM}}$) is preferred. The $\text{GBW}_{\text{CM}}$ should be set higher than the $\text{GBW}_{\text{DM}}$ of the main amplifier. Indeed, if the CMFB amplifier were slow, a high-speed spike in the substrate or supply line would put some transistors of the main amplifier in the linear region. The noise or spur generated from digital circuitry or intermodulation (IM) products of an analog part falling within the BW of the main amplifier could cause the same problem. A slow CMFB amplifier would take too much time to restore the biasing, and during that time, the main amplifier would be out of operation. So a CMFB amplifier with a GBW higher than that of the main amplifier is necessary to avoid this situation [93].

2. Part of the output stage of the main OTA is shared between the OTA and its CMFB amplifier. In fact, the CMFB amplifier consists of this shared part and an error amplifier (EA). Therefore, after choosing the topology of the CMFB amplifier, the design narrows to the design of an EA. A static analysis is necessary to find the required output range of the EA to set the CM voltage for the whole possible range of the CM input. At first an ideal amplifier can be used as an EA to simulate and find this range. It is especially important for the gyrator because the two amplifiers are connected in CM positive feedback. Besides, during the startup of the circuit, the CM voltage will sweep from GND to its nominal value. Therefore, the CMFB amplifier should set the right CM output level for all possible CM input ranges or at least avoid any latch up in the output stage of the main amplifier. After finding this range, the EA can be designed to provide this output voltage range. This voltage range is the result of transistors’ width ratios in the EA. Indeed, the design in this stage is to set the size of the transistors of the EA to provide this voltage range. The gain and $\text{GBW}_{\text{CM}}$ will be set later. Note that the ratios of the transistors’ width from this stage should be preserved during the rest of the design.

3. Another consideration is the capacitance loading of the CMFB amplifier if connected to GND. The CMFB amplifier sees twice the capacitive load of the main differential amplifier, which directly affects the $\text{GBW}_{\text{CM}}$ and the PM, and should be taken into account during simulation [97].
4. Finally the frequency response of the CMFB amplifier has to be shaped and the GBW_{CM} has to be set. The simulation setup to find the GBW_{CM} and PM of the CMFB amplifier needs particular attention due to the fact that open-loop simulations are required. In fact the CMFB loop should be broken for these simulations but opening the loop unbalances the biasing of the circuit. A CMFB amplifier provides biasing for the main amplifier as well as for itself since part of the circuit is shared between the two. Therefore, simulating the CMFB amplifier with a fixed and approximated biasing of the main amplifier is not possible. To that effect, the feedback loop should be closed for the DC signal but of course broken for the AC signal. Opening the loop for a small signal is possible with an ideal loop probe or controlled source along with an ideal low-pass filter. Having regard to these considerations as well as stability conditions presented in section 3.2.2, the design process for the CMFB amplifier continues to shape its frequency response and set its GBW_{CM}. The frequency response of a CMFB amplifier \( F(j\omega) \) is divided into three regions (low, high and transition frequencies), for which the CMFB amplifier should satisfy some conditions to ensure the CM stability of the gyrator.

At low frequencies, conditions (3.27) and (3.28) should be satisfied so a high DC gain for \( F(j\omega) \) is required. This can be achieved by increasing the transconductance of the input transistors of the EA which also increases the GBW_{CM} of the CMFB amplifier. Note that the transistors' width ratios which were obtained during the static design must be preserved.

At high frequencies, conditions (3.29) and (3.30) should be satisfied. The CMFB amplifier has the same loading capacitance as the OTA, except that the OTA sees it in differential mode (i.e. \( c_L \)) and the CMFB amplifier sees it in common mode (i.e. 2\( c_L \)). To satisfy (3.29) and (3.30) the capacitive load or a part of it should be connected to GND to provide the path also for the CM signals.

At transition frequency, of course the CMFB amplifier should have enough PM for its own stability, but to ensure the stability of the gyrator it should satisfy (3.32) at its unity-gain frequency (\( \omega_c \)). More PM can be achieved by means of a compensation capacitor which introduces a zero in the transfer function of the CMFB amplifier. In fact, gaining more PM by introducing a zero close to the second pole of \( F(j\omega) \) increases (3.26) and places the \( \omega_{6,7} \) away from the imaginary axis of the s-plane.

3.2.4 Case study: A high-quality-factor high-frequency resonator

To clarify and validate the proposed methodology, a resonator with 20 MHz resonance frequency and quality factor around 20 was designed and fabricated using UMC 0.18 \( \mu \)m CMOS technology. The schematic of the test-chip is shown in Figure 3.14 together with the die photograph in Figure 3.15. As the differential mode design was presented in [91], here we focus on the design of the CMFB amplifier.
3.2. Common-mode stability of OTA-based gyrators

Figure 3.14 – Schematic of the implemented circuit to examine the CM stability of the resonator.

Figure 3.15 – Micro photograph of the chip implemented in UMC 0.18 μm CMOS technology.

**Step 1:** The design procedure starts with choosing a value for the loading capacitance because it affects all the parameters for the design of the resonator. Although a lower value of the capacitor works in favor of power consumption and silicon die area, its minimum value is usually set by the noise requirement of the resonator [90]. In this design, based on the noise requirement of the resonator, $c_L = 1.18$ pF was chosen. The input and output CM voltages are set to 900 mV ($VDD/2$) because the OTAs in the resonator are connected back to back in a feedback loop. In other words, the output nodes of one OTA are the input nodes of the following OTA, thus the output CM voltage should be fixed to the value of the input CM voltage.

**Step 2:** The next step is to choose the topology of the OTA. OTA topologies are well explained in [93]. Among the different topologies for OTAs, the folded cascode has three main advantages over the others which makes it the first choice for most designers. The
first advantage is that the CM input voltage range can reach one of the supply rails. The second advantage is that the output stage always conducts current regardless of the input stage. Therefore, the output CM can be obtained even if the input CM would deviate from its typical value. The last advantage, which is very important in resonator design, is that the second pole is located at very high frequency compared to other topologies, i.e. telescopic or symmetrical OTA, without any extra compensation techniques. Therefore, the folded cascode topology was preferred for this design. The schematic of the folded cascode OTA is shown in Figure 3.16. Employing the methodology proposed in section 3.1 [91], the OTA has been designed for its differential mode to have GBW\text{DM} of 20 MHz. The design is similar to the one in Figure 3.6. However, the biasing is tuned to have resonance at 20 MHz. Its second pole has been placed at 880 MHz resulting in a quality factor of 20. The OTA’s core without its biasing circuitry consumes 307 \mu A from 1.8 V. All the sizing and biasing currents are shown in Table 3.2.

Step 3: The third step is to choose the topology of the CMFB amplifier. The schematic of the selected CMFB amplifier is shown in Figure 3.17. It consists of an EA followed by a common-source amplifier that is part of the second stage of the main OTA. The topology in Figure 3.17 was chosen due to the trade-off between power consumption and the feasibility of setting the GBW\text{CM} independently from the main OTA. The GBW\text{CM} depends on the transconductances of MC2a-c and can therefore be set independently from the main amplifier to a higher value than GBW\text{DM}. 

![Figure 3.16 – Schematic of the folded cascode OTA with a differential load of $c_L$.](image-url)
3.2. Common-mode stability of OTA-based gyrators

Figure 3.17 – Common-mode feedback amplifier with the error amplifier in black.

Table 3.2 – Geometry and operating point of transistors of the folded cascode OTA in Figure 3.16 and its CMFB amplifier in Figure 3.17.

<table>
<thead>
<tr>
<th>Device</th>
<th>M1a, b</th>
<th>M2</th>
<th>M3a, b</th>
<th>M4a, b</th>
<th>M5a, b</th>
<th>M6a, b</th>
<th>MC1</th>
<th>MC2a, b, c</th>
<th>MC3a, b</th>
<th>MC4a, b</th>
</tr>
</thead>
<tbody>
<tr>
<td>W/L μm</td>
<td>3/1</td>
<td>24.4/3</td>
<td>24.9/0.3</td>
<td>20/0.25</td>
<td>4/0.5</td>
<td>8/1</td>
<td>20/2</td>
<td>10/1</td>
<td>10/1</td>
<td>1/3</td>
</tr>
<tr>
<td>$I_{ds}$ μA</td>
<td>48.5</td>
<td>97</td>
<td>153.5</td>
<td>105</td>
<td>105</td>
<td>15</td>
<td>3.75</td>
<td>7.5</td>
<td>5</td>
<td></td>
</tr>
</tbody>
</table>

**Step 4:** To find the required output range of the EA to set the CM voltage for the whole possible range of the CM input, an ideal amplifier is used instead of the EA. The simulation result in Figure 3.18 shows that, for the OTA of Figure 3.16, the $V_{cmf}$ (see Figure 3.16) range of 350–600 mV can set the output CM at $900 \pm 1$ mV. For that purpose, without considering the GBW$_{CM}$ and the gain, the size of the transistors MC1–3 have been experimentally determined by changing the width ratio between the differential pair and current mirror while all the lengths have been set to 1 μm. Note that $V_{cmf}$ applies to the gate of M6, and therefore the length of M6 should be large enough to avoid channel length modulation.

**Step 5:** The differential capacitive load $c_L = 1.18$ pF is implemented with two $2c_L$ capacitors connected to the ground to provide the path for the CM signal as well. Although, this capacitor implementation takes four times the die area than implementing it as a differential load, it reduces the parasitics at each output node of the OTA and makes the design more symmetrical.

**Step 6:** The rest of the design is to shape the transfer function of the CMFB amplifier in low and high frequencies according to (3.27)–(3.30). Also the GBW$_{CM}$ should be bigger than GBW$_{DM}$ which is 20 MHz. The GBW$_{CM}$ was chosen to be 30 MHz. These conditions define the
bias current of the CMFB amplifier. Setting this current is possible by changing the number of fingers of MC1–3 while keeping the same width ratio determined in step 4 to preserve the output voltage range of the EA. The DC gain of the CMFB amplifier is set to 82 dB to satisfy (3.27) and (3.28), and connecting the loading capacitance to ground as explained in step 5, helps to meet conditions (3.29) and (3.30). Finally, as the last requirement, the PM of \( F(j\omega) \) should be larger than (3.32). Capacitor C along with transistors MC4 in Figure 3.17 introduce a zero to the transfer function of the EA, and the PM of the circuit can be easily adjusted by tuning the size (wd) of MC4 and C. All the sizing and biasing currents are shown in Table 3.2. The simulation results of the CM gain and phase of the main OTA as well as the CMFB amplifier are shown in Figure 3.19.

It is clear that the requirements of \( F(j\omega) \) and \( H(j\omega) \) for the CM stability of \( T(j\omega) \) are satisfied (see section 3.2.1) at low and high frequencies. At crossover frequency (GBW\(_{CM}\) or \( \omega_c = 30 \text{ MHz} \)), \( |G_{CM}(j\omega_c)| = -33 \text{ dB} \); thus from (3.32) the minimum required PM is around 1.3° which is much less than the achieved 50° PM for \( F(j\omega) \). Simulation results in Figure 3.20 show that reducing the PM by tuning the width of MC4 can cause zero crossing in \( H(j\omega) \) which leads to instability of \( T(j\omega) \).

The measured response of the implemented resonator is shown in Figure 3.21. It shows a quality factor of 22 with a resonance frequency at 20 MHz. The resonator consumes 660 \( \mu \text{A} \) from 1.8 V. To apply the signal to the resonator, the same OTA as in the resonator is used at the input (see Figure 3.14). Two output buffers are employed to avoid loading the resonator with measurement instruments. To examine the CM stability, a step signal with an amplitude of 300 mV was applied to the OTA’s input as a CM signal. The resonator’s response to the step
3.2. Common-mode stability of OTA-based gyrators

Figure 3.19 – Simulated CM gain and phase of the main OTA ($G_{CM}(j\omega)$) and the CMFB amplifier ($F(j\omega)$).

Figure 3.20 – Effect of tuning the width (wd) of MC4 on the CM stability.

input is shown in Figure 3.22. It is clear that the CMFB amplifier acts instantly to set the output CM voltage (settling time < 20 μs) and the resonator is completely stable.
Figure 3.21 – Measured resonator response tuned at 20 MHz; the estimated quality factor is 22.

Figure 3.22 – Measured resonator CM response to a 300 mV step signal applied as a CM signal to the resonator input.

### 3.2.5 Conclusion

In this section, the topology of the OTA-based gyrator, which is commonly used in active resonators, is briefly reviewed. It was shown that a stable OTA is not always sufficient to guarantee the CM stability of a gyrator. Indeed due to the feedback loop in the architecture of
the gyrator, more stringent requirements than just the CM stability of the OTA must be satisfied. To that effect, the mathematical models for CM analysis of a gyrator were presented and the sufficient requirements for its CM stability were analyzed. Based on these requirements, the methodology to design a CMFB amplifier for a given differential OTA employed in a resonator was presented. The methodology ensures the CM stability of the OTA as well as the resonator. The proposed methodology follows a detailed procedure that facilitates the design of a CMFB amplifier of a gyrator or a resonator. The simulation procedure to find the PM and GBW of the CMFB amplifier was also described. The methodology was employed to design and fabricate of a CMFB amplifier for a resonator. Finally, a measurement result shows the complete stability of the resonator.
Chapter 3. Wide-tuning-range continuous-time active filter

3.3 Continuous-time active filter

Integrated analog baseband filters are the indispensable building blocks in wireless receivers or transceivers. The most common application of this type of filter in wireless receivers is is for anti-aliasing, to limit a signal's bandwidth before sampling. The anti-aliasing filters have to be continuous-time filters and typically consume several milliwatts to tens of milliwatts, which is non-negligible in the total power consumption of the whole receiver or transceiver. In fact, continuous-time filters can sometimes be the only alternative to high-frequency filters, for which the clock feed-through problem in switched-capacitor filters escalates at high speeds, making them power hungry.

In a design re-use approach, a reconfigurable or tunable continuous-time low-pass filter that can satisfy the requirements of the different standards is necessary. Moreover, the coexistence of many systems (e.g., GNSS, Wi-Fi and LTE) on the same mobile equipment, which is very common nowadays, has tightened the interference rejection requirements of the receivers. This is directly reflected in the low-pass filter's requirements in terms of selectivity and linearity.

In the case of GNSS applications, the elliptic configuration for the low-pass filter is of interest because of its better selectivity and steeper roll-off transition as compared to the same order filters of the other configurations. The abrupt roll-off transition strongly mitigates out-of-band interferers while allowing sampling frequencies to be slightly above the Nyquist limit. This enables lower clock frequencies for analog-to-digital converters which means lower power consumption without suffering from aliasing noise.

Towards this end, this section presents a 4th-order Gm-C elliptic low-pass filter in CMOS technology for modern GNSS receiver IC front-ends. It employs a new Gm control circuit to tune its cut-off frequency as well as to improve the usual weak linearity of the Gm-C filters over tuning its cut-off frequency. The filter also incorporates Gm switching to achieve a wide continuous tuning range of 7.4–27.4 MHz. The large continuous tuning range can cover the bandwidth of all new GNSS signals (such as Galileo-E5) in zero-IF or low-IF receivers.

This section is organized as follows. Several filter topologies are briefly compared in section 3.3.1. A 4th-order Gm-C elliptic low-pass filter in CMOS technology for modern GNSS receiver IC front-ends is presented in section 3.3.2. The OTA design and a new Gm control circuit to improve the usual weak linearity of the Gm-C filters over tuning its cut-off frequency are presented in sections 3.3.3 and 3.3.4, respectively. A topological linearity improvement technique is described in section 3.3.5. The filter measurement results are presented in section 3.3.6. Finally, section 3.3.7 concludes this section by summarizing the key points and results.
3.3 Continuous-time active filter

3.3.1 Active filter topologies

Several topologies of integrated continuous-time filters have been developed, including the active-RC [98–101], MOSFET-C [102], active-Gm-RC [103], Gm-C [104–106], source-follower-based [107] architecture, and so on.

One popular approach for continuous-time filters is active-RC topology. Active-RC filters consist of opamps with resistors and capacitors in feedback. Because of their closed-loop nature and high loop gain of the opamp, active-RC filters show very low distortion at low frequencies, thus perform excellent linearity [108]. The same reason allows them to handle a large signal swing, resulting in a large dynamic range (DR) [109]. At higher frequencies, however, the loop gain decreases and the distortion increases. Active-RC topology uses the absolute value of resistors and capacitors; because of the low absolute accuracies of these passive components in CMOS technology, characteristic tuning for these filters is required. In fact, tuning is the main issue in these filters. Passive components cannot be tuned. Therefore, resistor or capacitor banks that lead to a discrete tuning are required for tuning the filter.

Substituting resistors with metal–oxide–semiconductor field-effect transistors (MOSFETs) in active-RC filters results in MOSFET-C filters, which solves the problem of the tuning. The ON-resistance of a MOSFET is inversely proportional to its gate voltage, allowing for tuning of the filter characteristics. However, for large signal swings, this resistance is no longer linear and introduces distortions and limits the DR of the filter. Moreover, the large value of the resistance requires a very large channel length of the MOSFET which results in limiting the performance of the filter at high frequencies. Employing opamps in filter topologies provides the highest DR of the filter for the low frequencies where the loop gain of the opamp is high. The need for an opamp bandwidth much larger than the filter cut-off frequency leads to high power consumption for high-frequency filters.

As an alternative, Gm-C filters reduce the power consumption at the cost of a lower linearity. In fact, Gm-C topology is more power efficient than active-RC and MOSFET-C topologies. Moreover, it has the great potential of working at high frequency [110], [111], since the Gm-C integrator is based on the open loop and the minimum GBW of the Gm cell is required to be not less than the filter’s cut-off frequency only. However, Gm-C filters suffer from poor linearity due to their open-loop nature. Linearity enhancement techniques [112, 113] can be applied, but higher excess noise would be produced, which implies additional power is necessary to sustain a high dynamic range. The cut-off frequency of Gm-C filters can be tuned continuously with dedicated circuitry.

Gm-C filters are capable of reasonable performance at the higher frequencies. At low frequencies, however, active-RC filters provide the highest dynamic range. The other types of filters provide a performance in between the two. Active-Gm-RC filters have a closed-loop structure that exploits the opamp frequency response in the filter transfer function. They propose an efficient trade-off between active-RC and Gm-C solutions. However, as with active-RC, they employ resistors, which results in higher in-band noise.
Another alternative is the source-follower topology. The source-follower structure uses an internal feedback loop that increases the linear range while reducing the input MOS overdrive voltage. This, as a consequence, reduces the power consumption of the filter while improving its linearity [114]. However, there is a trade-off between the accuracy of the frequency response and the linearity of the source-follower filters [115]. Capacitor banks are required for tuning the filter response which implies a discrete tuning.

For the purpose of this thesis, a Gm-C implementation has been chosen owing to the fact that it is more power efficient in contrast to active-RC filters, which is of value for battery-powered GNSS receivers. Moreover, as was mentioned above, Gm-C topology has the great potential of working at high frequencies, which facilitates the design of a wide-band filter that can accommodate all the wide-band GNSS signals. Additionally, Gm-C implementation enables the continuous tuning of the filter’s cut-off frequency over a wide range of frequencies by tuning the transconductance of the Gm cell.

### 3.3.2 A wide-tuning-range 4th-order Gm-C elliptic filter

The filter topology of Figure 3.23 is derived from the LC-ladder network which is known to be less sensitive to component mismatches compared to bi-quadratic topologies. The active representation of the LC-ladder network is achieved by substituting resistors and inductors with their active counterparts in the LC network as shown in Figure 3.23. The corresponding components’ values of the filter are available in Table 3.3.

![Figure 3.23 – A 4th-order elliptic LC-ladder low-pass filter with its active representation; Gm cells are identical and the components’ values are shown in Table 3.3.](image)

<table>
<thead>
<tr>
<th>Component</th>
<th>R</th>
<th>C1</th>
<th>C2</th>
<th>C3</th>
<th>C4</th>
<th>C5</th>
<th>L1</th>
<th>L2</th>
</tr>
</thead>
<tbody>
<tr>
<td>Value</td>
<td>4 kΩ</td>
<td>2 pF</td>
<td>800 fF</td>
<td>1.6 pF</td>
<td>2.2 pF</td>
<td>2.2 pF</td>
<td>27 μH</td>
<td>38.5 μH</td>
</tr>
</tbody>
</table>
3.3. Continuous-time active filter

The presented low-pass filter in Figure 3.23 is designed to approximate a 4\textsuperscript{th}-order elliptic transfer function. Its active implementation consists of only the capacitors and identical OTAs—also known as Gm cells. The filter is primarily designed to meet the low-pass filter requirements presented in Table 2.9. However, the design was extended to a wide-tuning-range filter that would be suitable for other systems.

Considering the filter impedance of 4 k\Ohm, the transconductance of the Gm cells should be 250 \mu S. However, this is not the only specification for the Gm cell to be designed. Apart from the transconductance and capacitance values, the Q of the active inductors also play an important role in the transfer function of the filter. Simulation results, based on the LC-ladder, show that inductors with Q \approx 20 are necessary to achieve the required selectivity (see Table 2.9) of the filter. Figure 3.24 compares the transfer function of the ideal LC-ladder 4\textsuperscript{th}-order elliptic low-pass filter with the same ladder when the inductor’s Q is 20. It shows that with an inductor Q of 20, the filter offers a cut-off frequency of 25 MHz and attenuation of 10 dB at 27 MHz.

![Figure 3.24 – Comparison between the transfer function of the ideal LC-ladder 4\textsuperscript{th}-order elliptic low-pass filter and the same ladder when the inductor’s Q is 20.](image)

3.3.3 OTA design

The Gm cell (OTA) is the main building block of the presented elliptic filter in Figure 3.23. Looking at the topology of the filter in Figure 3.23, it can be seen that the filter requires 11 identical OTAs. However, the outputs of each two pairs of OTAs are tied to each other. Therefore, by employing dual-input OTAs, the Gm-C implementation of the filter can be simplified as in Figure 3.25.

![Figure 3.25](image)

However, the filter illustrated in Figure 3.25 is equivalent to employing 12 OTAs in the filter. The two input pairs of the first OTA in Figure 3.25 can be tied together, which results in a higher filter gain, or one of the inputs can be kept unconnected, which results in the same
filter gain as the filter employing 11 OTAs in Figure 3.23. In any case, this choice does not affect the elliptic transfer function of the filter.

To design an OTA for the proposed filter, the methodology presented in section 3.1 can be used to achieve the required Q for the active inductors. The folded cascode was chosen as the core structure of the OTA. The advantage of the OTA’s folded cascode architecture for high-Q inductors and the CM stability of a gyrator are explained in section 3.1 and section 3.2, respectively. Moreover, the folded cascode topology allows for more than one input for the OTA, which is crucial for the required dual-input OTA.

Figure 3.26 shows the schematic of the OTA. It is composed of dual input stages, an output stage and a CMFB amplifier. The use of a dual-input OTA allows for the reuse of some parts of the circuit: the output stage, bias circuit and CMFB amplifier for another OTA. It helps to reduce the overall power consumption of the OTAs and thus of the filter. To achieve a high gain in the OTA, two cascade transistors are employed in the output stage of the OTA. Moreover, to avoid the problems that the internal pole of the OTA can cause on the Q of the filter over its tuning, transistors M8 and M9 have been designed with a short length to reduce their parasitic capacitance. The methodology presented in section 3.1 has been employed in the design of the OTA.

Table 3.4 – Geometry and operating point of the output stage’s transistors of the OTA in Figure 3.26.

<table>
<thead>
<tr>
<th>Device</th>
<th>M6a,b</th>
<th>M7a,b</th>
<th>M8a,b</th>
<th>M9a,b</th>
<th>MC1</th>
<th>MC2a,b,c</th>
<th>MC3a,b</th>
<th>MC4a,b</th>
</tr>
</thead>
<tbody>
<tr>
<td>W/L μm</td>
<td>8/1</td>
<td>4/0.5</td>
<td>20/0.25</td>
<td>14.4/0.3</td>
<td>20/2</td>
<td>10/1</td>
<td>20/8</td>
<td>3/10</td>
</tr>
<tr>
<td>I_{ds} μA</td>
<td>115</td>
<td>115</td>
<td>115</td>
<td>115</td>
<td>16.86</td>
<td>4.21</td>
<td>8.43</td>
<td>4.18</td>
</tr>
</tbody>
</table>

The geometry and operating point of the output stage’s transistors of the OTA in Figure 3.26 are presented in Table 3.4. The bias current of the output stage (115 μA) is constant over tuning of the OTA’s transconductance and is determined by the load driving requirement for the
3.3. Continuous-time active filter

The methodology and considerations presented in section 3.2 have been taken into account for the design of the CMFB amplifier. The schematic of the CMFB amplifier is presented in Figure 3.27, which sets the output CM voltage to 900 mV (half of the VDD) and ensures the CM stability of the filter.

3.3.4 Tuning filter's cut-off frequency

Generally, tuning of the Gm-C filters can be done by switching the capacitors or tuning the transconductance ($g_m$) of the Gm cells. Besides a discrete control, capacitor switching also suffers from the limitation that the minimum capacitance has to satisfy the noise requirements ($\propto 1/C$) at the highest tuning frequency. As a result, the maximum required capacitance for the minimum cut-off frequency may be too large. In addition, it requires switches in series with the capacitors or even sometimes floating switches, which may introduce huge parasitic effects. In contrast, in Gm tuning—tuning the transconductance of the Gm cell—a constant value of capacitance is used which leads to an optimal balance of noise, chip area, and frequency response accuracy. However, tuning the Gm cell outside its intrinsic range degrades linearity as well as accuracy of the filter responses. Indeed, on the one hand, pushing the bias of the Gm cell to a low current level not only reduces $g_m$ but also lowers the second
pole of the Gm cell and reduces its linearity. On the other hand, over a certain level of current, Gm shows a kind of saturation. The intrinsic range lies in between these two cases. Hence, to further extend the tuning range of the filter, Gm switching can be employed. This can be implemented by connecting in parallel small OTAs and switching on or off only their biasing so that no switches’ parasitic capacitance is added in the signal path.

The proposed filter-tuning scheme exploits the two aforementioned methods of tuning to implement fine and coarse tuning. The fine tuning is achieved by controlling the transconductance of the Gm cell, and results in a continuous tuning of the filter’s cut-off frequency. The coarse tuning is achieved by Gm switching and results in extending the tuning range.

### 3.3.4.1 Fine tuning

The input stage of the OTA with the proposed $g_m$ control circuit is shown in Figure 3.28. The transconductance ($g_m$) of the OTA is set by the transconductance of the input differential pair (M3). The biasing of M3 consists of a fixed part provided by M1 and M4 and a variable part that is implemented by changing the bias current in M2 and M5. The latter are biased by means of two current mirrors (Mc2 and Mc4) to make sure that the current in the tail and load change together in respect to $I_{tune}$. The perfect agreement between the bias current of M2 ($I_{M2}$) and the bias current of M5a,b ($I_{M5} = I_{M5a} + I_{M5b}$) is shown in Figure 3.29. The figure also indicates the range that is used for tuning the $g_m$. The transistor Mc3 is used to render the control circuit as a scaled branch of the input differential pair. The geometry of the transistors

Figure 3.27 – Schematic of the CMFB amplifier for the OTA in Figure 3.26; the geometry of transistors and bias current are presented in Table 3.4.
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in the unit cell and the \( g_m \) control are shown in Table 3.5.

![Diagram of the unit cell and \( g_m \) control circuit](image)

Figure 3.28 – Fine tuning scheme of the transconductance; the \( g_m \) control circuit is shown in blue.

<table>
<thead>
<tr>
<th>Device</th>
<th>M1</th>
<th>M2</th>
<th>M3a,b</th>
<th>M4a,b</th>
<th>M5a,b</th>
<th>Mc1</th>
<th>Mc2</th>
<th>Mc3</th>
<th>Mc4</th>
</tr>
</thead>
<tbody>
<tr>
<td>( W/L \ \mu \text{m} )</td>
<td>2/3</td>
<td>22.4/3</td>
<td>3/1</td>
<td>1.5/0.3</td>
<td>15/0.5</td>
<td>4/3</td>
<td>4/3</td>
<td>6/0.5</td>
<td>12/1</td>
</tr>
</tbody>
</table>

The simulated minimum \( (g_{m,\text{min}}) \) and maximum transconductance \( (g_{m,\text{max}}) \) of the OTA are 75 \( \mu \text{S} \) and 169 \( \mu \text{S} \), respectively. This means that the continuous \( g_m \) tuning ratio \( (g_{m,\text{max}}/g_{m,\text{min}}) \) is 2.25 which leads to the same tuning ratio as the filter's cut-off frequency based only on the fine-tuning scheme.

3.3.4.2 Coarse tuning

Tuning the Gm cell beyond its intrinsic transconductance by regulating its bias current degrades the linearity as well as accuracy of the filter responses. Therefore, to further extend the tuning range, other means of tuning are required. Considering the differential pair in Figure 3.28 as a unit cell of the input stage, to extend the tuning range of the OTA, thanks to its folded cascode topology, more than one unit cell can be used in parallel of each other. However, increasing the number of parallel unit cells increases the parasitic capacitance at
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Figure 3.29 – Simulation shows perfect matching between $I_{M2}$ and $I_{M5} = I_{M5a} + I_{M5b}$ (see Figure 3.28) for the $g_m$ tuning range.

the node of M8 and M9 (see Figure 3.26) and reduces the internal pole of the Gm cell which in turn degrades the filter’s Q over its tuning. This is why, in our implementation, only two unit cells are employed at each input of the OTA, as shown in Figure 3.30 where one unit cell is drawn in a sheet and the parallel one is represented with an overlapping sheet. Both unit cells are always connected but the second one will be biased to duplicate the overall $g_m$ of the OTA when necessary. Since the $g_{m,\text{max}}/g_{m,\text{min}}$ ratio of the fine-tuning scheme is higher than 2, the coarse-tuning scheme does not cause any discontinuity in the overall tuning range of the transconductance.

To summarize, tuning the $g_m$ continuously tunes the cut-off frequency of the filter. The coarse tuning divides the tuning range of the filter’s cut-off frequency to a lower band (LB) and a higher band (HB) of frequencies; when only one unit cell is biased in each input stage of the Gm cell, the fine-tuning scheme can tune continuously the cut-off frequency in LB, and when the second unit cell is also biased the fine-tuning scheme tunes the cut-off frequency in HB.

The filter bias circuit and its corresponding transistor’s geometry and bias are shown in Figure 3.31 and Table 3.6, respectively. Note that the bias currents in the table are indicated for the filter’s highest cut-off frequency.

3.3.5 Linearity improvement

Generally, Gm-C filters suffer from weak linearity performance due to their open-loop nature. Therefore, two linearity improvement methods are adopted in this design. The first method is the topological linearity improvement proposed in [116]. The use of this linearity improvement method is possible thanks to the symmetrical structure of the filter in Figure 3.25. In fact, in this method, the linearity improvement is achieved at the structural level.
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Assuming a dual-input transconductor is driven by two differential signals $V_1$ and $V_2$ where

$$V_1 = V_{1+} - V_{1-},$$  \hspace{1cm} (3.33)
$$V_2 = V_{2+} - V_{2-}.\hspace{1cm} (3.34)$$

A conventional integrator of the filter in Figure 3.25 is shown in Figure 3.32(a). Its integrating current assuming it has $g_m$ transconductance is

$$I_C = g_m (V_{1+} - V_{1-}) + g_m (V_{2+} - V_{2-}).\hspace{1cm} (3.35)$$

The linearity improvement can be achieved simply by exchanging the two negative inputs as shown in Figure 3.32(b). In this case, the integrator current is

$$I_C = g_m (V_{1+} - V_{2+}) + g_m (V_{2-} - V_{1-}).\hspace{1cm} (3.36)$$

The $I_C$ of (3.36) is equivalent to that of (3.35). However, by this method, each unit cell is driven with two in-phase signals rather than a differential signal; therefore, the differential signal swing is significantly reduced. This does not alter the overall filter response, due to the symmetry of the Gm cell as well as the filter’s topology. The reduced differential swing at the input of the Gm cell results in the better linearity performance of the filter without increasing.
the power consumption.

The other method, which is original to the best of our knowledge, is the fine-tuning scheme with the proposed $g_m$ control circuit in section 3.3.4.1. The linearity depends on the overdrive voltage of the OTA's differential input (M3) (see Figure 3.28). The M3's minimum overdrive happens at the $g_{m,min}$, which should satisfy the linearity requirements of the filter. Increasing the cut-off frequency increases the M3's bias current which in turn increases the overdrive of the M3 and therefore improves the linearity performance of the filter. In fact, the linearity slightly improves by increasing the cut-off frequency of the filter as far as the tuning stays within the OTA's intrinsic transconductance range. Since both the current tail and the load are tuned together, the output stage of the OTA remains independent from the tuning scheme.

### 3.3.6 Measurement results

The 4th-order elliptic low-pass filter was fabricated using UMC 0.18 μm CMOS technology. Figure 3.33 shows a micro photograph of the filter with an active area of 0.23 mm². Two
3.3. Continuous-time active filter

Figure 3.32 – Conventional (a) and linearity improved (b) Gm-C integrators.

Linear low-noise off-chip buffers (AD8351) [79] were used to make single-ended to differential conversion and vice versa to facilitate the measurement process, and their effects were deembedded from the measurement results. Moreover, to isolate the filter from the parasitic capacitance of the off-chip output buffer, two on-chip buffers which have a negligible effect on the filter response were also used.

Figure 3.33 – Micro photograph of the chip.

Figure 3.34 shows the frequency response of the filter. As seen in the figure, the cut-off frequency tuning range from 7.4 to 16.8 MHz (LB) is obtained only by fine tuning when the Gm cell has one unit cell biased in its input stage, whereas the tuning range from 13.2 to 27.4 MHz (HB) is achieved when the second unit cell of the Gm input stage is also biased. The overlap between LB and HB yields a continuous tuning range of the filter’s cut-off frequency from 7.4 to 27.4 MHz.
Figure 3.34 – Measured frequency response of the 4th-order elliptic low-pass filter with tunable cut-off frequency of 7.4–27.4 MHz; LB tuning range (red) is 7.4–16.8 MHz and HB tuning range (blue) is 13.2–27.4 MHz.

The measured in-band ripple of the filter’s responses is less than 2 dB and stop-band attenuation is more than 33 dB over the entire tuning range, while the notch attenuation in the transition band is higher than 45 dB at 1.45 of the cut-off frequency. This very steep roll-off response of the filter allows sampling a signal with a sampling frequency slightly above the cut-off frequency of the filter.

The phase and the group delay of the filter are also measured. The measures embed the contribution of the on-chip op-amps and the on-board buffers, but thanks to their wideband response, the error introduced by them is negligible. The group delay of the filter when its bandwidth is set to 25 MHz is shown in Figure 3.35. It is flat around 30 ns from 1 to 17 MHz and then increases as the frequency approaches the cut-off frequency.

Nevertheless, the average phase linearity is shown in Figure 3.36. For the frequency band from 300 KHz to the filter’s cut-off frequency of 25 MHz, the average phase linearity is 6.2° well below the maximum error defined in Table 2.9 (i.e. 8.6°).

The in-band linearity performance of the filter is characterized by measuring the IP1dB and IIP3 of the filter for the two frequency tones at 5 and 6 MHz. Figure 3.37 and Figure 3.38 show the measured P1dB and IIP3 of the filter over tuning its cut-off frequency, respectively. They show that a P1dB over $-17 \text{ dBVRMS}$ (0.4 $V_{p-p}$) as well as a high value IIP3 over $-8 \text{ dBVRMS}$ (1.13 $V_{p-p}$) are achievable for cut-off frequencies between 11–27.4 MHz. The maximum measured IIP3 is $-1.3 \text{ dBVRMS}$ (2.44 $V_{p-p}$) for a cut-off frequency near 27 MHz. The linearity degrades slightly in exchange of the tunability of the cut-off frequency, especially for lower cut-off frequencies where the differential input’s overdrive is around 300 mV, but still above the required value. Moreover, the filter’s out-of-band IIP3 is examined for cut-off frequency at
3.3. Continuous-time active filter

Figure 3.35 – Measured filter’s group delay when it is set to 25 MHz of bandwidth.

Figure 3.36 – Measured phase of the filter when it is set to 25 MHz of bandwidth; the average non-linear phase error is 6.2°.

26 MHz with two tones at 30 and 35 MHz in Figure 3.39. In this case the out-of-band IIP3 is measured as $-15.8$ dBVRMS (0.46 Vp-p).

The filter’s current consumption and its dependency on the filter’s cut-off frequency in both LB and HB frequency bands are shown in Figure 3.40. The current consumption at the high end of the HB frequency band (27.4 MHz) is 7.58 mA from a 1.8 V supply and it scales down logarithmically by reducing the bandwidth of the filter to 2.4 mA at the low end (13.16 MHz) of the HB frequency band. In the LB frequency band (7.4–16.8 MHz), the filter shows the same logarithmic trend of reduction of power consumption by reducing its bandwidth and consumes between 2.12 and 5.3 mA. The reduction of the filter’s power consumption with
respect to its bandwidth makes the filter very power efficient with an average normalized power consumption of 105 pW/pole/Hz over its whole tuning range.

Furthermore, the filter’s noise is characterized. However, its noise characterization is not an easy task, since two external buffers (AD8351) are employed prior and ahead of the filter (as for single-ended to differential conversion and vice versa) with their resistive matching networks. In fact, the filter noise contribution is masked by the higher noise level of the amplification
3.3. Continuous-time active filter

Figure 3.39 – Measured out-of-band IIP3 for two tones at 30 and 35 MHz for a filter cut-off frequency set to 26 MHz; the IM3 is measured at 25 MHz.

Figure 3.40 – Measured dependence of the current consumption on the cut-off frequency of the filter for both LB and HB bands of tuning.

chain. For low gain and high noise figure the best method for noise measurements is the signal generator twice-power method. First, the output power is measured with the device input terminated with a load at a temperature of approximately 290°C. Then a signal generator is connected, providing a signal within the measurement bandwidth. The generator’s output power is adjusted to produce a 3 dB increase in the output power. If the generator’s power level and measurement bandwidth (equivalent noise bandwidth) are known, the noise factor
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can be obtained by [117]:

$$F_{sys} = \frac{P_{gen}}{kT_0B},$$  \hspace{1cm} (3.37)

where $P_{gen}$ is the generator power, $k$ is the Boltzmann constant, $T_0$ is 290°K and $B$ is the measurement bandwidth. By using (3.37) and the spectrum analyser's noise marker, the noise power is measured with high accuracy. The measured NF is reported in Table 3.7 for different frequencies. In order to de-embed the buffers' noise contribution from the overall NF. The

<table>
<thead>
<tr>
<th>IF (MHz)</th>
<th>NF (dB)</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>47.9</td>
</tr>
<tr>
<td>5</td>
<td>47.9</td>
</tr>
<tr>
<td>10</td>
<td>47.9</td>
</tr>
<tr>
<td>15</td>
<td>48</td>
</tr>
<tr>
<td>20</td>
<td>47.6</td>
</tr>
</tbody>
</table>

Table 3.7 – Measured noise figure of the filter and the input-output buffers; at filter's cut-off frequency of 25 MHz.

The noise figure of the whole system was simulated considering gain and noise of all buffers and matching networks. The simulated noise figure of the system is shown in Figure 3.41.

![Figure 3.41 – Simulated noise figure of the system; including the filter, input and output buffers and their matching networks.](image)

The simulated NF of the system is perfectly matched with the measured noise figures in Table 3.7. Accordingly, we can assume that the noise simulation results of the standalone filter should be fairly close to the measurements. The simulated noise figure, input and output noise spectral densities of the standalone filter are shown in Figure 3.42. From this figure, the
input and output noise voltage densities are $13.5 \text{nV/Hz}$ and $20 \text{nV/Hz}$, respectively, at 10 MHz. Moreover, the integrated input-referred noise is $120 \mu\text{V}$ for the frequency band between 2–30 MHz. The minimum noise figure occurs within the filter’s bandwidth from 1-10 MHz and it is about 13.3 dB.

![Figure 3.42 – Simulated noise figure, input and output noise spectral noise voltages of the standalone filter.](image)

In order to compare different continuous-time low-pass filters, a FOM introduced in [104] is used, which accounts for the linearity as well as the available tuning range of the filter. The FOM is defined as:

$$
\text{FOM} = 10\log_{10} \left( \frac{\text{IMFDR}_{\text{lin.-} f_0, \text{tuning}}}{\text{ppp}} \right),
$$

(3.38)

where $f_0$ is the cut-off frequency geometrical mean in Hz, tuning is the tuning ratio of the filter ($f_{\text{max}}/f_{\text{min}}$), and $\text{ppp}$ is the power per pole quantity in watts. The IMFDR is calculated as:

$$
\text{IMFDR} = (2/3)(\text{OIP3} - \text{N}),
$$

(3.39)

where OIP3 and $N$ are the output-referred IP3 and the noise voltage power spectral density, respectively; both are expressed in $\text{dBV}_{\text{RMS}}$ in (3.39). However, (3.38) requires a linear representation of (3.39). Accordingly, the proposed filter achieved a FOM of 151.7.

Finally, the measured filter’s performances are summarized in Table 3.8 and compared to the performances of recently published CMOS filters [106, 116, 118, 119]. The values in Table 3.8 are reported for the highest cut-off frequency of their respective filters. The proposed filter achieved a high range of tuning as well as satisfactory results regarding noise and power consumption.
Chapter 3. Wide-tuning-range continuous-time active filter

Table 3.8 – Performance comparison with state-of-the-art CMOS filters.

<table>
<thead>
<tr>
<th></th>
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<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
</tr>
</thead>
<tbody>
<tr>
<td>This Work</td>
<td>180</td>
<td>0.23</td>
<td>4</td>
<td>1.8</td>
<td>3.8 - 13.6</td>
<td>7.4 - 27.4</td>
<td>-1.27</td>
<td>-2.5</td>
<td>49</td>
<td>-78.4</td>
<td>151.7</td>
</tr>
<tr>
<td>[106]</td>
<td>180</td>
<td>0.125</td>
<td>4</td>
<td>1.8</td>
<td>4.68</td>
<td>0.3 - 12</td>
<td>-4.3</td>
<td>0</td>
<td>42.63</td>
<td>-68.2</td>
<td>150.8</td>
</tr>
<tr>
<td>TCAS’14</td>
<td>180</td>
<td>0.25</td>
<td>3</td>
<td>1.8</td>
<td>2.3</td>
<td>17</td>
<td>15.2</td>
<td>0</td>
<td>51.5</td>
<td>-62</td>
<td>155</td>
</tr>
<tr>
<td>[118]</td>
<td>130</td>
<td>0.12</td>
<td>5</td>
<td>1.5</td>
<td>21</td>
<td>70 - 280</td>
<td>7</td>
<td>0</td>
<td>53.08</td>
<td>-72.6</td>
<td>164.3</td>
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<td>E-Lett.’11</td>
<td>180</td>
<td>1.5</td>
<td>3</td>
<td>5</td>
<td>180</td>
<td>6 - 12</td>
<td>20</td>
<td>0</td>
<td>62.07</td>
<td>-73.1</td>
<td>146.6</td>
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<tr>
<td>[116]</td>
<td>500</td>
<td>1.4</td>
<td>5</td>
<td>5</td>
<td>85</td>
<td>30</td>
<td>10.5</td>
<td>0</td>
<td>59.52</td>
<td>-78.8</td>
<td>152</td>
</tr>
<tr>
<td>TCAS’10</td>
<td>350</td>
<td>1.8</td>
<td>5</td>
<td>3.3</td>
<td>3</td>
<td>19.7</td>
<td>5.3</td>
<td>2</td>
<td>56.55</td>
<td>-77.5</td>
<td>156</td>
</tr>
<tr>
<td>JCSS-I’07</td>
<td>130</td>
<td>0.2</td>
<td>3</td>
<td>1.5</td>
<td>1.8</td>
<td>10</td>
<td>7</td>
<td>2</td>
<td>52.31</td>
<td>-71.5</td>
<td>149.2</td>
</tr>
<tr>
<td>JCSS’07</td>
<td>120</td>
<td>0.25</td>
<td>3</td>
<td>1</td>
<td>3</td>
<td>6.1</td>
<td>7</td>
<td>0</td>
<td>11.2</td>
<td>10</td>
<td></td>
</tr>
<tr>
<td>JCSS’06</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

1 Elliptic, 2 Butterworth, 3 Chebyshev, 4 Simulation.

3.3.7 Conclusion

A 4th-order Gm-C elliptic low-pass filter with a continuous cut-off frequency tuning range of two octaves has been presented. The wide continuous tuning has been achieved by combining a new Gm tuning circuit with the Gm switching techniques to cover all the new wideband modernized GNSS signals. The filter uses constant capacitors, leading to an optimal balance of noise, chip area and frequency response accuracy. The measured filter’s responses show a very steep roll-off, which allows the signal to be sampled slightly above the cut-off frequency of the filter. Measurements show that IIP3 remains near constant over a wide tuning range thanks to the new $g_m$ control circuit. The new tuning circuit scales down the current consumption with respect to the bandwidth of the filter, which makes the filter very power efficient.

The filter was implemented using 0.18 μm CMOS technology. Its cut-off frequency is tunable from 7.4 to 27.4 MHz with less than 2 dB ripple and more than 31 dB attenuation in its pass-band and stop-band, respectively. The filter consumes 7.58 mA at its highest cut-off frequency and its consumption scales down to 2.12 mA at the cut-off frequency of 7.4 MHz. Therefore, its power consumption depends on its bandwidth which makes the filter very power efficient with average normalized power consumption of 105 pW/pole/Hz. It achieves IIP3 up to $-1.3$ dBVRMS for the cut-off frequency near 27 MHz.
3.4 Effect of Q enhancement on the selectivity of the filter

In the active filter design, the selectivity of the filter, i.e., the sharpness of the filter’s amplitude response in its transition band, depends on the type and order of the filter. However, in practice, due to the limited inductor’s Q, the selectivity degrades from its ideal value. In fact, the filter entails a minimum Q for its active inductors to achieve the required selectivity. On the other hand, the method proposed in section 3.1 offers the possibility of improving the Q to a desirable value without any extra power consumption. However, as shown in Figure 3.2, the Q changes by tuning the resonance frequency, which should be taken into account during the design of a tunable filter to ensure the minimum required Q over the tuning.

This section presents the measures to employ the method proposed in section 3.1 in the design of a tunable continuous-time active low-pass filter. Moreover, the filter proposed in section 3.3 is adopted to demonstrate the effects of the Q-enhancement method on the selectivity of the filter.

3.4.1 Tuning considerations for Gm-C filters

Tunable Gm-C filters employ tunable resonators and inductors. In fact, tuning the resonator’s resonance frequency or active inductor’s value tunes the cut-off frequency of the filter. On the other hand, as Figure 3.2 shows, for $\beta > 2$ the resonator’s Q increases by increasing its resonance frequency. In other words, the minimum resonator’s Q occurs at the minimum filter’s cut-off frequency. Therefore, for a tunable filter, resonators (or more precisely, the OTA of the resonator) should be designed at the very low end of the filter’s cut-off frequency tuning range to yield a minimum Q that satisfies the required selectivity for the filter. Designing the OTA (Gm cell) in this way ensures that the selectivity of the filter does not degrade by tuning the filter’s cut-off frequency to a higher value. Nevertheless, the maximum cut-off frequency of the filter restricts how far the second pole of the OTA should be placed to ensure that $\beta$ does not reach a value close to 2 in Figure 3.2.

3.4.2 Filter selectivity

To show the effect of enhancing the Q of the resonator on the selectivity of the filter, a highly selective 4th-order elliptic low-pass filter presented in section 3.3 is adopted. The same design procedure that was used for resonator design in section 3.1 was employed to design the filter’s OTA. The filter’s architecture and its micro photograph are shown in Figure 3.25 and Figure 3.33, respectively. Its cut-off frequency is tunable from 7.4 to 27.4 MHz. The tunable cut-off frequency is achieved by employing a control circuit that adjusts the overdrive voltage of M2 and M3 (see Figure 3.28) to tune the $g_{m,M3}$ from 75 to 169 $\mu$S as well as Gm switching which has been explained in section 3.3.4.2. Thanks to the folded cascode architecture of the OTAs and the tuning scheme of the filter, the filter’s cut-off frequency can be tuned without affecting the OTA’s second pole. This lowers the $\beta$ and enhances the Q of the inductors and
Figure 3.43 – Measured frequency response of the 4th-order elliptic low-pass filter with a tunable cut-off frequency from 7.4 to 27.4 MHz along with the simulated results when the OTA is modeled with ideal transconductance and one internal pole at 880 MHz.

The experimental results are in good agreement with the expected ones: Pass-band ripple (expected < 1.5 dB, measured < 2 dB), stop-band attenuation (simulated 30 dB, measured > 31 dB). This indicates that the OTA’s internal poles except its second pole have a minor effect on the filter’s amplitude response.

To see the effect of the Q enhancement on the selectivity of the filter, the roll-off of the pass-band to stop-band of the filter ($\alpha$) versus its cut-off frequency is shown in Figure 3.44. Indeed, $\alpha$ is the sharpness of the filter’s amplitude response from its pass-band to stop-band which represents the selectivity of the filter and is defined as:

$$\alpha = \frac{T(f_{30 \, dB}) - T(f_{3 \, dB})}{\log_2 \left( \frac{f_{30 \, dB}}{f_{3 \, dB}} \right)} \quad [\text{dB/Octave}],$$

(3.40)

where $T(f)$ is the transfer function of the filter and $f_{30 \, dB}$ and $f_{3 \, dB}$ are the first frequencies in which the filter transfer function experiences the attenuation of 30 and 3 dB, respectively.

Figure 3.44 compares the sharpness of the filter’s measured amplitude response (trace I) with the simulated response where the filter uses the model of the OTA (trace II). Moreover, to see the effect of OTA’s second pole on the filter’s selectivity, the filter’s response was simulated with the same model of the OTA except in this case the OTA’s second pole was omitted ($\omega_2 \rightarrow \infty$). Its $\alpha$ (trace III) is also compared with the two previous cases in Figure 3.44.

Based on (3.4), the resonator’s Q is proportionally related to the $g_m$ of its OTA. On the other
3.4. Effect of Q enhancement on the selectivity of the filter

Figure 3.44 – The roll-off of the pass-band to stop-band of the filter (α) versus its 3-dB cut-off frequency for three different cases: (I) Measured roll-off of the filter, (II) Simulated roll-off of the filter when its OTA is modeled by a transconductance and its second pole, and (III) Simulated roll-off of the filter when its OTA is modeled by a transconductance with no internal pole (ω₂ → ∞).

On the other hand, tuning the $g_m$ of the OTA to a higher value increases the cut-off frequency of the filter. Even by considering the internal poles of the OTA, the relation between Q and $g_m$ still exists in some degree although it is no longer proportional. Therefore, it is expected that the selectivity of the filter improves by tuning its cut-off frequency to a higher value. Indeed, Figure 3.44 shows this for all three traces as the cut-off frequency increases. However, in Figure 3.44, when the OTA model includes the second pole (trace II), the selectivity of the filter is at least 3 dB/Octave better than that of the model without the second pole (trace III). This is achieved due to the Q enhancement method. The selectivity improvement is even better at the higher filter’s cut-off frequencies when the Q is more magnified due to the OTA’s second pole.

The measured filter’s roll-off (trace I) in Figure 3.44 also follows the same trend. Increasing the cut-off frequency of the filter decreases the $\beta$ and thereby magnifies the Q of the active inductors and resonator in the filter. The larger Q results in a better selectivity. The measured $\alpha$ at the filter’s lowest cut-off frequency is more than 59 dB/Octave which makes the filter equivalent to a 10th-order Butterworth filter. It reaches almost up to 66 dB/Octave at 27 MHz cut-off frequency. The small mismatch in Figure 3.44 between the measurement (trace I) and the model (trace II) is attributed to the other internal poles and zeros of the OTA which are not considered in the model.

In fact, as the cut-off frequency increases -$g_m$ increases- which corresponds to a more dominant second pole in the OTA (since the OTA’s second pole is not affected by $g_m$), the other internal poles of the OTA become more submissive. Therefore, trace (I) approaches trace (II) which is the result of modeling only the second pole of the OTA. However, approaching
the limit of the OTA’s intrinsic range (see section 3.3.4) deteriorates the accuracy of the filter response and thus degrades its selectivity as can be seen for trace (I) of Figure 3.44 for the cut-off frequencies above 25 MHz.

3.4.3 Conclusion

This section described how to employ the Q-enhancement methodology presented in section 3.1 in the design of a wide-tuning-range filter. Moreover, the effects of Q-enhancement on the selectivity of the filter were described and the considerations for the OTA design based on the tuning range of the filter were presented.

It has been shown that, in a proper design, the OTA’s internal poles except its second pole have a minor effect on the filter’s amplitude response. To that end, the highly-selective 4\textsuperscript{th}-order elliptic low-pass filter of section 3.3 was adopted and modeled by OTAs with only one internal pole which corresponds to the second pole of the filter’s OTA. The simulation responses of the model and measured responses of the filter were in good agreement with one another. Both filter’s cut-off frequencies are tunable from 7.4 to 27.4 MHz with less than 2 dB ripple and more than 31 dB attenuation in their pass-band and stop-band, respectively. Moreover, the measured pass-band to stop-band’s roll-off of the filter at its lowest cut-off frequency is more than 59 dB/Octave which is the same as the ideal selectivity of a 10\textsuperscript{th}-order Butterworth filter. The selectivity increases nearly to 66 dB/Octave at 25 MHz cut-off frequency as was expected from the model.
Although the GPS was devised and developed primarily for military purposes, its civil use has increased considerably since the end of the Cold War. Recently, the demand for a higher position accuracy and availability has increased, which GPS-L1 C/A only receivers cannot fully satisfy. Indeed, the current GPS-L1 C/A open signal has poor sensitivity performance in a multipath environment [15]. Fortunately, multi-band GPS receivers can provide better accuracy [45]. However, since the GPS bands are located far away from each other in the frequency domain, multi-band GPS receivers require front-ends that consume more power and are therefore not the best choice for mass-market applications requiring ultra-low power consumption.

Currently, as stated in section 1.3, besides GPS, the Russian GLONASS is also fully operational, and two more systems, the Chinese Beidou and the EU Galileo, will become operational in the near future. These additional GNSSs can be used to improve the performance of GPS receivers. Indeed, a much improved availability can be achieved by employing different constellations, which increases the number of visible satellites for the receiver. Inter-operation among the GNSS systems can improve signal reliability in hostile environments and system reliability in case of malfunctioning of one of the constellations [15, 16].

To that end, the purpose of this research was to design a hybrid GPS/Galileo/Beidou front-end (FE) for mass-market civil applications. As mass-market applications demand compact, low-power and low-cost solutions, the front-end has been integrated on a cost-effective 0.18 μm CMOS process. Moreover, the front-end is intended to be capable of receiving Beidou B1-I, GPS L1C, and Galileo E1 B/C simultaneously.

The FE’s architecture selection and frequency plan are laid out in section 4.1. By having in mind that the FE is targeting the mass market applications, system specifications were derived for all the sub-systems in section 4.2. The design of each sub-system is presented in section 4.3. Finally, this chapter is concluded by presenting the measured characterizations of the FE in section 4.4.
4.1 Beidou RF front-end architecture

4.1.1 Band selection

The main GNSS signals have been reviewed in section 1.3. Since the focus of this chapter is on open service signals, the detailed specifications of those signals of GPS, Galileo and Beidou are shown in Table 4.1.

Table 4.1 – Specifications of GPS L1, Galileo E1 and Beidou B1 open service signals.

<table>
<thead>
<tr>
<th>GNSS System</th>
<th>GPS</th>
<th>GPS</th>
<th>Galileo</th>
<th>Beidou</th>
<th>Beidou</th>
</tr>
</thead>
<tbody>
<tr>
<td>Service name</td>
<td>C/A</td>
<td>L1C</td>
<td>E1 OS</td>
<td>B1 GSO</td>
<td>B1 N-GSO</td>
</tr>
<tr>
<td>Frequency band</td>
<td>L1</td>
<td>L1</td>
<td>E1</td>
<td>B1</td>
<td>B1</td>
</tr>
<tr>
<td>Center frequency [MHz]</td>
<td>1575.42</td>
<td>1575.42</td>
<td>1575.42</td>
<td>1561.098</td>
<td>1561.098</td>
</tr>
<tr>
<td>Access technique</td>
<td>CDMA</td>
<td>CDMA</td>
<td>CDMA</td>
<td>CDMA</td>
<td>CDMA</td>
</tr>
<tr>
<td>Spreading modulation</td>
<td>BPSK(1)</td>
<td>TMBOC(6,1,1/11)</td>
<td>CBOC(6,1,1/11)</td>
<td>QPSK(2)</td>
<td>QPSK(2)</td>
</tr>
<tr>
<td>Phase</td>
<td>Q</td>
<td>I</td>
<td>Q</td>
<td>I</td>
<td>Q</td>
</tr>
<tr>
<td>Signal component</td>
<td>Data</td>
<td>Data</td>
<td>Pilot</td>
<td>Data</td>
<td>Pilot</td>
</tr>
<tr>
<td>Sub-carrier frequency [MHz]</td>
<td>-</td>
<td>1.023</td>
<td>6.0138</td>
<td>6.0138</td>
<td>6.0138</td>
</tr>
<tr>
<td>Chip rate ($R_c$) [Mcps]</td>
<td>1.023</td>
<td>1.023</td>
<td>1.023</td>
<td>1.023 &amp;</td>
<td>2.046</td>
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<tr>
<td>Primary PRN code length</td>
<td>1023</td>
<td>10230</td>
<td>10230</td>
<td>4092</td>
<td>4092</td>
</tr>
<tr>
<td>Secondary PRN code length</td>
<td>-</td>
<td>1800</td>
<td>-</td>
<td>25</td>
<td>-</td>
</tr>
<tr>
<td>Data rate ($R_b$)</td>
<td>50 bps</td>
<td>50 bps</td>
<td>-</td>
<td>250 bps</td>
<td>50 bps</td>
</tr>
<tr>
<td>Maximum received power [dBW]</td>
<td>-158.5</td>
<td>-157</td>
<td>-157</td>
<td>-157</td>
<td>-163</td>
</tr>
</tbody>
</table>

As can be seen in Table 4.1, the Galileo E1 shares its carrier frequency with GPS L1 at 1575.42 MHz. Therefore, receiving the L1 band offers the opportunity to receive also E1 OS. As for Beidou signals, B1-I provide the open service signal only 14.322 MHz from L1, which makes it a very good candidate in the band selection of a low-cost mass-market FE. In fact, the L1 and B1 bands enable a low-cost single-channel FE to downconvert all three bands and takes advantage of the three constellations that are of interest for low-cost receivers in consumer applications.

4.1.2 Architecture selection

GNSS FE s and topologies are reviewed in the state-of-the-art review in section 1.5.1 and section 1.5.2. For the purpose of this FE, since the two desired signal bands are fairly close to one another, in order to have a compact receiver, it is possible to receive both bands with a single-channel FE employing a fixed local oscillator.

Table 2.3 compares the different multi-frequency front-end (MFFE) architectures. For consumer applications, compact, low-power and cheap devices are required. Moreover, these applications do not require as high jamming immunity as the PRS application, therefore it is possible to alleviate the FE specifications in terms of noise and interference performance to achieve a lower power receiver. Given these considerations, the broadband architecture
was chosen to downconvert both the L1 and B1 bands. Nevertheless, since L1 and B1 are only 14.322 MHz apart in frequency, the architecture does not need to be really broadband, and a minimum bandwidth of 19 MHz is sufficient when only the BOC(1,1) part of the CBOC or TMBOC is considered [121].

As for the FE topology, given that a significant amount of the energy of open service GNSS signals is around the carrier frequency, the low-IF topology is more suitable than the zero-IF topology. In fact, the low-IF topology avoids the problem of the DC offset and flicker noise of the CMOS implementation as well as RF-to-LO crosstalk [122]. Moreover, a higher bandwidth than the one required for L1 C/A is reserved by regulation for the M-code, and thus the GNSS signals in the low-IF topology around L1 C/A are dominated only by thermal noise which enables us to exploit the low-IF topology to downconvert the signals in the vicinity of the L1 band.

For these reasons, the low-IF topology is chosen for the FE. The FE architecture is shown in Figure 4.1. It is a single-channel FE which uses one LO to downconvert all three desired bands of signals to their respective IFs (note that E1 and L1 overlap). The presented FE employs a complex conversion to cope with the low-power requirement while enabling image suppression in the baseband processor.

![Figure 4.1 – Hybrid GPS/Galileo/Beidou front-end architecture.](image)

The LNA in Figure 4.1 is followed by a passive IQ downconverter that is then followed by a translational filter (TF) in both the I and Q paths. The passive mixer in conjunction with the TF results in a voltage sampling arrangement. The TF itself delivers an RF band-limited impedance response at the LNA output that helps to maximize the LNA linearity by presenting a low impedance out of band which in turn minimizes any voltage swing that is generated by unwanted interferers. This is an important concept that is the key to the RF receiver architecture’s delivering both a low NF and high gain (to limit downstream NF degradation) along with an acceptable out-of-band IP3. The TF is followed by a high-dynamic-range VGAs with the desirable attributes of high input impedance (in line with the mixer’s voltage sampling operation). The VGA contains a number of gain steps to be used in conjunction with the LNA as part of an overall FE gain plan. Each path ends with a 6-bit flash ADC that delivers the downconverted signals to the baseband processor.
A SAW filter is placed between the active antenna and the FE to relax the linearity requirements of the FE by suppressing the out-of-band interferers.

### 4.1.3 Frequency plan

In the low-IF receiver, choosing the value of the IF is a matter of trade-offs. On one hand, the IF should be high enough to easily remove the DC offset and avoid flicker noise. On the other hand, a lower IF allows for lower-power ADCs and IF filters.

Given the low-IF architecture of the FE, the DC offset can easily be canceled by decoupling capacitors throughout the FE chain. These decoupling capacitors exhibit a high-pass response with the cut-off frequency around 2 MHz. It is intended to reuse the same IF filter in section 3.3 (only a small modification in the filter is needed which will be discussed later on) for this FE. As shown in section 3.3, the filter offers a range from 7.4 to 27.4 MHz for its cut-off frequency, which results in a similar range for the FE’s intermediate frequency.

The downconversion frequency can be chosen by considering the FE’s IF range and topology. There are three main possible ranges of frequencies for the FE’s LO. The first option is to place the LO slightly lower than Beidou B1 in the frequency range of 1550.066–1557.052 MHz. This frequency range downconverts the L1 and B1 to their respective IFs: 4.046–11.032 MHz for B1, and 18.368–25.354 MHz for L1 (assuming that both bands have a bandwidth of 4 MHz).

The other option is to place the LO higher than the L1 band in the frequency range of 1579.466–1604.866 MHz, which results in a similar range of IFs in the left side of the frequency axis: from -25.354 to -18.368 MHz for B1, and from -11.032 to -4.046 MHz for L1. However, the second option not only does not offer any advantage over the first one, but also requires that the VCO work at higher frequency, which entails an inevitable higher power consumption of the synthesizer.

The third possible range for the LO can be obtained by placing the LO between the B1 and L1 band. This downconverts the B1 and L1 to a negative and positive IF, respectively. Thanks to the complex downconversion, the B1 and L1 band can be separated in the baseband processor. The feasible range of frequencies for this option is from 1565.144 to 1571.374 MHz. Moreover, the required IF bandwidth, in this case, is half that of the first option. Therefore, placing the LO between the B1 and L1 band seems to be an optimal choice with regard to power consumption. However, selecting the LO also depends on the choice of the reference frequency as well as the synthesizer.

Moreover, choosing a temperature-compensated crystal oscillator (TCXO) as the reference frequency is not trivial, since the TCXO performs as a source of interference in a case of adverse selection. In fact, the integer harmonics of the reference frequency as well as their mixing products are expected to appear at RF [123]. Even though these harmonics are usually weaker than the external interferers, for a GNSS receiver in which the received signal power is around -157 dBW, they are critical if they fall within the bands of interest. Although in differential
implementation the even harmonics of the reference frequency will be canceled, achieving the perfect cancellation of the even harmonics requires a particular attention in the layout of the FE to be completely symmetrical. This is hard to achieve and guarantee, and it is therefore better to avoid having any harmonic in the desired bands. For this reason, a good practice is to consider all the integer harmonics of the reference frequency and make sure that none of them falls within the B1 and L1 bands.

As a consequence, even though the LO range of 1565.144–1571.374 MHz seems optimal with regard to power consumption, the FE requires either a fractional-N PLL in the synthesizer with any common practical TCXOs of 16.369, 26, 30.72, 49.125, 50.1, 50.625 or 51.84 MHz or an integer-N with a big prime number divider. Therefore, for the simplicity of the design, 1555.2 MHz is chosen as the LO (LO below the B1 band). Since the downconverter requires quadrature clocks, twice this frequency can be achieved by an integer-N PLL with $N = 60$ from a TCXO of 51.84 MHz.

Accordingly, the frequency plan for this RF receiver is outlined in Figure 4.2. Setting the LO at 1555.2 MHz results in the IFs of 5.898 and 20.22 MHz for the B1 and L1, respectively. As was mentioned before, the IF filter’s $f_c$ is tunable which, in combination with this frequency plan, results in a reconfigurable FE with two modes of operation: narrow-band (NB) and wide-band (WB). For $f_c$ at 8 MHz, the FE is able to receive the B1-I with a 4 MHz BW in its NB mode, and is capable of receiving both the L1 and B1-I for $f_c$ at 23 MHz in its WB mode.
4.2 Beidou RF front-end specifications

4.2.1 Power supply

Since the front-end is designed for portable and battery-powered applications, its power consumption is of course one concern of the design. Considering the state-of-the art GNSS MFFEs in Table 1.2, the average power consumption of a FE is 54 mW. This value is half of the intended power for the PRS receiver presented in section 2, which has two independent FE operating simultaneously. Therefore, 54 mW is considered as the maximum power consumption for the FE in its WB mode of operation. In the NB operating mode, however, the FE requires less bandwidth in its IF section as well as lower sampling rate for its ADCs. Therefore, its power consumption will be less than 54 mW.

4.2.2 Noise and sensitivity

The definition of the FE’s noise figure (NF) is stated in section 2.3.2. In this section the relation between the noise and sensitivity of the FE is discussed to derive the maximum acceptable NF of the FE. The NF of the FE will degrade its sensitivity as well as the positioning accuracy of the receiver. The noise figure requirement of a FE is usually determined by FE’s minimum acceptable SNR. Given that the received signal strength for the L1, E1 and B1 is around -157 dBW, it is clear that these signals are dominated by thermal noise at the receiver’s input, and therefore have negative SNRs. Fortunately, since GNSS signals are being DSSS, their SNRs increase after despreading. Despreading correlates each signal with its respective PRN code and as a result concentrates the energy of the signal to a narrower bandwidth equivalent to the data rate ($R_b$) of the signal. On the other hand, since the noise is not correlated with the PRN code, its power will not be concentrated in the narrower bandwidth which results in higher SNR for the signal after the correlation. The boost in the SNR is determined by the processing gain ($G_p$), which depends on the data rate ($R_b$) and the chip rate ($R_c$) of the signal, and can be calculated for any GNSS signal by:

$$G_p = 10\log_{10}\left(\frac{R_c}{R_b}\right) \text{ [dB]}.$$  \hspace{1cm} (4.1)

Note that the processing gain can be further increased by integrating the signal beyond the bit boundary, either coherently or non-coherently depending on the knowledge or not of the data bits. Nevertheless, with the coherent integration, from (4.1) and Table 4.1, the $G_p$ is 43.1 dB for the L1 C/A and 36.1 dB for E1 and B1-I. However, despreading takes place in the baseband processor and the SNR of these signals is negative throughout the FE. This means that the bandwidth and SNR of the GNSS signals vary in the receivers from the FE to the baseband processor. Pre-correlation SNRs are negative, whereas post-correlation SNRs are positive. Therefore, it is convenient to normalize the SNR to 1 Hz and achieve a $C/N_0$ that
4.2. Beidou RF front-end specifications

is independent of the signal’s bandwidth [61] (note that the signal’s bandwidths before and after correlation are different). The $C/N_0$ can easily be converted to SNR or $E_b/N_0$ using the following equation:

$$\frac{C}{N_0} [\text{ratio} - \text{Hz}] = \left( \frac{S}{N} \right) [\text{ratio}] B [\text{Hz}] = \left( \frac{E_b}{N_0} \right) [\text{ratio}] R_b [\text{Hz}],$$

(4.2)

where $B$ is the bandwidth of the signal and the terms in square brackets denote the units. The minimum required $C/N_0$ at the ADC’s output is determined by the specific algorithm and integration time within the digital baseband processor. Once the minimum required $C/N_0$ is given by a digital correlator, to maintain the wanted acquisition or tracking performance, the receiver sensitivity ($S$) is uniquely determined as [2]:

$$S [\text{dBm}] = \left( \frac{C}{N_0} \right)_{\text{min}} [\text{dB} - \text{Hz}] + N_0 \left[ \frac{\text{dBm}}{\text{Hz}} \right] + \text{NF} [\text{dB}]$$

$$= \left( \frac{E_b}{N_0} \right)_{\text{min}} [\text{dB}] + 10 \log_{10} R_b [\text{dB} - \text{Hz}] + N_0 \left[ \frac{\text{dBm}}{\text{Hz}} \right] + \text{NF} [\text{dB}].$$

(4.3)

Note that $N_0$ is the thermal noise power density, which is equal to $-174 \text{ dBm/Hz}$, and the terms in square brackets denote the units in which $C/N_0$ is being expressed. Assuming that the digital correlator yields a minimum $C/N_0$ of 25 dB-Hz, with a NF of 4 dB the receiver can achieve $-145$ dBm of sensitivity. Nevertheless, there is degradation of the receiver sensitivity due to the limited resolution of the ADC which is less than 0.5 dB for a 6-bit ADC [2, 61]. Note that 4 dB NF is for the FE including a RF filter and an active antenna. Considering, as a conservative worst case, an active antenna with 20 dB of gain and 3 dB of NF followed by a RF filter with 5 dB of loss, the ASIC FE with a NF of 12 dB will result in an overall NF of less than 4 dB for the receiver.

4.2.3 Gain

The required gain of the FE can be derived by considering the fact that it should amplify the noise signal at its input to a detectable signal for its ADC. Similar to chapter 2 a 6-bit ADC with a 500 mV full-scale input dynamic range is employed in this FE. With 4 bits of back-off for interference mitigation, the required ADC’s input voltage is around 31.25 mVpp. Since for a GNSS receiver, the signal that reaches the ADC is mainly thermal noise, it can be considered that 31.25 mVpp is three times the standard deviation ($\sigma$) of the noise voltage. Therefore, the required RMS voltage at the input of the ADC is 10.42 mV RMS. The ratio between this voltage and the noise voltage at the input of the antenna determines the required voltage gain of the FE. To that effect, the input noise power within the FE’s bandwidth of 21 MHz (WB mode) in absence of any interference can be calculated by:

$$P_{n,\text{ant}} [\text{dBm}] = N_0 + 10 \log(B) \approx -101 \text{ dBm},$$

(4.4)
where \( N_0 \) is the noise spectral density \((N_0 \approx -174 \text{ dBm/Hz} \text{ at a room temperature of } 290 \degree \text{K})\) and \( B \) is the equivalent noise bandwidth approximated by that of the FE’s most selective filter. The equivalent voltage of -101 dBm is \( 2 \mu \text{VRMS} \). Accordingly, the required receiver’s voltage gain can be estimated by:

\[
G_v = 20 \log \left( \frac{V_{n,\text{ADC}}}{V_{n,\text{ant}}} \right) = 20 \log \left( \frac{10.42 \text{ mVRMS}}{2 \mu \text{VRMS}} \right) \approx 74.3 \text{ dB.} \tag{4.5}
\]

Similarly, the required voltage gain for the FE in its NB mode is 79.3 dB. Considering temperature variations and additional losses, a gain range of 68 to 88 dB would be an appropriate gain range.

### 4.2.4 Subsystems specifications

#### 4.2.4.1 Gain and noise budget

The distribution of noise and gain requirements across the front-end chain is presented in Table 4.2. The high gain and low NF of the active antenna relax the noise requirements of the other sub-systems. The insertion losses of the RF filters are normally around 2 dB. The internal LNA combined with the downconversion stage should be able to provide a gain of 20 dB with a NF of 4 dB. However, this NF can be higher thanks to the external active antenna. Under these conditions, a total NF lower than 4 dB can be obtained if the IF section’s NF is kept on the order of 25–30 dB. These goals seem a feasible starting point to progress towards a more optimized gain/noise distribution.

#### 4.2.4.2 Active antenna

Antenna design is outside the scope of this thesis, therefore a gain of 30 dB and NF of 2 dB is considered for the active antenna. Active antennas that meet these specifications for the required frequency bands (L1/E1/B1-I) are available as commercial products from AMOTECH [124, 125].
4.2. Beidou RF front-end specifications

4.2.4.3 RF filter

Like the active antenna, the RF filter is not a topic of research in this thesis. Therefore a commercial product is considered for it. The RF filter in this FE should filter out all the frequencies except the ones for B1-I and L1/E1. A SAW filter from Murata Manufacturing Co., Ltd. (Product no. SAFFB1G56KB0F0A) [126] can be used.

4.2.4.4 Low-noise amplifier

The FE should cover both the L1 and B1 bands. Given that these two bands are separated from each other by only 14.322 MHz, and the required bandwidth for B1-I and E1 is 4 MHz, a minimum bandwidth of 18.42 MHz is sufficient for the LNA. To guarantee this minimum bandwidth, a 25 MHz bandwidth is chosen for the LNA. The requirements of the LNAs are summarized in Table 4.3.

Table 4.3 – LNA requirements.

<table>
<thead>
<tr>
<th>Requirement</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>Input impedance</td>
<td>50 Ω, single-ended, $</td>
</tr>
<tr>
<td>Output impedance</td>
<td>Match to downconverter, single-ended, $</td>
</tr>
<tr>
<td>Minimum gain</td>
<td>LNA + Mixer 20 dB</td>
</tr>
<tr>
<td>Maximum NF</td>
<td>LNA + Mixer 4 dB</td>
</tr>
<tr>
<td>Bandwidth</td>
<td>1568.26 ± 12.5 MHz</td>
</tr>
<tr>
<td>Supply voltage</td>
<td>1.8 V</td>
</tr>
<tr>
<td>DC power consumption</td>
<td>8 mW</td>
</tr>
</tbody>
</table>

4.2.4.5 Downconverter

The design requirements of the downconverter is summarized in Table 4.4.

Table 4.4 – Downconverter requirements.

<table>
<thead>
<tr>
<th>Requirement</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>Input impedance</td>
<td>Match to LNAs output, single-ended, $</td>
</tr>
<tr>
<td>Output impedance</td>
<td>Match to IF filter</td>
</tr>
<tr>
<td>Minimum gain</td>
<td>LNA + Mixer 20 dB</td>
</tr>
<tr>
<td>Maximum NF</td>
<td>LNA + Mixer 4 dB</td>
</tr>
<tr>
<td>Bandwidth</td>
<td>1555.2 ± 25 MHz</td>
</tr>
<tr>
<td>Supply voltage</td>
<td>1.8 V</td>
</tr>
<tr>
<td>DC power consumption</td>
<td>3 mW</td>
</tr>
</tbody>
</table>
4.2.4.6 Frequency synthesizer

Based on the frequency plan of the receiver, the frequency synthesizer should provide a fixed output at 1555.2 MHz to the mixer to downconvert the signal to the appropriate IF. However, since a 25% duty-cycle clock is required for the quadrature mixer, the frequency synthesizer will run at \(2 \times 1555.2 \text{ MHz} = 3110.4 \text{ MHz}\). The VCO signal then is divided in two by means of a 25% duty-cycle divider to drive the downconversion mixer.

Moreover, the VCO phase noise (PN) is one of the key features of a synthesizer in GNSS FEs because it affects the stability of the phase component of the code correlation. In fact, the tracking loops in the baseband processing are responsible for locking on the code delay (delay lock loop) and carrier frequency (frequency lock loop) or carrier phase (phase lock loop) using some or all of the correlations outputs (early, prompt and late) \([127]\). While these parameters are varying within acceptable bounds, set by the dynamics-handling capability of the tracking loops, the tracking loops are able to successfully track the satellite signal. However, increasing the PN increases the variation in phase of the correlation product calculated over consecutive epochs and may also cause loss of tracking lock if these variations go beyond the PLL pull-in range thresholds. It has been shown that, in order to maintain standard deviation of phase angle below 10 degrees, the maximum FE phase noise is \(-123 \text{ dBc/Hz} @ 1 \text{ MHz}\) and \(-83 \text{ dBc/Hz} @ 10 \text{ kHz}\) for 4 ms coherent integration time \([128]\). The PN requirement is more relaxed for a maximum PLL phase error of 25 degrees by 9 dB for 4 ms of integration time. The design requirements of the frequency synthesizer are summarized in Table 4.5.

<table>
<thead>
<tr>
<th>Requirement</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>Frequency output</td>
<td>3110.4 MHz</td>
</tr>
<tr>
<td>Phase noise</td>
<td>(&lt; -83 \text{ dBc/Hz} @ 10 \text{ kHz})</td>
</tr>
<tr>
<td>Supply voltage</td>
<td>1.8 V</td>
</tr>
<tr>
<td>DC power consumption</td>
<td>5-10 mW</td>
</tr>
</tbody>
</table>

4.2.4.7 Active IF filter

As was shown in section 2, an elliptic configuration is particularly convenient because of their abrupt cut-off that strongly mitigates out-of-band interferers while allowing sampling frequencies tightly above the Nyquist limit without suffering from aliasing noise. The design requirements of the active filter are summarized in Table 4.6. The specifications are noted for both NB and WB operating modes.

The average non-linear phase error is adopted from the calculation for the PRS receiver; however, this can be relaxed since the FE will receive only OS signals.
### 4.2. Beidou RF front-end specifications

#### Table 4.6 – Active IF filter requirements.

<table>
<thead>
<tr>
<th>Requirement</th>
<th>Value (narrow-band mode)</th>
<th>Value (wide-band mode)</th>
</tr>
</thead>
<tbody>
<tr>
<td>$f_3$ dB</td>
<td>8 MHz</td>
<td>23 MHz</td>
</tr>
<tr>
<td>[100 kHz, 2 MHz]</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Attenuation mask</td>
<td>10 dB @ 9 MHz</td>
<td>10 dB @ 25 MHz</td>
</tr>
<tr>
<td></td>
<td>20 dB @ 10 MHz</td>
<td>20 dB @ 27 MHz</td>
</tr>
<tr>
<td>Maximum ripple</td>
<td>2 dB</td>
<td></td>
</tr>
<tr>
<td>Minimum gain</td>
<td>−2 dB</td>
<td></td>
</tr>
<tr>
<td>Noise figure</td>
<td>Combined IF section &lt; 25 dB</td>
<td></td>
</tr>
<tr>
<td>Supply voltage</td>
<td>1.8 V</td>
<td></td>
</tr>
<tr>
<td>DC power consumption</td>
<td>4 mW/filter</td>
<td>8 mW/filter</td>
</tr>
<tr>
<td>Average non-linear phase error</td>
<td>8.8°</td>
<td></td>
</tr>
</tbody>
</table>

#### 4.2.4.8 Variable-gain amplifier

The VGA provides the gain of the FE aside from the gain that is provided by the LNA (also some losses through the mixer and possibly the IF filter). The VGAs are digitally controlled, either through direct selection of the gain, or by means of the AGC configured via a serial peripheral interface (SPI). Considering the required gain range given in section 4.2.3 and a 30 dB gain of the active antenna, a gain range between 20 dB and 40 dB is sufficient for the VGA to compensate for process, temperature and voltage variations. A gain step resolution of 1.25 dB is chosen for the VGA, which can compensate for an amplitude IQ mismatch of more than 0.63 dB. This can be achieved by means of a 4-bit control in the VGA. Furthermore, the IF section also presents a transmission zero at DC to cancel offset errors due to fabrication mismatches in the differential pairs (stages will be AC-coupled) and to reduce noise (typically high close to DC, but also because of the self-mix of the local oscillator). The requirements of the VGA are summarized in Table 4.7.

#### Table 4.7 – Variable gain amplifier requirements.

<table>
<thead>
<tr>
<th>Requirement</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>$f_3$ dB</td>
<td>&gt; 27 MHz</td>
</tr>
<tr>
<td>Gain</td>
<td>[20, 40] dB in 1.25 dB-steps</td>
</tr>
<tr>
<td>Maximum ripple</td>
<td>&lt; 1 dB</td>
</tr>
<tr>
<td>Noise figure</td>
<td>Combined IF section &lt; 25 dB</td>
</tr>
<tr>
<td>Control bits</td>
<td>4 bits</td>
</tr>
<tr>
<td>Supply voltage</td>
<td>1.8 V</td>
</tr>
<tr>
<td>DC power consumption</td>
<td>3 mW/filter</td>
</tr>
</tbody>
</table>
4.2.4.9 Analog-to-digital converter

Similar to the PRS receiver in section 2 a 6-bit resolution was chosen for the ADC. The purpose of the 6-bit high-frequency ADC is to enable the implementation of effective interference-mitigation algorithms at the baseband. It is intended to reuse the ADC presented in section 2.4.1, for this front-end. The ADC requirements are presented in Table 4.8.

The sampling frequency of the ADC is determined by the maximum FE’s bandwidth. Thanks to the highly selective IF filter, for a FE’s bandwidth of 23 MHz, the IF section can provide more than 10 dB attenuation at 25 MHz. Therefore, a minimum sampling frequency of around 50 MHz should be more than enough on this regard, and increasing this figure increases the power consumption of the ADC with little performance improvement.

Table 4.8 – Analog-to-digital converter requirements.

<table>
<thead>
<tr>
<th>Requirement</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>Precision</td>
<td>6 bits</td>
</tr>
<tr>
<td>DNL</td>
<td>0.3 LSB</td>
</tr>
<tr>
<td>Sampling frequency</td>
<td>&gt;50 MSps</td>
</tr>
<tr>
<td>Supply voltage</td>
<td>1.8 V</td>
</tr>
<tr>
<td>DC power consumption</td>
<td>120 μW/MHz per ADC</td>
</tr>
</tbody>
</table>

4.3 Subsystems design

4.3.1 Low-noise amplifier

This section presents the LNA designs developed for the RF FE during the course of this thesis. The circuit requirements are laid out in Table 4.3. Although only 25 MHz bandwidth is required for the LNA, considering that the bandwidth of the IF section will be wide enough to be adequate for all the GNSS signals, a wideband LNA to cover all the GNSS signals (frequency range of 1145–1600 MHz) is desirable for a design reuse approach. On the other hand, a NF below 3 dB is required for the LNA. This is easily achievable by employing inductors in the LNA but only for a narrow frequency band [129]. Besides, on-chip inductors are bulky in CMOS process. Therefore, in order to achieve a compact wideband LNA, the use of an inductor is avoided in this design.

Wideband LNA topologies have been studied extensively in the literature [129–133]. Among these topologies, the resistive shunt feedback topology in Figure 4.3 has shown superior performance within the design of the wideband LNAs [130, 131, 133]. This topology has a straightforward bandwidth equation [134] as:

\[
f_{3dB} = \frac{1 + A_v}{2\pi R_f \left( C_{gs} + (1 + A_v)C_{gd} \right)}.
\]
4.3. Subsystems design

Figure 4.3 – A resistive shunt feedback LNA.

where $A_v$ is the voltage gain and can be given by

$$A_v = \frac{R_o(1 - g_m R_f)}{R_o + R_f}, \quad (4.7)$$

$C_{gs}$ and $C_{gd}$ are the parasitic capacitance of the transistor M1, $R_f$ is the shunt feedback resistor, and $R_o$ is the output impedance of the LNA. The minimum noise factor ($F$), achievable by this topology can be written as [135]:

$$F \geq 1 + \frac{4\gamma g_m}{\alpha R_s} \left( \frac{R_o(R_s + R_f)}{A_v(R_o(1 + g_m R_s) + (R_s + R_f))} \right)^2, \quad (4.8)$$

where, $R_s$ is the source impedance, $\gamma$ is the thermal noise coefficient of the technology, and $\alpha = g_m / g_{d0}$.

It is clear from (4.6) that a higher $A_v$ and smaller $R_f$ result in a wider bandwidth. However, from (4.8), a smaller $R_f$ deteriorates the noise performance of this LNA. Therefore, this topology requires a high $A_v$ and $R_f$ in order to achieve both the wide bandwidth and low noise response.

Transistor implementation of the LNA is shown in Figure 4.4. In order to achieve a higher $A_v$, a CMOS inverter, consisting of transistors M1 and M2, is adopted, providing larger $I_d/g_m$ (current reuse). Therefore, the overall equivalent transconductance in (4.6)–(4.8) increases from $g_m$ to $g_{m1} + g_{m2}$. This allows for a higher $R_f$ for a given bandwidth which, since the total NF is dominated by this inverter amplifier, leads to a lower NF. However, as shown in (4.6) the operating bandwidth is limited by the parasitic capacitance of the CMOS transistors which in this case are M1 and M2. To lessen their effect and increase the bandwidth, a peaking inductor, $L_M$, is placed at the input of the inverter cell. It is placed externally as a matching circuit to facilitate the tuning and matching process.

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Chapter 4. Multi-constellation L1/E1/B1 receiver

A source follower (M3) is added as the second amplifying stage to increase the overall gain of the LNA. It also prevents the inverter stage from being loaded by the eventual 400 $\Omega$ from the downconverter and the IF filter. Employing inductors in the gate and drain of the M3 can result in a smaller noise contribution from the second stage amplifier and an increase in the overall gain of the LNA. However, given the high gain of the inverter resistive shunt feedback stage, the noise contribution of the second stage is not significant on the NF of the LNA, thus inductors can be avoided to achieve a more compact circuit.

The inverter-based amplifier is a self-bias structure and transistors M5–M8 provide the bias current for M3 and M4. The capacitor $C_{BP}$ is employed to maintain the constant bounce in VDD and GND as well as reduce the sensitivity of this structure to the supply noise. The LNA is integrated within the FE and its output is not taken out to avoid any parasitic capacitance due to the pad and package. The matching network is implemented externally by means of a decoupling capacitor in series with a boosting inductor. The external matching network is tuned for the bands of interest.

The transistor’s geometry and operating current along with the value of the resistor and capacitors are shown in Table 4.9. The measured return loss is presented in section 4.4.4. The simulated NF for the frequency range of interest is shown in Figure 4.5. The LNA consumes 5 mA from 1.8 V and has a voltage gain of 32 dB.

4.3.2 Downconverter

Active Gilbert downconverter mixers have been widely used in integrated receiver systems due to their superior gain performance. However, they suffer from voltage headroom limitations and high flicker noise, as technologies scale down [136, 137]. Additionally, due to current-to-voltage followed by voltage-to-current conversions, the combined LNA and mixer suffers from poor linearity, which is generally not adequate for today’s multi-band receivers. This is also a concern of GNSS receivers in presence of interferers.

![Figure 4.4 – Schematic of the integrated LNA.](image-url)
4.3. Subsystems design

Table 4.9 – Geometry and operating point of the LNA’s transistors with components’ values.

<table>
<thead>
<tr>
<th>Device</th>
<th>W/L μm</th>
<th>I_d μA</th>
<th>Parameter</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>M1</td>
<td>26/0.18</td>
<td>2398</td>
<td>R_f</td>
<td>10.98 kΩ</td>
</tr>
<tr>
<td>M2</td>
<td>44.88/0.18</td>
<td>2398</td>
<td>C</td>
<td>999 fF</td>
</tr>
<tr>
<td>M3</td>
<td>20/0.18</td>
<td>2080</td>
<td>C_{BP}</td>
<td>12.85 pF</td>
</tr>
<tr>
<td>M4</td>
<td>33.84/0.24</td>
<td>2080</td>
<td>C_{DC}</td>
<td>10 pF</td>
</tr>
<tr>
<td>M5</td>
<td>2/0.24</td>
<td>519.6</td>
<td>I_M</td>
<td>13.6 nH</td>
</tr>
<tr>
<td>M6</td>
<td>33.84/1</td>
<td>519.6</td>
<td></td>
<td></td>
</tr>
<tr>
<td>M7,8</td>
<td>1/5</td>
<td>3</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

Figure 4.5 – Simulated noise figure of the LNA in Figure 4.4.

One solution to this problem is to employ a passive mixer, which was introduced in [138] and has been used in numerous receivers since then [139–144]. Passive mixers can operate either in voltage mode or in current mode depending on the relative values of the RF and baseband (BB) impedances. The current mode operation is popular in low-voltage applications because it shows better linearity and a higher capability of handling large signal swings [145, 146].

4.3.2.1 Current-driven passive mixer

The downconversion passive mixer consists of CMOS switches that work in conjunction with a LNA and a BB load as shown in Figure 4.6 where the LNA and BB load are sketched as an RF current source and a frequency-selective impedance, respectively. The switches’ V_{DS} are set to zero. Therefore, the mixer commutates only the RF current supplied by an LNA to a baseband current, i_{BB}. In this structure, when used in the AC-coupled configuration, mixer switches do not carry any DC current, hence contribute no flicker noise. The downconverted current is
delivered to a BB load which is a low input impedance transimpedance amplifier. As a result, in a careful design the voltage swings across the switches remain low, making the structure highly linear. The low- and zero-IF receivers can benefit from the lower power consumption, modest headroom requirements, high linearity and excellent flicker noise performance of passive mixers despite their lower conversion gain [136, 147].

Figure 4.6 – Downconversion current-driven passive mixer with a baseband impedance $Z_{BB}(s)$, RF source $I_{RF} \exp(j\phi_{RF})$ and RF load $Z_L(s)$.

To understand the concept of frequency translation in the current-driven passive mixer in Figure 4.6, let’s assume that $LO_n$ and $LO_p$ are out-of-phase rail-to-rail square-wave which drive the mixer as the local oscillator with the frequency of $\omega_{LO}$. As a result of the frequency translation, the RF current $i_{RF}$, is downconverted to a baseband current of $i_{BB} = \frac{2}{\pi} i_{RF}(t) \cos(\omega_{LO} t)$ [136]. Therefore, the resulting baseband voltage, assuming that the baseband impedance of $Z_{BB}$ is a linear time-invariant (LTI) system, is:

$$v_{BB}(t) = \left[ \frac{2}{\pi} i_{RF}(t) \cos(\omega_{LO} t) \right] * Z_{BB}(t), \quad (4.9)$$

where * is the convolution sign.

So far, the concept of a current-driven passive mixer is not much different from an active mixer. However, contrary to the active mixer, there is no reverse isolation in a current-driven passive mixer. This will cause the baseband impedance of $Z_{BB}$ to be scaled and frequency-shifted to $\pm \omega_{LO}$ and its odd harmonics and appear at the RF. In fact, at the RF side of the switch, at any moment only one of the CMOS switches is ON and can be represented by the ON resistance $R_{SW}$ of the switch. In contrast, the baseband voltage at any moment is either $+v_{bb}(t)/2$ or $-v_{bb}(t)/2$, depending on which switch is ON. As a matter of fact, by ignoring its higher-order harmonics, the RF voltage can be written as [136]

$$v_{RF}(t) = R_{SW} i_{RF}(t) + \frac{4}{\pi^2} \cos(\omega_{LO} t) \left[ i_{RF}(t) \cos(\omega_{LO} t) * Z_{BB}(t) \right]. \quad (4.10)$$

This indicates that $Z_{BB}$ is scaled and shifted in frequency to the RF. It means a low-Q LPF
4.3. Subsystems design

will appear at the output of the LNA as a high-Q BPF.

The basic concept of non-quadrature downconversion current-driven passive mixer was presented above. However, the proposed front-end requires a quadrature downconversion. The quadrature downconversion passive mixer consists of four switches as opposed to two in the non-quadrature mixer. There are mainly two possibilities to configure the required LO of this type of mixers: 25% and 50% duty-cycle rail-to-rail square-waves [139–142, 148]. Mirzaei et al. have performed a detailed analysis of a 50% duty-cycle current-driven passive mixer in [136]. Although the mixer seems to be suitable for a low-voltage multi-band receiver, it suffers from unequal high- and low-side conversion gain, input-referred second-order intercept point (IIP2) and IIP3. It also suffers from unexpected IIP2 and IIP3 as well as IQ crosstalk as compared to its 25% duty-cycle counterpart.

In fact, applying 25% duty-cycle quadrature clocks to the passive mixer increases the down-conversion gain by 3 dB as compared to 50% duty-cycle. This reduces the noise contribution of the following stages [141, 142, 149]. Moreover, since within a 25% passive mixer only one of the switches is ON at any moment, there is therefore no crosstalk between I and Q in the two quadrature channels. This not only alleviates the problem of the crosstalk in 50% duty-cycle mixers but also prevents that the nonlinear components from one channel leak to the other one and as a result reduces the issue of having unexpected IIP2 and IIP3 of the receiver.

A 25% duty-cycle passive mixer is employed in the proposed front-end due to its aforementioned advantages over its 50% duty-cycle counterpart. Figure 4.7 shows a simple model of a typical IQ receiver front-end with current-driven passive downconversion mixers driven by rail-to-rail 25% duty-cycle quadrature clocks. The clock phases are also shown in the figure and for simplicity the baseband impedance is shown by $Z_{BB}(s)$ and a simple mode is used for the LNA.

As was mentioned before, this mixer scales and shifts the baseband impedance to the RF. In order to match the LNA to the frequency-shifted baseband impedance, it is necessary to calculate the input impedance at the RF side of the mixer. Additionally, the downconversion gain which is needed for the design is then calculated. More detailed mathematical derivations and analysis of the mixer can be found in [150].

For the simplicity of the analysis, let’s assume the switches are ideal except they have an ON resistance of $R_{SW}$. From the clock phases in Figure 4.7, it is observed that over a period of $T_{LO}/4$ ($T_{LO}$ is the LO period), only one of the four switches is ON and that the mixer current $i_{Mix}$ flows to the corresponding baseband impedance. To analyze the mixing system, we can define the periodic function corresponding to the $LO_{I+}$ as:

$$
LO_{I+}(t) = \begin{cases} 
1, & kT_{LO} \leq t \leq (k + \frac{1}{4})T_{LO}, \\
0, & (k + \frac{1}{4})T_{LO} < t < (k + 1)T_{LO},
\end{cases}
$$

(4.11)
where $k$ is an integer number. Accordingly, the other LOs can be written:

\[
LO_{Q+}(t) = LO_{I+} \left( t - \frac{T_{LO}}{4} \right), \tag{4.12}
\]
\[
LO_{I-}(t) = LO_{I+} \left( t - \frac{T_{LO}}{2} \right), \tag{4.13}
\]
\[
LO_{Q-}(t) = LO_{I+} \left( t - \frac{3T_{LO}}{4} \right). \tag{4.14}
\]

Now, for example, the baseband current corresponding to $I^+$ can be written as:

\[
i_{BB,I+}(t) = LO_{I+}(t)i_{Mix}(t). \tag{4.15}
\]

and similarly for the other paths:

\[
i_{BB,Q+}(t) = LO_{Q+}(t)i_{Mix}(t), \tag{4.16}
\]
\[
i_{BB,I-}(t) = LO_{I-}(t)i_{Mix}(t), \tag{4.17}
\]
\[
i_{BB,Q-}(t) = LO_{Q-}(t)i_{Mix}(t). \tag{4.18}
\]

These currents flow into the corresponding $Z_{BB}(s)$, which results in the following baseband
voltages:

\[ v_{BB,I+}(t) = i_{BB,I+}(t) \ast Z_{BB}(t), \]
\[ v_{BB,Q+}(t) = i_{BB,Q+}(t) \ast Z_{BB}(t), \]
\[ v_{BB,I-}(t) = i_{BB,I-}(t) \ast Z_{BB}(t), \]
\[ v_{BB,Q-}(t) = i_{BB,Q-}(t) \ast Z_{BB}(t), \]

where \( \ast \) is the convolution sign. In order to find the input impedance \( Z_{in}(s) \) at the RF side of the mixer, first we have to find the \( v_{RF}(f) \). This voltage is a result of the corresponding baseband voltages \( v_{BB}(t) \) translated to the RF, similar to the downconversion mechanism, plus the voltage drop on the ON resistance of the switches \( R_{SW} \) and can be written as:

\[ v_{RF}(t) = R_{SW} i_{Mix}(t) + LOI+ (t) v_{BB,I+}(t) + LOI- (t) v_{BB,I-}(t) \]
\[ + LOQ+ (t) v_{BB,Q+}(t) + LOQ- (t) v_{BB,Q-}(t). \]

Considering the Fourier series of (4.11)–(4.14) and considering (4.15)–(4.22), the input impedance at the RF side of the mixer can be written as:

\[ Z_{in}(\omega) = \frac{V_{RF}(\omega)}{I_{Mix}(\omega)} \equiv R_{SW} + \frac{2}{\pi^2} [Z_{BB}(\omega - \omega_{LO}) + Z_{BB}(\omega + \omega_{LO})]. \]

Note that (4.24) is approximated in the vicinity of the \( \omega_{LO} \) and that the term of \( Z_{BB}(\omega) \) at the baseband as well as at higher harmonics of \( \omega_{LO} \) is omitted for simplicity. The elaborated equations can be found in [150].

From (4.24), the input impedance is the switch resistance in series with the baseband impedance, which is scaled and frequency-shifted to \( \omega_{LO} \). The latter is called impedance transformation; with this property a low-Q low-pass filter will be transferred to a high-Q bandpass filter at the \( \omega_{LO} \). The input impedance in (4.24) also can be used for impedance matching between the LNA and the following stage of the mixer.

In order to calculate the downconversion gain of the mixer, first we need to calculate the baseband current of interest for I (in-phase), \( i_{BB,I} = i_{BB,I+} - i_{BB,I-} \) and Q (quadrature phase), \( i_{BB,Q} = i_{BB,Q+} - i_{BB,Q-} \). Assuming that the RF is above the \( \omega_{LO} \) (as for the case of this FE), from (4.15)–(4.18) and the Fourier series of (4.11)–(4.14) the baseband current can be written as:

\[ I_{BB,I} = e^{-j\frac{\pi}{4}} I_{BB,Q} = \frac{\sqrt{2}}{\pi} I_{Mix} e^{j(\phi_{Mix} - \pi/4)}, \]

where \( I_{Mix} e^{j\phi_{Mix}} \) is the phasor representation of the current flowing to the mixer at the RF side. Therefore, the downconversion gain, \( G_C \), can be written as:

\[ G_C = \left| \frac{I_{BB,I}}{I_{Mix}} \right| = \frac{\sqrt{2}}{\pi}, \]

which is equal to -6.9 dB. However, the overall downconversion gain \( |I_{BB,I}/I_{RF}| \) depends on
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the LNA impedance, $Z_L(s)$, and input impedance $Z_{in}(\omega)$ from (4.24). To that effect, $I_{Mix}$ can be presented as:

$$I_{Mix}(\omega_{RF})e^{j\phi_{mix}} = \frac{Z_L(\omega_{RF})}{Z_L(\omega_{RF}) + Z_C(\omega_{RF}) + R_{SW} + \frac{2}{\pi} Z_{BB}(\omega_{RF})} I_{RF} e^{j\phi_{RF}}, \quad (4.27)$$

where $Z_C(\omega_{RF})$ is the impedance of the capacitor $C$ in Figure 4.7 at the RF. Therefore, the overall conversion gain is:

$$G_C = \left| \frac{I_{BB,I}}{I_{RF}} \right| = \left| \frac{\sqrt{2}}{\pi} \frac{Z_L(\omega_{RF})}{Z_L(\omega_{RF}) + Z_C(\omega_{RF}) + R_{SW} + \frac{2}{\pi} Z_{BB}(\omega_{RF})} \right|. \quad (4.28)$$

Conventionally, the series capacitor $C$ is selected to be large enough to have very small $Z_C(\omega_{RF})$, and $Z_L(\omega_{RF})$ is designed to be much larger than $R_{SW} + \frac{2}{\pi} Z_{BB}(\omega_{RF})$. In this case the overall $G_C$ approaches the constant value of $\frac{\sqrt{2}}{\pi}$ over the frequency. However, it is shown in [150] that the $Z_L(s)$ can be optimized to result in a higher conversion gain.

For the purpose of this frond-end, as described in section 4.3.1, the LNA has been designed to have very high $Z_L(\omega_{RF})$, with the capacitance $C$ given in Table 4.9 as 999 fF. The switch’s width is 60 $\mu$m with the minimum length of 0.18 $\mu$m which results in an effective ON resistance of 40 $\Omega$. The baseband load is the low-pass filter presented in section 3.3 but the first input OTA is removed to acquire a low-impedance trans-impedance load. With this configuration, the mixer shows a conversion gain of -8.5 dB and accordingly the overall downconversion gain of the LNA, mixer and the low-pass filter, as shown in Figure 4.8, is 20 dB.

![Figure 4.8](image-url)

Figure 4.8 – Simulated overall downconversion gain achieved by the LNA, 25% duty-cycle current-driven passive mixer and the low-pass filter. The LO is at 1555.2 MHz. The frequency axis, offset from the LO, indicates the IF.

Figure 4.9 shows the frequency transformation property of the 25% duty-cycle current-
4.3. Subsystems design

driven passive mixer. The low-pass filter transfer function is frequency-shifted to the RF frequency. The simulated high- and low-side conversion gains versus the input RF are shown in red and blue, respectively, which together form a very high-Q band-pass filter. The cut-off frequency of the filter in Figure 4.9 is 29.5 MHz which results in a Q of 26, however, the filter’s cut-off frequency can be tuned to 8 MHz and as a result the Q will reach 97.

Figure 4.9 – Demonstration of the frequency transformation property of the 25% duty-cycle current-driven passive mixer. Simulated high- and low-side conversion gains are shown by red and blue, respectively.

4.3.2.2 25% duty-cycle divider

To maximize the conversion gain and to reduce IQ interaction, a 25% duty-cycle clock must be used to drive the mixer. In the passive mixer architecture, the generation and distribution of the clock are the only power-consuming parts of the circuit and since they are operating at $2 \times f_{LO}$ they could become very power hungry. In this design the four clock phases are generated directly by a divider, avoiding the use of a dedicated stage for saving power. The employed divider was originally proposed by Razavi et al. [151] and was modified by Fabiano et al. [140] by eliminating the static power consumption of the original circuit. The divider along with its four-phase 25% duty-cycle outputs is shown in Figure 4.10 (b). It employs the latch in Figure 4.10 (a) to generate 25% duty-cycle outputs.

The latch in Figure 4.10 (a) consists of two sense devices (M3a and M3d), a regeneration loop (M3b and M3c), two pull-down devices (M1a and M1b) and two pass devices (M2a and M2b) that were added to eliminate the static power [140]. Assuming that the $Q$ and $\overline{Q}$ are high and low, respectively, when the latch senses the signal and the CLK goes down, the pull-down devices are OFF, and $Q$ maintains its state while the $\overline{Q}$ is pulled-up by the input sense device. This asymmetry in the latch response gives the 25% duty-cycle output. Transistors M2a and
M2b prevent the static current, when the M1a and M1b are ON and either one of the two inputs is low, by eliminating the direct path between VDD and ground. The divider requires a differential input to generate four phases of the output shown in Figure 4.10 (b). The driver

![Figure 4.10](image)

Figure 4.10 – 25% duty-cycle divider: (a) Schematic of the latch, and (b) the divider including two latches in (a) and four inverters, along with its four-phases outputs to drive the passive mixer.

in Figure 4.10 (b) including its inverters consumes 2.45 mA from 1.8 V. Table 4.10 shows the geometry of the transistors of the latch designed for the divider.

<table>
<thead>
<tr>
<th>Device</th>
<th>M1a,b</th>
<th>M2a,b</th>
<th>M3a,b,c,d</th>
</tr>
</thead>
<tbody>
<tr>
<td>W/L μm</td>
<td>23.2/0.18</td>
<td>8.7/0.18</td>
<td>29/0.18</td>
</tr>
</tbody>
</table>

### 4.3.3 Frequency synthesizer

This section is dedicated to the design of the VCO and the PLL for the FE. The PLL is a closed-loop feedback system which forces the output signal to track the input in the frequency and the phase. In other words, the PLL is a servo system that in closed loop controls the phase of its output signal to follow the phase of its input signal. The ultimate result is to have precisely zero difference in the phase and frequency between the PLL output signal and input reference. Nevertheless, some static phase errors may still exist in the steady state, due to practical non-idealities i.e. charge pump (CP) mismatches.

A FS is the most common application of a PLL. Having a high-frequency low-PN clock is not possible directly from a crystal oscillator, which is the best source of high-quality clock. Besides, many systems need different clock frequencies to work. The PLL allows a stable high-frequency signal to be generated from a low-frequency reference. Any system
that requires stable high frequency tuning can benefit from the PLL technique. Examples of these applications include a GSM handset or base station and GNSS receivers. If the system demands a high-performance and low phase noise LO, such as a GSM system, an analog PLL is typically preferred. This has been changed lately and all-digital phase-locked loops (ADPLLs) have been developed to be suitable for mobile phones [152, 153]. However, an analog PLL is chosen for this thesis due to background experience of the author.

The general architecture of the FS along with the signals associated with different nodes of the system is given in Figure 4.11. As can be seen in Figure 4.11, the VCO output, \( \text{Out}(t) \), is divided by \( N \), and then the phase of the result signal, \( \text{Div}(t) \), is compared with the phase of the reference source, \( \text{Ref}(t) \), in order to produce an error signal \( E(t) \). The phase comparison is done by means of a phase-frequency detector (PFD) which also acts as a frequency discriminator when the PLL is out of lock. The \( E(t) \) controls the CP, but due to the non-ideal performance of the PFD and CP, the output of the CP contains high-frequency components that must be attenuated before feeding into the VCO input. This task is accomplished by the loop filter (LPF in Figure 4.11). The filtered error signal, \( V_{\text{cont}}(t) \), adjusts the frequency of the VCO, and the feedback action of the PLL accurately sets the output carrier frequency [154].

The requirements for the frequency synthesizer of the FE are available in Table 4.5. Based on the frequency plan of the receiver, the frequency synthesizer should provide fixed outputs at 3110.4 MHz to the 25% duty-cycle divider which drives the downconversion mixer. However, due to the inaccuracy and tolerance of the passive components in CMOS technology such as inductor inaccuracy (±5%) and capacitor tolerance (±15%), as well as few percent error in parasitic estimation, a ±200 MHz tuning range around 3110.4 MHz is considered for the VCO.

The design starts by choosing the TCXO as the reference and local oscillator frequency. This was discussed in section 4.1.3, where a reference frequency of 51.84 MHz was chosen for the design. An integer-N PLL with \( N = 60 \) can provide a 3110.4 MHz signal. Half of this
frequency drives the mixer as its local oscillator \( (f_{LO} = 1555.2 \text{ MHz}) \). As a consequence of this \( f_{LO} \), the two signals (BeiDou and GPS) will be centered at the IF frequency of \( f_{B1} = 5.898 \text{ MHz} \) and \( f_{L1} = 20.22 \text{ MHz} \), respectively.

### 4.3.3.1 VCO

In the course of this thesis, the most important parameter of the VCO is its PN (see section 4.2.4.6); the power consumption and the tuning range are of less concern. Therefore, a LC-VCO which has a good PN and jitter performance at high frequency among the different types of VCOs is adopted. Furthermore, a differential top-biased cross-coupled LC tank shown in Figure 4.12 is chosen as the topology for the oscillator owing to the fact that it shows a better PN compared to the complementary cross-coupled at high voltage swing [155]. The VCO also features differentially tuned varactors, which treat all low-frequency noise, such as flicker noise, as common-mode noise and suppress it from being up-converted to the carrier frequency.

![Figure 4.12 – Top-biased cross-coupled LC-VCO topology. The frequency selective network is comprised of both LC tanks, and \( R_T \) is the equivalent differential resistance of each tank.](image)

The oscillation frequency, \( \omega_o \), is set by the frequency selective network in Figure 4.12 and can be written as:

\[
\omega_o = \frac{1}{\sqrt{LC_{eq}}},
\]

where \( C_{eq} = C + C_{par} \), and \( C_{par} \) is the parasitic capacitance. The frequency selective network is comprised of both LC tanks, and \( R_T \) is the equivalent differential resistance of each tank. Apart from the oscillation frequency, the most fundamental design criterion for any oscillator consists of satisfying the start-up conditions. Such conditions are satisfied when the magnitude of the loop-gain is greater than unity. Considering that the \( g_m \) is the small-signal...
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transconductance of the M1 transistor, the start-up condition can be expressed by:

\[ g_m R_T \geq 1, \] (4.30)

where for an inductor with a quality factor of \( Q_L \)

\[ R_T = \omega_o \times L \times Q_L. \] (4.31)

Equation (4.30) indicates a fundamental lower limit on the power consumption for a given transconductor and LC tank configuration. In practice, \( g_m \) is set to a value that guarantees start-up with a reasonable safety margin under worst-case conditions. Increasing \( g_m \) beyond this critical value generally contributes more parasitics (larger device) and noise and is thus undesirable.

As for the design of the VCO, the inductor \( L = 1.2112 \text{ nH} \) is chosen from the UMC 0.18 \( \mu \text{m} \) design kit with the \( Q \) ranges from 7.68 to 10.64 for frequencies of 2.4–5 GHz. Accordingly, the required capacitor for the frequency selective network to oscillate at 3110.4 MHz is:

\[ C = \frac{1}{L\omega_o^2} = 2.162 \text{ pF}. \] (4.32)

From (4.31), for \( Q_L = 8 \) the \( R_T \) is approximately 190 \( \Omega \). Therefore to satisfy the start-up conditions in (4.30), \( g_m \) should be greater than 5.3 mS. Based on this transconductance, the transistor M1 is accordingly sized with a width of 200 \( \mu \text{m} \) and biased, which in turn sets the fundamental lower limit of \( I_{SS} \). However, the \( I_{SS} \) has an impact on the PN of the VCO and therefore the \( I_{SS} \) should be optimized for the best PN. Figure 4.13 shows the simulated (using Cadence® Spectre® simulator) PN at 1 MHz frequency offset versus different values of the \( I_{SS} \) for the designed VCO.

![Figure 4.13 – Simulated PN at 1 MHz frequency offset versus different values of the \( I_{SS} \).](image-url)
As shown in Figure 4.13, the VCO achieves its best PN at an $I_{ss}$ around 2 mA. This current is used for the first design iteration. Of course an optimization is needed later when the design of the VCO is completed.

The frequency-tuning range is another issue that should be considered in the design of the VCO. In order to overcome the process and temperature variations, a typical VCO requires a 15–20% tuning range. Tuning the frequency selective network is possible by employing a variable capacitor. Towards this end, Figure 4.14 compares the behavior of all available capacitors in the CMOS 0.18 $\mu$m technology (even though the MOS capacitors are not suitable for RF design).

Figure 4.14 shows that the accumulation-mode metal-oxide-semiconductor (AMOS) RF varactor (VARMIS) provides the widest range of tuning with the minimum $k_v$ ($k_v = \Delta C/\Delta V$ i.e. varactor sensitivity). Note that high varactor sensitivity is unfavorable to PN as described by Leeson's PN formula [156]:

$$L(\Delta f, k_v) = 10 \log_{10} \left\{ \left( \frac{f_o}{2Q\Delta f} \right)^2 \left[ \frac{FkT}{2P_s} \left( 1 + \frac{f_c}{\Delta f} \right) \right] + \left( \frac{k_v v_n}{k_{LC} \Delta f} \right)^2 \right\}, \quad (4.33)$$

where $f_o$ is the frequency of oscillation, $Q$ is the quality factor, $\Delta f$ is the frequency offset from the carrier, $F$ is the noise factor of the amplifier gain element, $k$ is Boltzmann's constant, $T$ is the temperature, $P_s$ is the RF power delivered by the VCO, $f_c$ is the flicker noise corner frequency, and $k_{LC}$ is a constant that is a function of $L$ and $C$ in the resonator.

Therefore, the AMOS RF varactors are employed to continuously tune the oscillation frequency of the VCO. In order to reduce the effect of varactor sensitivity on the PN of the VCO two metal-insulator-metal (MIM) capacitors are placed in series with the varactors. Moreover,
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the AMOS varactors are tuned differentially. As explained in [156], the differential tuning rejects the common-mode noise. Reducing the up-conversion of low-frequency noises, such as flicker and shot noise, results in a better PN. To achieve the best differential tuning, all the varactors in the VCO are the same, and special attention is given to a high layout symmetry of the VCO.

Reducing the varactor sensitivity by placing the varactors in series with the MIM capacitors reduces the tuning range of the varactors and thus of the VCO eventually. Therefore, to extend the tuning range in order to compensate for the PVT variations, the VCO also features a band-switching topology that is implemented by means of a capacitor array in the VCO. Figure 4.15 shows the schematic of the implemented VCO.

![Figure 4.15 – Schematic of the differentially tuned LC-VCO.](image-url)

The VCO consists of two inductors, four AMOS varactors, MIM capacitors ($C_1$–$C_4$), and transistors M1a,b. The geometry of the transistors and the components’ values are presented in Table 4.11.

The simulated dependency of the oscillation frequency over the tuning voltage for the four possible configurations of the control bits ($S_0$ and $S_1$) is shown in Figure 4.16. It is shown that the carrier frequency of the VCO can be tuned from 2.902 GHz to 3.449 GHz. This means the VCO can achieve up to 18% tuning range, which should be enough to compensate for the process, voltage and temperature variations.
Table 4.11 – Geometry of the VCO’s transistors with its components’ values.

<table>
<thead>
<tr>
<th>Device</th>
<th>W/L μm</th>
<th>Parameter</th>
<th>Value</th>
<th>Parameter</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>M1a,b</td>
<td>200/0.18</td>
<td>C₁</td>
<td>1.411 pF</td>
<td>C&lt;sub&gt;var&lt;/sub&gt;</td>
<td>1.038 pF</td>
</tr>
<tr>
<td>M2</td>
<td>280/0.5</td>
<td>C₂</td>
<td>103 fF</td>
<td>L</td>
<td>1.2112 nH</td>
</tr>
<tr>
<td>M3</td>
<td>35/0.5</td>
<td>C₃</td>
<td>385.85 fF</td>
<td>R</td>
<td>10.52 kΩ</td>
</tr>
<tr>
<td>M4</td>
<td>50/0.18</td>
<td>C₄</td>
<td>184.2 fF</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

Figure 4.16 – Simulated oscillation frequency versus tuning of the differentially tuned VCO. The desired frequency of 3.1104 GHz is indicated by the dashed line.

Furthermore, Figure 4.16 indicates that there are three possible configurations for the control bits and tuning voltage for the VCO to attain an oscillation frequency of 3110.4 MHz. In order to find the best configuration, Figure 4.17 compares the simulated PN of the VCO at 1 MHz offset frequency from the oscillation frequencies in Figure 4.16.

Figure 4.17 shows that the best PN performance of the VCO happens at S₀, S₁ = 1, 0 and a differential tuning voltage of 218.9 mV where the VCO for the resonance frequency of 3110.4 MHz can achieve PN of -115 dBc/Hz@1 MHz. In this configuration, the oscillation frequency can be tuned from 3097 MHz to 3338 MHz, which accordingly results in a VCO conversion gain, k<sub>VCO</sub>, of 121 MHz/V. For this configuration, the PN of the VCO is simulated and is shown in Figure 4.18.

### 4.3.3.2 PLL

A reference frequency of 51.84 MHz is chosen for this design which requires a divider by N = 60 for the PLL to deliver 3110.4 MHz. Most of the required sub-systems of the PLL in Figure 4.11 are implemented differentially to gain better immunity to supply and substrate noise. The
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4.3.3.3 Phase frequency detector

The logic diagram of the PFD is shown in Figure 4.19. Note that since the D-flip-flop input is always at the constant logic high, a simplified D-flip-flop implementation is used [157]. To minimize the dead zone of the PFD, extra care is taken to ensure the reset path is sufficiently long. The output of the PFD directly drives the charge pump.
4.3.3.4 Charge pump

There is a trade-off between the PLL’s PN and the die area of the loop filter’s capacitor to choose the charge pump (CP) current. In fact, the higher CP current results in a higher PN but in return the loop filter requires a smaller capacitor. Since the main focus of this design is on the PN for a reasonable size of capacitor around 10 pF, 100 μA is chosen as the CP current.

The core of the differential CP circuit is implemented as shown in Figure 4.20. In order to minimize the CP dead zone and speed up its operation sufficiently for the input reference of 51.84 MHz, four current steering switches are employed.

The differential implementation of the CP requires a CMFB amplifier. The CMFB amplifier and the bias circuit of the CP are shown in Figure 4.21 (a) and (b) respectively. The CMFB circuit generates vcmfb and vcasp. These two signals set the CM value of the CP to half the supply voltage. Moreover, vcasp, which is the result of the replica bias (M13, M16 and M18) and the op-amp feedback circuit in the CMFB amplifier, actively balances the CP current source to alleviate the positive-negative CP current mismatch [158]. The geometry of the transistors of the CP and its CMFB and bias circuit are noted in Table 4.12. Overall, the CP and its bias and CMFB circuit consume 520 μA from 1.8 V.

4.3.3.5 Loop filter

Due to the nature of the CP, which consists of switches and current sources, its output current contains high frequency noise. Therefore a low-pass filter is required to convert the CP’s output current into the VCO’s control voltage. A standard passive loop filter configuration for a type II current mode charge pump PLL is shown in Figure 4.22.
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Figure 4.20 – Schematic of the PLL’s differential charge pump. The geometry of the transistors is noted in Table 4.12.

Figure 4.21 – Schematic of (a) the CMFB amplifier and (b) the bias circuit of the charge pump in Figure 4.20. The geometry of the transistors is noted in Table 4.12.

The shunt capacitor $C_2$ is recommended to avoid discrete voltage steps at the control port of the VCO due to the instantaneous changes in the charge pump current output. A low-pass filter section may be needed for some high-performance synthesizer applications that require additional rejection of the reference sidebands, known as spurs.
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Table 4.12 – Geometry of the transistors in the charge pump, its CMFB amplifier and its bias circuit in Figure 4.20 and Figure 4.21.

<table>
<thead>
<tr>
<th>Device</th>
<th>$W/L$ $\mu$m</th>
<th>Device</th>
<th>$W/L$ $\mu$m</th>
<th>Device</th>
<th>$W/L$ $\mu$m</th>
</tr>
</thead>
<tbody>
<tr>
<td>M1a,b</td>
<td>20/0.3</td>
<td>M10a,b,c,d</td>
<td>6/0.18</td>
<td>M19a,b,c</td>
<td>1/1</td>
</tr>
<tr>
<td>M2a,b</td>
<td>8/0.24</td>
<td>M11a,b</td>
<td>20/0.3</td>
<td>M20</td>
<td>4/1</td>
</tr>
<tr>
<td>M3a,b</td>
<td>2/0.24</td>
<td>M12a,b</td>
<td>8/0.24</td>
<td>M21</td>
<td>20/2</td>
</tr>
<tr>
<td>M4a,b</td>
<td>2.4/1</td>
<td>M13</td>
<td>4/1</td>
<td>M22</td>
<td>8/1.1</td>
</tr>
<tr>
<td>M5a,b,c,d</td>
<td>4/0.18</td>
<td>M14a,b,c,d</td>
<td>2/0.24</td>
<td>M23</td>
<td>20/0.24</td>
</tr>
<tr>
<td>M6a,b</td>
<td>8/0.24</td>
<td>M15a,b</td>
<td>2/0.24</td>
<td>M24</td>
<td>20/2</td>
</tr>
<tr>
<td>M7a,b</td>
<td>2.4/1</td>
<td>M16</td>
<td>2/0.24</td>
<td>M25</td>
<td>4/2</td>
</tr>
<tr>
<td>M8a,b</td>
<td>4/1</td>
<td>M17a,b</td>
<td>2.4/1</td>
<td>M26a,b,c</td>
<td>8/0.24</td>
</tr>
<tr>
<td>M9a,b</td>
<td>20/0.24</td>
<td>M18</td>
<td>2.4/1</td>
<td>M27a,b,c</td>
<td>2.4/1</td>
</tr>
</tbody>
</table>

Figure 4.22 – The standard passive loop filter configuration for a type II current mode charge pump PLL.

To define the components’ values of the loop filter in Figure 4.22, one method is to look at the open-loop gain-bandwidth ($\omega_p$) and phase margin ($\phi_p$) of the PLL loop. In order to do that, the linearized model of the PLL, shown in Figure 4.23, should be employed.

Figure 4.23 – PLL linear model.

The PLL model in Figure 4.23 is a simple negative feedback system. For a given $N$, CP ($K_{\phi}$), and a VCO ($K_{VCO}$), $Z(s)$ can be derived from $\omega_p$ and $\phi_p$ to ensure the stability of the feedback loop. Usually $\omega_p$ is chosen to minimize the PN of the PLL and its optimal value is where the...
high-pass VCO noise contribution is equal to the total low-pass noise contribution from the reference, PFD and CP. However, for the sake of the loop stability, \( \omega_p \) should be less than one tenth of the reference frequency. The phase margin (\( \phi_p \)) is usually chosen between 30° and 70°. A higher \( \phi_p \) results in a higher stability in return; however, the loop response time is slower.

The impedance of the loop filter in Figure 4.22 is:

\[
Z(s) = \frac{sC_1R_1 + 1}{s^2C_1R_1C_2 + sC_1 + sC_2}.
\] (4.34)

From (4.34) the loop gain of the PLL in Figure 4.23 can be written as:

\[
H(s) \bigg|_{s=j\omega} = \frac{-K_\phi K_{VCO}(1 + j\omega T_2) T_1}{\omega^2 C_2(1 + j\omega T_1) T_2},
\] (4.35)

where \( T_1 \) and \( T_2 \) are defined as:

\[
T_1 = R_1 \frac{C_1 C_2}{C_1 + C_2},
\] (4.36)

\[
T_2 = R_1 C_1.
\] (4.37)

For the loop gain in (4.35) the phase margin, as a function of \( \omega \) can be written as:

\[
\phi(\omega) = 180^\circ + \tan^{-1}(\omega T_2) - \tan^{-1}(\omega T_1).
\] (4.38)

By setting the derivative of (4.38) equal to zero, the loop bandwidth will be obtained as a function of \( T_1 \) and \( T_2 \):

\[
\omega_p = \frac{1}{\sqrt{T_1 T_2}}.
\] (4.39)

Based on the definition of the phase margin from (4.35), at \( \omega_p \) we have:

\[
|H(s)| \bigg|_{s=j\omega_p} = 1.
\] (4.40)

From (4.36)–(4.40), \( T_1 \) and \( T_2 \) can then be obtained as:

\[
T_1 = \frac{\sec(\phi_p) - \tan(\phi_p)}{\omega_p},
\] (4.41)

\[
T_2 = \frac{1}{\omega_p^2 T_1}.
\] (4.42)
Accordingly, \( R_1, C_1, C_2 \) can be written as:

\[
C_2 = \frac{T_1 K_V K_{VCO}}{T_2 \omega_p^2 N} \sqrt{1 + (\omega_p T_2)^2} \frac{1}{1 + (\omega_p T_1)^2},
\]

\[ (4.43) \]

\[
C_1 = C_2 \left( \frac{T_2}{T_1} - 1 \right),
\]

\[ (4.44) \]

\[
R_1 = \frac{T_2}{C_1}.
\]

\[ (4.45) \]

For the design of the loop filter, a phase margin of 45° is chosen, which is a good trade-off between stability and speed. On the other hand, the loop bandwidth is chosen as 1.5 MHz to filter out the VCO PN below this frequency. Thus from (4.41)–(4.45) the values of the components are obtained. However, these values are the result of the continuous-time approximation in order to linearize the PLL model, and thus have been used as the first guess in the design of the loop filter. Figure 4.24 shows the schematic of the differential implemented loop filter. The components’ values have been optimized in the simulator and are noted in Table 4.13.

![Figure 4.24 – Schematic of the differential loop filter. The components’ values are noted in Table 4.13.](image)

**Table 4.13 – Component values of the loop filter in Figure 4.24.**

<table>
<thead>
<tr>
<th>Parameter</th>
<th>( C_1 )</th>
<th>( C_2 )</th>
<th>( R_1 )</th>
</tr>
</thead>
<tbody>
<tr>
<td>Value</td>
<td>11.44 pF</td>
<td>1.71 pF</td>
<td>95.39 kΩ</td>
</tr>
</tbody>
</table>

Transistors M1a,b and M2a,b are sized 2/0.5 and 1/1 (\( W/L \ \mu m/\mu m \)) and have been used to set the initial charge for the capacitors. Figure 4.25 shows the simulated loop gain and phase margin of the PLL based on the loop filter in Figure 4.24.

### 4.3.3.6 Prescaler

As shown in Figure 4.11, a prescaler is needed to reduce the high-frequency VCO output to a lower frequency signal by integer division of \( N = 60 \). This is achieved by combinations of two cascaded divide-by-2, followed by a cascade of a divide-by-3 and a divide-by-5, respectively. Note that the first divide-by-2 operates at the highest frequency within the PLL and should
provide the 25% duty-cycle clock at half the VCO frequency. Therefore, the 25% duty-cycle divide-by-2 presented in section 4.3.2.2 is employed as the first divide-by-2 in the prescaler. The second divide-by-2, however, operates at half the VCO frequency and there is no restriction on the duty cycle of its output. Therefore, in order to reduce the power consumption, this divide-by-2 is realized using toggling D-flip-flops based on the master-slave structure of the differential high-speed common-source latch [159]. The schematic of the implemented high-speed CML latch and the divide-by-2 based on it are shown in Figure 4.26 (a) and (b), respectively. The geometry of the transistors in the latch is noted in Table 4.14. The clock

Figure 4.26 – Flip-flop-based divide-by-2 topology: (a) Schematic of the high-speed CML D-latch, and (b) high level schematic of the divide-by-2 employing the D-latch on the left. The geometry of the transistors is noted in Table 4.14.
Chapter 4. Multi-constellation L1/E1/B1 receiver

Table 4.14 – Geometry of the transistors in the flip-flop-based divide-by-2 in Figure 4.26.

<table>
<thead>
<tr>
<th>Device</th>
<th>M1a,b</th>
<th>M2a,b</th>
<th>M3a,b</th>
<th>M4a,b</th>
</tr>
</thead>
<tbody>
<tr>
<td>W/L μm</td>
<td>10/0.18</td>
<td>10/0.18</td>
<td>20/0.18</td>
<td>40/0.4</td>
</tr>
</tbody>
</table>

signal, clk, determines the track and latch modes of the high-speed CML D-latch in Figure 4.26 (a). When the clk is HIGH, the circuit operates in the tracking mode, in which the current from M4b flows entirely into the tracking circuit, M1a and b, whereby the output (Q) tracks the input (D). On the other hand, when the clk is LOW, the tracking stage is disabled, whereas the latch pair is enabled storing the logic state at the output.

Since the operating frequency of the two last dividers (divider-by-3 and divider-by-5) is relatively low, they have been implemented using simple CMOS logic flip-flops as synchronous counters. Figure 4.27 and Figure 4.28 show a conventional divide-by-3 and -5 respectively.

![Figure 4.27](image-url)  
Figure 4.27 – Synchronous counters for the conventional divide-by-3.

![Figure 4.28](image-url)  
Figure 4.28 – Synchronous counters for the conventional divide-by-5.
4.3. Subsystems design

4.3.4 Active IF filter

The same filter presented in section 3.3 is used in this front-end. However, since the current-driven passive mixer in the front-end requires a current-input filter as its load, the filter of section 3.3 is slightly modified. The modification is only at the input stage of the filter. In fact, the first Gm cell which was performing a voltage-to-current conversion is removed, as is shown in Figure 4.29. As a matter of fact, the first Gm cell was not required in the LC-ladder network and was only added to provide a voltage-input filter for the PRS receiver in section 2 (see Figure 3.23). Therefore, removing the first Gm cell from the filter's architecture does not alter the filter's transfer function but, thanks to the topological linearity improvement method in section 3.3.5, a better linearity is expected.

![Figure 4.29 – Block diagram of the 4th-order elliptic Gm-C low-pass filter with dual input OTAs (Gm cells). The Gm cells are identical and the capacitors' values are shown in Table 3.3. The Gm cell highlighted in red is removed to have a current input filter.](image)

The phase and group delay of the filter are measured for the cut-off frequencies of 8 MHz and 23 MHz. The measure embeds the contribution of the on-chip op-amps and the on-board buffers, but thanks to their wideband response, their contributions are negligible. The group delays of the filter when its bandwidth is set to 8 MHz (NB mode) and 23 MHz (WB mode) are shown in Figure 4.30 and Figure 4.31, respectively. It is flat for the NB mode around 65 ns from 1 MHz to 5 MHz and then increases as the frequency approaches the cut-off. For the WB mode, the group delay is around 30 ns from 1 MHz to 17 MHz followed by an increase when approaching 23 MHz.

The average phase linearity is shown in Figure 4.32 and Figure 4.33 and is 6°/6.5° for NB/WB, when considering the frequency band from 300 KHz to the respective cut-off frequency in each case. These values are well below the maximum error defined in Table 4.6 (i.e. 8.8°).
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Figure 4.30 – Measured filter’s group delay when it is set to 8 MHz of bandwidth.

Figure 4.31 – Measured filter’s group delay when it is set to 23 MHz of bandwidth.

4.3.5 Variable-gain amplifiers

A high dynamic range VGA comes after the IF filter in each I and Q branch of the front-end to amplify the signal to a detectable level for the ADC regardless of the received signal strength to achieve an optimum SNR. Moreover, the VGA is also required to compensate for process, voltage and temperature variations. Additionally, the baseband processor can adjust the gain of the front-end when it detects any interference to avoid saturation in the VGAs or ADCs. As is shown in the block diagram in Figure 4.34, the VGA is composed of two AC-coupled programmable gain stages.

Each programmable gain stage consists of a differential amplifier and a switched resistor
4.3. Subsystems design

Figure 4.32 – Measured phase of the filter when it is set to 8 MHz of bandwidth. The average non-linear phase error is 6°.

Figure 4.33 – Measured phase of the filter when it is set to 23 MHz of bandwidth. The average non-linear phase error is 6.5°.

network that can be configured to deliver four different voltage gains by means of two control bits. Both programmable gain stages adopt an identical differential amplifier; however, their switched resistor networks are configured differently to minimize the required resistance for the design. The schematic of the differential amplifier and its CMFB amplifier and biasing circuit are shown in Figure 4.35 and Figure 4.36, respectively. The geometry and operating point of the amplifier’s transistors can be found in Table 4.15.

The VGA consumes 1.37 mA from 1.8 V and is capable of providing 19.4–41.6 dB gain with control steps of 1.25 dB. Table 4.16 shows the VGA’s control bits and their simulated respective...
gain. Note that B0–B1 and B2–B3 pairs of bits control the first and second programmable gain stage, respectively.

The programmable gain stages are AC-coupled to overcome the offset problem which in return show a high-pass frequency response at low frequency with a cut-off frequency of less than 2 MHz. Figure 4.37 shows the simulated frequency response of the VGA for all 16 different gain steps.

### 4.3.6 Analog-to-digital converter

As for the ADC of the front-end, to reduce the design effort, the same ADC presented in section 2.4.1 is reused for this front-end.
4.4 Measurement results

This section presents the measurement results of the front-end. The front-end was characterized in analog domain. The results related to the ADC are presented in section 2.4.1.6. The
Figure 4.37 – Simulated frequency response of the VGA for all 16 different gain steps.

The frequency synthesizer was integrated on a separate die from the front-end thus was packaged and characterized separately.

### 4.4.1 Frequency synthesizer

A micro photograph of the FS is shown in Figure 4.38. It occupies an active area of $670 \times 880 \ \mu$m$^2$. It was packaged within a LQFP64 and mounted on a testing printed circuit board (PCB) as shown in Figure 4.39.

Figure 4.38 – Micro photograph of the frequency synthesizer.

The VCO consumes 2.12 mA of a 1.8 V supply while providing an oscillation tuning range of 2621–3107 MHz. For test purposes, each VCO’s output signal was connected to an open-drain circuit with an external resistance of 150 Ω and 10 nH inductor. The buffered VCO’s
4.4. Measurement results

Figure 4.39 – Photograph of the characterization PCB for the frequency synthesizer.

differential output was converted to a single-ended by means of an RF balun [160] in order to measure it with an spectrum analyzer. In this case, the VCO provide a maximum output power of -16.9 dBm. Since the Q of the external inductor decreases with decreasing the oscillation frequency, the VCO’s output power thus slightly decreases at lower oscillation frequency. The measured dependency of the oscillation frequency over the tuning voltage for the four possible configurations of the control bits ($S_0$ and $S_1$) is shown in Figure 4.40.

The VCO can achieve up to 16.9% tuning range of which 14.6% is achieved within the voltage tuning of -1 V to 1 V. However, due to the parasitic capacitance, the oscillation frequency is lower than the one expected from the simulation by 10.4%. For the same reason, the overall tuning range is also less than expected by 24%. Accordingly, the VCO exhibits a $k_{vco}$ of 62.3 MHz/V and 93.5 MHz/V for voltage tuning range of [-1 V, 1 V] and [-1.8 V, 1.8 V], respectively. Unfortunately, the VCO cannot provide the required frequency (3110.4 MHz) for the front-end, and therefore, the front-end was characterized by an external LO.

Figure 4.40 – Measured oscillation frequency versus tuning of the differentially tuned VCO.
A signal generator was used as the reference for all closed-loop measurements. The measured output range of the synthesizer ranges from 2625 MHz to 3102 MHz if varying the input reference frequencies. The PN of the frequency synthesizer was measured using a 26.5 GHz Agilent N9010A spectrum analyzer with a PN module. For a given reference clock of 50 MHz, Figure 4.41 illustrates the measured PN of the frequency synthesizer at the oscillation frequency of 3000 MHz in $S_0S_1 = 0, 0$ configuration (divider provides the fix division of 60). A PN of -80.3 dBc/Hz and -87.6 dBc/Hz is measured at 10 kHz and 1 MHz offset from the carrier frequency, respectively. Considering that the synthesizer provide twice the required LO for the FE, the overall PN improves by 6 dB. This satisfies the PN requirement of the FE (see Table 4.5) at 10 kHz but not at 1 MHz. However, the averaged phase noise of 80 dBc/Hz only results in less than 0.1 dB of loss in $C/N_0$ [45].

![Figure 4.41 – Measured PN of the frequency synthesizer at 3000 MHz. The reference clock is 50 MHz and the PLL is configured with $S_0S_1 = 0, 0$.](image)

The buffered output in a close-in spectrum for an oscillation frequency of 3 GHz and a PLL configuration of $S_0S_1 = 0, 0$ is shown in Figure 4.42. The measured spurs are approximately 42 dB below the carrier.

The PN performance of the synthesizer is further characterized for different oscillation frequencies at 10 kHz and 1 MHz offset in the four configurations of $S_0$ and $S_1$. The results are shown in Figure 4.43. To further investigate the PN performance in Figure 4.43, it is necessary to pay attention that the loop filter in the PLL behaves as a low-pass filter for the noise of the PLL circuitries and as a high-pass filter for the PN of the VCO. The PN at 1 MHz is mainly dominated by the PN of the VCO while at 10 kHz, noise contribution of the PLL circuitries play an important role on the synthesizer’s PN.

In each configuration, at 1 MHz offset, the synthesizer’s PN improves by moving away from the middle of the tuning range. This is because, the VCO sensitivity is high at the middle of the tuning range, which results in a higher PN for the VCO. On the other hand, near the
4.4. Measurement results

Figure 4.42 – Measured output spectrum of the frequency synthesizer for oscillation frequency at 3000 MHz. The reference clock is 50 MHz and the PLL is configured with $S_0S_1 = 0, 0$. The measured spurs are approximately 42 dB below the carrier.

$S_0S_1 = 0,0 @ 10$ kHz  
$S_0S_1 = 0,1 @ 10$ kHz  
$S_0S_1 = 1,0 @ 10$ kHz  
$S_0S_1 = 1,1 @ 10$ kHz  

Figure 4.43 – Measured PN performance of the frequency synthesizer versus operating frequency at 10 kHz and 1 MHz frequency offset.

edges of the tuning range the VCO sensitivity is minimal thus the PN of the VCO is lower.

At 10 kHz offset, PLL circuitries especially the CP, play an important role on the PN. The CP in Figure 4.20 is designed differentially to suppress the supply noise. However, to tune the VCO near the edges of the tuning range, the CP should provide a large output differential voltage around $\pm VDD$. In this case, the CP requires that its output nodes of ioN and ioP (see
Figure 4.20) to be biased near the rail voltage of VDD or GND. In this case the CP is less linear thus its noise is higher. Moreover, this disturbs the balanced configuration of the differential CP and as a result the CP cannot perfectly reject the supply noise. This is the reason that the PN at 10 kHz offset is higher around the edges of the tuning range compared to the PN in the middle of the tuning range. Therefore, in order to have a lower in-band PN, the FS tuning range should be restricted to 2640–3070 MHz, which is equivalent of differential tuning voltage of [-1 V, 1 V].

The measured current consumption of the PLL over frequency range of 2640–3070 MHz is shown in Figure 4.44. The current consumption increase from 7.67 mA linearly to 8.95 mA with respect to the oscillation frequency.

![Figure 4.44 – Measured current consumption of the PLL (frequency synthesizer without the VCO), from a 1.8 V supply, versus operating frequency.](image)

4.4.2 Front-end die and packaging

The front-end was integrated using UMC 0.18 μm CMOS technology and occupies 1 × 2.6 mm² of silicon area. A micro photograph of the ASIC FE including the pad rings is shown in Figure 4.45. In order to be able to test the FE, it was encapsulated within a LQFP64 package.

4.4.3 Measurement setup

The packaged ASIC was assembled on a PCB to allow for detailed measurements. A photograph and the schematic and of the PCB are shown in Figure 4.47 and Figure 4.46, respectively. Note that all the outputs are differential; however, for the sake of simplicity, the circuits are shown as single-ended architecture in Figure 4.47.

The frequency synthesizer was integrated on a separate die and was characterized inde-
Figure 4.45 – Micro photograph of the front-end ASIC implemented on UMC 0.18 μm CMOS. The front-end including and excluding the pad rings occupies 1.525×3.24 mm² and 1×2.6 mm², respectively.

Independent in section 4.4.1. All the characterizations of the FE that are presented in this section were acquired with an external LO driving the 25% duty-cycle divider in section 4.3.2.2.

The in-phase and quadrature outputs are not directly taken from the ASIC but buffered through AD8351 differential-to-single converters [79] to allow the use of 50 Ω loads. Their nominal 3 dB bandwidth is 3 GHz with reported 0.1 dB flatness up to 600 MHz so their effect on the general frequency response is negligible. Moreover, internal buffers are used to interface the input capacitance of these amplifiers, which also have a negligible influence on the FE’s frequency response.

Figure 4.46 – Photograph of the characterization PCB.
Figure 4.47 – Schematic of the characterization PCB. All the outputs of the front-end are differential.

### 4.4.4 LNA input matching

The first necessary step for characterization is the matching of the RF input. Internal or integrated matching is avoided in this project because it would be necessary to characterize the package and bonding process alone for optimal results, and because the design of the RF section would have been conditioned by the die location within the package. Therefore an external matching network was considered by means of a series capacitor and inductor. The values of the capacitor and inductor are noted in Table 4.9. Figure 4.48 shows the measured return loss of the LNA after matching. The LNA consumes 4.3 mA of a 1.8 V supply. As is shown in Figure 4.48, the LNA achieves a return loss of less than -10 dB for the bands of interest. To avoid the pad parasitic capacitance at the output of the LNA, its output is not taken out to any pad, thus the gain of the LNA cannot be measured independently. For the same reason, its NF also cannot be measured. However, the total NF of the FE is measured and reported in section 4.4.8.

### 4.4.5 Frequency response

The transfer function of the front-end was verified in analog domain by means of a constant-power single-tone sweep around the downconversion frequency of 1555.2 MHz at both the I and Q channel. The single-tone sweep is generated by a signal generator entering the RF input (see Figure 4.47), and the IF power after the VGA for both the I and Q channel was measured
4.4. Measurement results

Figure 4.48 – Measured S11 of the LNA after matching.

by a spectrum analyzer. Figure 4.49 compares the transfer function of the FE’s I and Q channel at the minimum gain of the FE. The IF bandwidth is set to 23 MHz. The results show a very good matching between the response of the I and Q channel with the band flatness within ±1 dB, demonstrating the good integration of the reconfigurable filters inside the full chain.

Figure 4.49 – Comparison between front-end’s I and Q channel measured response. The front-end bandwidth is set to 23 MHz. The IF bands of B1 and L1 are highlighted at the left and right, respectively.

In order to see the wider channel response, the bandwidth of the FE was set to 25 MHz and the output spectrum of the I channel is shown in Figure 4.50. It is clear that the in-band response of the front-end is similar to the response of the stand-alone filter (see section 3.3.2). Note that the notch in the stop-band is not visible due to the high noise floor (because of
relatively high-resolution bandwidth of the spectrum analyzer) and the hold max option of
the spectrum analyzer. To reduce the noise floor of the system the resolution bandwidth of
the spectrum analyzer was reduced and the result is shown in Figure 4.51 for the front-end
bandwidth of 12 MHz. By reducing the noise floor, the notch of the filter in its stop-band is
clearly visible.

![Figure 4.50](image1)

Figure 4.50 – Measured output spectrum of the front-end. The front-end bandwidth is set to
25 MHz. The IF bands of B1 and L1 are highlighted at the left and right, respectively.

![Figure 4.51](image2)

Figure 4.51 – Measured output spectrum of the front-end. The front-end bandwidth is set to
12 MHz. The IF bands of B1 and L1 are highlighted at the left and right, respectively. The notch
of the filter is clear at its stop-band.

The reconfigurable filter enables the front-end to receive only B1 or both B1 and L1/E1
bands by setting its cut-off frequency to 8 MHz (NB mode) and 23 MHz (WB mode), re-
4.4. Measurement results

respectively. Figure 4.52 and Figure 4.53 demonstrate this functionality of the front-end. A BPSK(1) signal, generated by the signal generator at the B1 band (centered at 1561.098 MHz), is downconverted to its IF for both FE’s NB and WB mode of operations. Figure 4.52 shows the spectrum of these signals along with the frequency response of the FE in its both operating modes. Although the nominal received power of a GNSS signal is below the noise power, the input power was increased in order to have a clear spectrum in the IF.

![Figure 4.52](image_url)

**Figure 4.52** – Measured downconverted spectrum of a BPSK(1) signal transmitted at 1561.098 MHz. B1-NB is the measured spectrum of the BPSK(1) signal when the FE is in NB mode while B1-WB is the same signal received in the WB mode of the front-end. The front-end’s bandwidth is 8 MHz for the NB mode and 23 MHz for the WB mode. The frequency responses for both modes of operation are shown in the figure. The IF bands of B1 ($f_{IF,B1} = 5.898$ MHz) and L1 ($f_{IF,L1} = 20.22$ MHz) are highlighted at the left and right, respectively.

Figure 4.52 shows that the IF filter of the FE in the NB mode lets the signal pass through without attenuation up to 8 MHz. However, after this point in frequency, attenuation is obvious due to the high selectivity of the elliptic filter as compared to the signal’s spectrum in the WB mode.

Moreover, Figure 4.53 shows the FE functionality in its WB mode. The figure shows that the FE downconverts two BPSK(1) signals centered at 1561.098 MHz and 1575.42 MHz to their respective IFs. The output spectra for these signals along with the front-end frequency response are shown in Figure 4.53. The two input signals had the same power; however, the power of the signal in the L1 band is slightly lower than the one in B1 band after downconversion. This is due to the front-end frequency response as is shown in the figure.

The FE’s intermediate frequency was also inspected for any spur in the frequency spectrum. Figure 4.54 shows a BPSK(1) signal, downconverted to B1 IF, and no obvious spur is noticed in the frequency band up to 150 MHz.
Figure 4.53 – Measured downconverted spectrum of two BPSK(1) input signals centered at 1561.098 MHz and 1575.42 MHz along with the front-end’s WB mode frequency response. The IF bands of B1 \( (f_{IF,B1} = 5.898 \text{ MHz}) \) and L1 \( (f_{IF,L1} = 20.22 \text{ MHz}) \) are highlighted at the left and right, respectively.

Figure 4.54 – A BPSK(1) signal downconverted to the B1 IF at \( f_{IF,B1} = 5.898 \text{ MHz} \). No spur is noticed up to 150 MHz.

Furthermore, the front-end’s out-of-band rejection is measured by a two-tone test at 1560.2 MHz (in-band) and 1590.2 MHz (out-of-band), resulting in the IF of 5 MHz and 35 MHz, respectively. The result is shown in Figure 4.55 which indicates a rejection of over 30 dB as expected. Following this measurement, Figure 4.56 shows the out-of-band rejection of the front-end versus sweeping the input power for the same two tones (1560.2 MHz and 1590.2 MHz). The results show almost constant rejection of over 30 dB even at a high output power, which implies the high linearity of the FE.
4.4. Measurement results

Figure 4.55 – The front-end’s filter rejection: Two tone are applied at 1560.2 MHz and 1590.2 MHz resulting in the IF of 5 MHz and 35 MHz, respectively. The filter bandwidth is set to 23 MHz and the front-end gain is 39 dB. 30.7 dB of rejection is achieved at an input power of -60 dBm.

Figure 4.56 – The front-end’s filter rejection over sweeping the input power: Two tones are applied at 1560.2 MHz and 1590.2 MHz resulting in the IF of 5 MHz and 35 MHz, respectively. The filter’s bandwidth is set to 23 MHz and front-end’s gain is 39 dB. The output power at 5 and 35 MHz along with the filter rejection is plotted versus the input power. Over 30 dB of rejection is achieved even at high output power.

4.4.6 VGA gain

The VGA consists of two stages that are controllable with 4 bits. In order to verify the gain steps of the VGA, the measurements were performed by taking the output power with an input tone of -80 dBm at 1560.2 MHz to detect it clearly above the noise floor. The maximum
power level was taken as 0 dB reference, and the gain steps (effectively attenuation settings) are represented referenced to this value. The measured results are shown in Figure 4.57. Even though the results do not follow the expected trend of $1.25 \text{ dB/step}$, the gain response is monotonic with errors of about $\pm 1 \text{ dB}$ (except for two points where the error is 1.5 dB). The VGA provides 19.1 dB of variable gain. Accordingly, Figure 4.58 shows the frequency response of the front-end for five different VGA gain steps. The maximum measured gain is 58 dB.

![Figure 4.57 – Measured VGA gain steps.](image)

![Figure 4.58 – Measured frequency response of the front-end for five different VGA gain steps. The front-end bandwidth is set to 23 MHz.](image)
4.4. Measurement results

4.4.7 Quadrature matching

Given that the image rejection will be performed in the digital domain, the front-end is required to offer a good balance in its I and Q channels. In order to measure the IQ imbalance, the analog outputs of the front-end from both the I and Q channels were captured with an oscilloscope, for a single tone once at 1561.098 MHz (B1-band) and the other time at 1575.42 MHz (L1/E1-band). The results are shown in Figure 4.59 and Figure 4.60, respectively.

Accordingly, the average measured quadrature error is less than ±0.6 dB in amplitude for both the B1 and L1 bands. The average measured IQ imbalance in phase for the B1 band is ±1.1° and increases to ±4° for the L1 band. These quadrature errors will result in an IMRR of 23.1 dB and 22.2 dB for the B1 and L1 bands, respectively. Note that no compensation mechanism was implemented other than a symmetrical layout. However, these IMRRs are acceptable for GNSS signals since a 16 dB IMRR degrades the $C/N_0$ only by about 0.1 dB [45].

![Figure 4.59](image.png)

Figure 4.59 – Time domain signals at $f_{IF,B1} = 5.898$ MHz. Both the I and Q outputs are presented.

4.4.8 Noise figure

The front-end noise figure (NF) was obtained by the gain method [16] as:

$$\text{NF} = 174 \text{ dBm/Hz} + P_{n,\text{OUT}} - 10\log(B) - G,$$

(4.46)

where $B$ is the measurement bandwidth, $P_{n,\text{OUT}}$ is the noise power in the bandwidth, and $G$ is the gain of the FE. The measured noise spectrum of the front-end is shown in Figure 4.61. Both gain and noise levels change with frequency, so several points within the band were considered. The noise power within the bandwidth of 1 MHz were measured and are noted on the figure. Note that the output buffer and matching network have loss of about 17.3 dB; however, due to the high gain of the front-end, their noise contributions are negligible, and

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Figure 4.60 – Time domain signals at $f_{IF, L1} = 20.22$ MHz. Both the I and Q outputs are presented.

their effects are therefore not de-embedded in this measurement. Table 4.17 shows these results at different offsets with respect to the origin. The average front-end’s NF is 12.5 dB,

Figure 4.61 – Measured noise spectrum of the front-end. The band powers are indicated on the figure for 1 MHz bandwidth.

which, in conjunction with a RF filter with a NF of 5 dB and an active antenna with 30 dB gain and 3 dB NF will result in an overall NF of less than 3.2 dB.
4.4. Measurement results

Table 4.17 – Front-end noise figure including the output buffer and matching network.

<table>
<thead>
<tr>
<th>IF (MHz)</th>
<th>Gain (dB)</th>
<th>Noise power in 1 MHz [dBm]</th>
<th>NF (dB)</th>
</tr>
</thead>
<tbody>
<tr>
<td>6</td>
<td>40.7</td>
<td>-59.37</td>
<td>13.93</td>
</tr>
<tr>
<td>10</td>
<td>40.2</td>
<td>-61.67</td>
<td>12.13</td>
</tr>
<tr>
<td>15</td>
<td>39</td>
<td>-62.99</td>
<td>12.01</td>
</tr>
<tr>
<td>20</td>
<td>38.5</td>
<td>-63.42</td>
<td>12.08</td>
</tr>
<tr>
<td>23</td>
<td>36.7</td>
<td>-65.05</td>
<td>12.25</td>
</tr>
</tbody>
</table>

4.4.9 Linearity

The FE linearity was measured through sweeping the RF input power and recording output power of the FE at the minimum gain mode. As shown in Figure 4.62 and Figure 4.63, the IP1dB is about -25.4 dBm when receiving the GNSS signals in the B1 band, and about -27.6 dBm for the GNSS signals in the L1/E1 band. These IP1dB can effectively alleviate the continuous wave interference to guarantee the optimum output SNR.

Figure 4.62 – Measured I-P1dB for a tone at 1561.098 MHz (B1 band) at the minimum front-end’s gain.

Furthermore, the IIP3 was also measured with the same method as for the IP1dB but with the two tones 500 kHz away from the center frequency of the B1 and L1 bands (the tones have a 1 MHz frequency gap between them). The results are shown in Figure 4.64 and Figure 4.65 for the B1 and L1, respectively. As one can see in the figures, the IIP3 is about -14.2 dBm when receiving the GNSS signals in the B1 band, and about -14.9 dBm for the GNSS signals in the L1/E1 band.
Figure 4.63 – Measured $IP_{1\text{dB}}$ for a tone at 1575.42 MHz (L1/E1 band) at the minimum front-end’s gain.

Figure 4.64 – Measured IIP3 for two tones at 1560.598 MHz and 1561.598 MHz (B1 band) at the minimum front-end’s gain.

### 4.4.10 Power consumption

The front-end without the FS consumes 28.45 mA and 22.85 mA from a 1.8 V supply for its WB and NB mode, respectively. The power breakdown of each building block is presented in Table 4.18.
4.4. Measurement results

Figure 4.65 – Measured IIP3 for two tones at 1574.92 MHz and 1575.92 MHz (L1 band) at the minimum front-end’s gain.

<table>
<thead>
<tr>
<th>Building block</th>
<th>WB mode [mA]</th>
<th>NB mode [mA]</th>
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<tbody>
<tr>
<td>LNA</td>
<td>4.3</td>
<td>4.3</td>
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<tr>
<td>Mixer¹</td>
<td>2.45</td>
<td>2.45</td>
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<tr>
<td>FS</td>
<td>10</td>
<td>10</td>
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<td>BPF</td>
<td>4.7</td>
<td>2.2</td>
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<td>VGA</td>
<td>1.35</td>
<td>1.35</td>
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<tr>
<td>ADC</td>
<td>4.8</td>
<td>3.5</td>
</tr>
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</table>

¹ The mixer is passive. A 25% duty-cycle divide-by-2 consumes the power.

4.4.11 Performance comparison

Table 4.19 summarizes the performance of the presented GNSS FE and a comparison with the state-of-the-arts. As can be seen, the FE achieved the largest IF-BW compared to the state-of-the-art FEs with the bandwidth extending from 8 MHz to 23 MHz. It also achieved a better linearity than most of the previous studies with IP1dB and IIP3 of -26 dBm and -14.2 dBm, respectively. In the NB mode, its power consumption is comparable with the other FEs while in the WB mode it consumes a little more than other studies. This is partially because of the highly linear and selective wide-band low-pass filter that consumes more power to provide these characteristics. Additionally, the FE features the 6-bit flash ADCs that, compared to the 2- to 4-bit ADC resolution of the previous works, requires more power. Moreover, employing an inductorless LNA helped to achieve a very compact FE that only occupies 2.6 mm. Given the size of the FS is mainly determined by the LC-VCO which in our design occupies 0.63 mm²,
### Chapter 4. Multi-constellation L1/E1/B1 receiver

Table 4.19 – Performance summary and comparison to the state-of-the-art.

<table>
<thead>
<tr>
<th>References</th>
<th>This work</th>
<th>[28]</th>
<th>[29]</th>
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<th>[2]</th>
<th>[31]</th>
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<tr>
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<td>E1/E5a</td>
<td>E1/E5a</td>
<td>E1/UMTS</td>
<td>E1/E5</td>
<td>E1/E5b</td>
<td>LI/E1bc</td>
<td>B1/Glonass L1</td>
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<td>All-LNA</td>
<td>LNA</td>
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<td>RF section</td>
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<td>Low-IF</td>
<td>Low-IF</td>
<td>Zero-IF</td>
<td>Low-IF</td>
<td>Low-IF/Zero-IF</td>
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<td>Low-IF</td>
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<td>IF-BW (MHz)</td>
<td>8/23</td>
<td>9</td>
<td>4.5/3/24</td>
<td>2.5</td>
<td>2/4/20</td>
<td>2.2-18</td>
<td>2.2–10</td>
<td>2-20</td>
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<td>IF freq. (MHz)</td>
<td>5.898/20.22</td>
<td>5.67/3.2</td>
<td>4/12</td>
<td>-</td>
<td>6.4/16</td>
<td>19.23</td>
<td>3.996/13.29</td>
<td>15.9/15.48/12.24</td>
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<td>-</td>
<td>2.2/2.3</td>
<td>-</td>
<td>2.7/2.5</td>
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<td>-</td>
<td>110</td>
<td>110</td>
<td>112/115</td>
<td>107</td>
<td>125</td>
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<td>ΔG [dB]</td>
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<td>50</td>
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<td>IP3 in-band [dBm]</td>
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<td>-</td>
<td>-35</td>
<td>-</td>
<td>-50</td>
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<td>-</td>
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<tr>
<td>Image rej. [dB]</td>
<td>-</td>
<td>-</td>
<td>30</td>
<td>-</td>
<td>28/23</td>
<td>50</td>
<td>45</td>
<td>49</td>
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<td>OL PN [dBc/Hz] @1 MHz</td>
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<td>-114/-119</td>
<td>-110/-116</td>
<td>-</td>
<td>-122</td>
<td>-118</td>
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<td>-</td>
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<td>130</td>
<td>180</td>
<td>65</td>
<td>180</td>
<td>55</td>
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<td>11.4</td>
<td>-</td>
<td>7.2</td>
<td>10.5</td>
<td>7.2</td>
<td>8.4</td>
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<td>26 (E1/E5)</td>
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<td>45/ch</td>
<td>44/ch</td>
<td>41.4</td>
<td>36.24/ch</td>
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</table>

1 One channel switchable, 2 Extrapolated by I-P1d = -61 dBm, 3 IF frequency varies depending on which two constellations are chosen, 4 With off-chip SAW, 5 With an active antenna with 30 dB gain and 3 dB NF, 6 The PN of the VCO, 7 Without FS.

The overall FE including the FS will occupy less than half of the smallest FE of the previous works.

### 4.5 Conclusions

A reconfigurable single-channel multi-band RF front-end for Beidou/Galileo/GPS is implemented in 0.18 µm CMOS with an active die area of 2.6 mm². Thanks to the reconfigurable LPF, the front-end has two modes of operation: narrow-band (NB) and wide-band (WB). In the NB mode, it has an IF bandwidth of 8 MHz and receives the Beidou B1-I, while in the WB mode it can accommodate the simultaneous reception of Galileo-E1 and GPS-L1 as well as Beidou B1-I in its 23 MHz IF bandwidth.

Consuming 22.85/28.45 mA current in NB/WB mode from a 1.8 V supply, this front-end provides a maximum voltage gain of 58 dB, a gain dynamic range of 19.1 dB and an IMRR of 22.2 dB. The front-end exhibits a very good linearity for GNSS receivers with a IP1dB better than -27.6 dBm. This along with the 6-bit ADCs allows the baseband processor to implement an interference mitigation algorithm to withstand strong interferers and improve the robustness of the receiver. In conjunction with an active antenna with a 30 dB gain, this front-end can achieve a NF of less than 3 dB.
5 Conclusions and perspectives

5.1 Achievements

Two multi-band GNSS IC FEs are the main outcomes of this thesis. One FE addresses the PRS and is capable of receiving Galileo-E1 and E6 signals simultaneously, to serve authorized governmental bodies, while the other FE can accommodate the simultaneous reception of the GPS-L1, Galileo-E1 and Beidou-B1 OS signals to respond to the mass market demands of the multi-frequency multi-constellation GNSS receivers.

To the best of our knowledge, the presented FE in chapter 2 is the first documented multi-band PRS IC FE. To start, the system specifications were derived for the FE and its sub-systems and were laid out in chapter 2. A fundamental quality of the PRS is its robustness against jamming and spoofing. Accordingly, all the sub-systems were designed and fabricated on a single chip using 0.18 μm CMOS. The presented dual-frequency FE incorporates two fully independent wide-band FEs consisting of the LNA, quadrature mixer, FS, IF filter, VGA and ADC and, all told, occupies a die area of 11.5 mm². The FE’s frequency band coverage is limited only by the tuning range of the VCO, thanks to the wide-band design of all the sub-systems. As a consequence, the FE not only covers the desired E1 and E6 bands but also provides partial coverage of L5/E5 with the E6 channel while consuming 64 mA from a 1.8 V. It has a maximum gain of 65 dB with a dynamic range of 30 dB.

One of the characteristics of the Galileo signals is their wide bandwidth that can reach up to 51 MHz for some applications (E5). A challenge for this design was that the LPF is the limiting factor of the FE’s bandwidth. This challenge was overcome by the proposed reconfigurable wide-tuning-range LPF. As a result, the FE exhibits 50 MHz of bandwidth, which is more than twice the largest IF bandwidth of the FEs reported in the state-of-the-art (24 MHz in [29]). The integrated filter in the FE is a power-efficient 4th-order Gm-C elliptic filter with an almost two-octave continuous tuning of its cutoff frequency. The wide continuous tuning was achieved by combining a new Gm tuning circuit with the Gm switching techniques, with which the filter can accommodate any of the new wide-band modernized GNSS signals. With the proposed tuning scheme, the power efficiency was achieved by scaling down the
filter’s power consumption proportionally to its cutoff frequency, which is of value in a design reuse approach. A Q enhancement method was also incorporated in the filter, resulting in a high selectivity of up to 66 dB/octave, which is of value for PRS applications to mitigate out-of-band interferers. The filter achieves a high linearity over its tuning range with an IIP3 of up to -1.3 dBVRMS thanks to the topological linearity enhancement method. The FE also features a 6-bit ADC with a sampling frequency of 52 MS/s (the state-of-the-art is 4 bits for IC receivers). The high resolution of the ADC enables the baseband processor to implement mitigation algorithms to improve the receiver’s immunity to jamming signals and interferences.

The FE is fully configurable through external tuning of passive components and a complete serial interface. Overall, this FE offers a compact, low-power, wide-band solution for high-precision dual-frequency GNSS receivers, not only for the PRS or military GPS, but also for many open service signals.

The specifications of the FE presented in chapter 4 were derived while having in mind that the FE aims at mass market applications which demand low power consumption and low costs. In order to reduce the design efforts, the FE utilizes the same ADC and LPF of the PRS receiver. The FE features two modes of operation: wide-band (WB) and narrow-band (NB). In the NB mode, the FE receives the Beidou-B1 signal, whereas in the WB mode, it simultaneously receives the GPS-L1, Galileo-E1 and Beidou-B1 signal. In line with the low-cost solution, a wide-band inductorless LNA was employed in the FE which results in reducing the silicon area.

The FE also features a quadrature passive mixer that, in conjunction with the LPF, delivers an RF band-limited impedance response at the LNA’s output. This helps to improve the LNA linearity by presenting a low out-of-band impedance at the LNA, which in turn minimizes any voltage swing that is generated by unwanted interferers. In order to reduce the power consumption, no complex filtering was adopted, and thus image rejection will be performed in the digital domain. The FE shows a gain dynamic range of 19.1 dB to compensate for the PVT variations. At this stage, the FE uses an external LO and occupies an active die area of only 2.6 mm² while consuming 22.85/28.45 mA current in NB/WB mode from a 1.8 V supply. It demonstrates a very good linearity with IP1dB of more than -27.6 dBm.

A FS that has an oscillation tuning range from 2625 MHz to 3102 MHz was designed and fabricated separately from the FE. It consists of an LC-VCO and an integer-N PLL with a fixed division of 60. The oscillation range is 10.4% less than expected, and therefore it needs a design tuning for the final integration into the FE. This is mainly due to the capacitance parasitic, which should be considered in the next integration. A PN of -80.3 dBc/Hz is measured at 10 kHz offset from the carrier frequency of 3 GHz. Considering that the synthesizer provide twice the required LO for the FE, the overall PN improves by 6 dB which means that the FS satisfies the PN requirement of the FE at 10 kHz offset. The FS including the VCO consumes from 9.8 mA to 11 mA with respect to the oscillation frequency from a 1.8 V supply.
Completing the design and integration of the FS is the most important step toward having a stand-alone FE. In this regard, the designed VCO needs to be improved in terms of the tuning range and PN.

In order to facilitate the control of the FE’s bandwidth, the filter requires an automatic tuning circuit. This can be achieved by a feedback system that consists of a PLL-like circuit and the most selective resonator of the filter.

For the OS FE, the next important step is to conduct experiments with the live satellite signals and a baseband receiver to test the sensitivity of the FE. The FE, especially its LNA and LPF, can be optimized for lower power consumption at the expense of lower linearity.

Adding an AGC is another necessary step toward the completeness of the FE. The AGC is provisioned to be implemented in the baseband processor by monitoring the ADC’s output. This provides flexibility to the baseband processor to implement different mitigation algorithms to improve the robustness of the receiver.

Equipping the FE with an I/Q mismatch calibration circuit can guarantee a maximum level of IQ imbalance, and thus result in a better image rejection.

The adopted architecture for the FE is very suitable for a phased-array FE, owing to the fact that this architecture requires a minimal effort to combine a few phase-shifted RF signals (after their downconversion) at the very beginning of the IF section. In fact, each array consists of an LNA and a quadrature mixer. The phase shift can be applied to the LO that drives the mixer instead of the RF signals. All the downconverted signals from the arrays can be combined and fed the current-input LPF. Of course, the phased-array FE necessitates the design of a phase shifter. However, considering that the phase shifter needs to operate only at the single frequency of the LO, its design even at the high frequency of the LO is not complicated.

Future work on the PRS FE implementation includes the removal of the characterization analog blocks, and the inclusion of standard ESD protection and voltage regulation cells using the foundry’s intellectual property (IP) blocks. In addition, different automated calibration methods could be applied to enable a more robust commercial implementation.


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Bibliography


Bibliography


# Acronyms

<table>
<thead>
<tr>
<th>Acronym</th>
<th>Description</th>
</tr>
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<tbody>
<tr>
<td>AC</td>
<td>alternating current</td>
</tr>
<tr>
<td>ADC</td>
<td>analog-to-digital converter</td>
</tr>
<tr>
<td>ADPLL</td>
<td>all-digital phase-locked loop</td>
</tr>
<tr>
<td>AGC</td>
<td>automatic gain control</td>
</tr>
<tr>
<td>AMOS</td>
<td>accumulation-mode metal-oxide-semiconductor</td>
</tr>
<tr>
<td>ARMOURS</td>
<td>Antenna and fRont-end MOdules for pUblic Regulated Service applications</td>
</tr>
<tr>
<td>ARNS</td>
<td>Aeronautical Radio Navigation Service</td>
</tr>
<tr>
<td>ASIC</td>
<td>application-specific integrated circuit</td>
</tr>
<tr>
<td>BaSE</td>
<td>Bavarian security receiver</td>
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<tr>
<td>BB</td>
<td>baseband</td>
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<tr>
<td>BOC</td>
<td>binary offset carrier</td>
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<tr>
<td>BPF</td>
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<tr>
<td>BPSK</td>
<td>Binary Phase-Shift Keying</td>
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<tr>
<td>BW</td>
<td>bandwidth</td>
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<tr>
<td>CDMA</td>
<td>code division multiple access</td>
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<tr>
<td>CM</td>
<td>common-mode</td>
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<tr>
<td>CMFB</td>
<td>common-mode feedback</td>
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<tr>
<td>CML</td>
<td>current-mode logic</td>
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<tr>
<td>CMOS</td>
<td>complementary metal-oxide-semiconductor</td>
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<td>CP</td>
<td>charge pump</td>
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<td>CS</td>
<td>Commercial Service</td>
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<td>Description</td>
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<td>direct current</td>
</tr>
<tr>
<td>DNL</td>
<td>differential non-linearity</td>
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<tr>
<td>DR</td>
<td>dynamic range</td>
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<tr>
<td>DSSS</td>
<td>direct-sequence spread spectrum</td>
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<tr>
<td>EA</td>
<td>error amplifier</td>
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<tr>
<td>ENOB</td>
<td>effective number of bits</td>
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<td>ESD</td>
<td>electrostatic discharge</td>
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<td>Global Positioning System</td>
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<td>Global System for Mobile Communications</td>
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<td>IC</td>
<td>integrated circuit</td>
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<td>intermediate frequency</td>
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<td>IIP2</td>
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<td>process, voltage and temperature</td>
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<td>SNDR</td>
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<tr>
<td>SoL</td>
<td>Safety of Life</td>
</tr>
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<td>SPI</td>
<td>serial peripheral interface</td>
</tr>
<tr>
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<td>space vehicle</td>
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<tr>
<td>TETRA</td>
<td>Terrestrial Trunked Radio</td>
</tr>
<tr>
<td>TF</td>
<td>translational filter</td>
</tr>
<tr>
<td>THD</td>
<td>total harmonic distortion</td>
</tr>
<tr>
<td>UMC</td>
<td>United Microelectronics Corporation</td>
</tr>
<tr>
<td>VCO</td>
<td>voltage-controlled oscillator</td>
</tr>
<tr>
<td>VGA</td>
<td>variable-gain amplifier</td>
</tr>
</tbody>
</table>
CURRICULUM VITAE

Saeed Ghamari

Rue de Maillefer 20,
CH-2000, Neuchâtel,
Switzerland
Cell: +41 79 305 3049
saeed.ghamari@epfl.ch, saeed.ghamari@gmail.com

born on July 8, 1985
Male, Single
Iranian

Last update: March 11, 2016

Education

Ph.D. Student - Microelectronics
École Polytechnique Fédérale de Lausanne, CH-2000 Neuchâtel, Switzerland
Thesis: CMOS ASIC Design of Multi-Frequency Multi-Constellation GNSS Front-Ends
May 2011–present

M.Sc., Fields and Waves, Communications, Electrical Engineering
Amirkabir University of Technology, Tehran, Iran
Sept. 2007–April 2010

B.Sc., Communications, Electrical Engineering
Khaje Nasir Toosi University of Technology (KNTU) Tehran, Iran
Thesis: Design a Watermarking Algorithm for Telephone Channel

Experience

Ph.D. Student/Doctoral Assistant - Analog IC Design
École Polytechnique Fédérale de Lausanne, 2000 Neuchâtel, Switzerland
May 2011–present

Projects:

► C-Max
in collaboration with EM Microelectronic - Marin SA, Marin, Switzerland
• design of the RF amplification stage
• extensive simulations to meet specifications of commercial product

► ARMOURS - Antenna and fRont-end Modules for pUblic Regulated Service applications
in collaboration with ACORDE Technologies S.A., Sofant Technologies, Interuniversitair Micro-Electronica Centrum vzw (IMEC)
• design of a dual-frequency PRS FE ASIC
• design of a 6-bit flash ADC
• design of a reconfigurable continuous-time wide-tuning-range elliptic filter
• PCB development and testing

► Dual-frequency Beidou/GPS/Galileo RF Front-End for Mass Market Applications
• design of a dual-frequency GNSS FE ASIC
• design of all the building blocks of the GNSS FE including an LNA, mixer, IF filter, VGA, ADC, VCO
• design of a reconfigurable continuous-time wide-tuning-range elliptic filter
• PCB development and testing

Research Assistant at iRadio Lab
University of Calgary, Calgary, Alberta, Canada
July 2010–April 2011

Projects:

► Development of a passive reflectometer using a six-port junction

Research Assistant at MMWCL
Amirkabir University of Technology, Tehran, Iran
Sep. 2007–April 2010

Projects:

► Design and implementation of a Five Port Receiver at 2.14 GHz
► Design and implementation of Power Amplifier Linearization Circuits base on Predistortion
► Design and implementation of a Doherty Power Amplifier Linearization Circuits.
Publication:


Graduate Courses:

- PLLs Advanced Techniques course - Mead Education, July 2014
- Design of ultra-low power wireless sensor networks - Mead Education, July 2013
- High-Performance Data Converters - Mead Education, July 2012
- Practical Aspects of Mixed Signal Design - Mead Education, August 2011
- RF Analog IC Design - Mead Education, July 2011
- ESA International Summer School on GNSS, June 2011

Teaching Experience:

- Teaching Assistant, EPFL-MSc Course, Microelectronics
- Teaching Assistant, Khaje Nasir University of Technology-BSc Course, Mathematical Engineering

Computer Skills

- MAC OS X, Linux, Microsoft Windows
- Cadence, ADS, PSPICE, HFSS
- MATLAB, Ocean Script, VHDL, C/C++
- Farsi, Office
- Altium Designer

Languages:

- Persian, mother tongue
- English, full professional proficiency
- French, elementary proficiency

Hobbies:

- Ski, Football, Swimming, Chess
- Photography, Movies